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TPS65381-Q1 SLVSBC4F - MAY 2012 - REVISED MAY 2016

# TPS65381-Q1 Multi-Rail Power Supply for Microcontrollers in Safety Applications

#### **Device Overview** 1

#### 1.1 Features

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following **Results:** 
  - Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature
  - Device HBM ESD Classification Level H2
  - Device CDM ESD Classification Level C3B
- Multi-Rail Power Supply Supporting Among Others
  - Texas Instruments TMS570LS Series **Microcontrollers**
- Supply Rails
  - Input voltage range:
    - 5.8 V to 36 V (CAN, I/O, MCU Core, and Sensor-Supply Regulators Functional)
    - 4.5 V to 5.8 V (3.3-V I/O and MCU Core-Voltage Functional)
  - 6-V Asynchronous Switch-Mode Preregulator With Internal FET, 1.3-A Current-Limit, and **Temperature Protection**
  - 5-V (CAN) Supply Voltage, Linear Regulator With Internal FET, 350-mA Current-Limit, and **Temperature Protection**
  - 3.3-V or 5-V MCU I/O Voltage, Linear Regulator With Internal FET, 350-mA Current-Limit, and **Temperature Protection**
  - 0.8-V to 3.3-V Adjustable MCU Core Voltage, Linear Regulator Controller With External FET
  - Sensor Supply: Linear Tracking Regulator With Tracking Input, 100-mA Current-Limit. Temperature Protection, and Protection Against Short to Battery and Short to Ground
  - Charge Pump: Typ. 12 V Above Battery Voltage

#### Power Supply and System Monitoring ٠

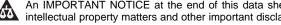
- Independent Undervoltage and Overvoltage Monitoring on All Regulator Outputs, Battery Voltage, and Internal Supplies
- Independent Bandgap Reference for Voltage Monitoring
- Independent Voltage References for Regulator

References and Voltage Monitoring. Voltage-Monitoring Circuitry With Separate Battery Voltage Input Pin

- Self-Check on all Voltage Monitoring (During Power-Up and After Power-Up Initiated by External MCU)
- Junction Temperature Sensing With Shutdown Thresholds

## Microcontroller Interface

- Watchdog: Trigger Mode (OPEN/CLOSE Window) or Question and Answer Mode
- MCU Error-Signal Monitor (Supports TI TMS570 MCU Mode or Other MCUs with PWM Signaling)
- DIAGNOSTIC State for Performing Device Self-Tests, Diagnostics, and External Interconnect Checks
- Safe-State for Device and System Protection on Error Event Detection
- Clock Monitor for Internal Oscillators
- Self-Tests for Analog- and Digital-Critical Circuits Executed With Every Device Power Up or Activated by MCU in DIAGNOSTIC State
- CRC on Non-Volatile Memory, Device, and System Configuration Registers
- Reset circuit for MCU
- Diagnostic Output Pin Allowing MCU to Observe Internal Analog and Digital Signals of the Device, Selectable Through Multiplexer
- SPI
  - Configuring IC Registers
  - Watchdog Question-Answering
  - Diagnostic Readout
  - Compliant With 3.3-V and 5-V Logic Levels
- Enable-Drive Output for Disabling Safing-Path or External Power-Stages on Detected System-Failure
- Wake-Up Through IGNITION Pin or CAN WAKEUP Pin
- Package: 32-Pin HTSSOP PowerPAD<sup>™</sup> IC Package





## 1.2 Applications

#### Safety Automotive Applications

- Power Steering (EPS, or Electrical Power Steering, and EHPS, or Electro Hydraulic Power Steering)
- Braking (ABS, ESC, and Electric Park Break)
- Advanced Driver Assistance Systems (ADAS)
- Suspension

## Industrial Safety Applications

- Safety PLC Controllers
- Safety I/O Control Modules
- Test and Measurement
- Railway and Subway Signal Control and Safety Modules
- Elevator and Escalator Safety Control
- Wind Turbine Control

## 1.3 Description

The TPS65381-Q1 device is a multi-rail power supply designed to supply microcontrollers (MCUs) in functional safety applications, such as those found in automotive and industrial applications. The device supports Texas Instruments' TMS570LS series flash MCU and other MCUs with dual-core lockstep (LS) or loosely-coupled architectures (LC).

The TPS65381-Q1 device integrates multiple supply rails to power the MCU, CAN, or FlexRay, and an external sensor. An asynchronous-buck switch-mode power-supply converter with an internal FET converts the input battery voltage to a 6-V preregulator output. This 6-V preregulator supplies the other regulators. Furthermore, the device supports wake-up from IGNITION or wake-up from the CAN transceiver.

A fixed 5-V linear regulator with an internal FET is integrated to be used as a CAN supply (as one example). A second linear regulator, also with an internal FET, regulates the 6 V to a selectable 5-V or 3.3-V MCU I/O voltage.

The TPS65381-Q1 device comprises a linear regulator controller with an external FET and resistor divider that regulates the 6 V to an externally adjustable core voltage of between 0.8 V and 3.3 V.

The device comprises a sensor supply with short-to-ground and short-to-battery protection. Therefore this supply can power a sensor outside the electronic-control unit (ECU).

The device has an integrated charge pump to provide overdrive voltage for the internal regulators. Reverse-battery protection is obtained by using the charge-pump output to control an external NMOS transistor. This solution allows for a lower minimum-battery-voltage operation compared to a traditional reverse-battery blocking diode.

The device monitors undervoltage and overvoltage on all regulator outputs, battery voltage, and internal supply rails. A second bandgap reference, independent from the main bandgap reference, is used for the undervoltage and overvoltage monitoring, to avoid any drifts in the main bandgap reference from being undetected. In addition, regulator current-limits and temperature protections are implemented.

The TPS65381-Q1 has monitoring and protection functions which include the functions as follows: watchdog with trigger and *question and answer* modes, MCU error-signal monitor, clock monitoring on internal oscillators, self-check on the clock monitor, CRC on non-volatile memory, a diagnostic output pin allowing the MCU to observe the internal analog and digital signals of the device, a reset circuit for the MCU, and an enable drive output to disable the safing-path or external power-stages on detected faults. A built-in self-test (BIST) monitors the device functionality at start-up. A dedicated DIAGNOSTIC state allows the MCU to check TPS65381-Q1 monitoring and protection functions.

The TPS65381-Q1 device is offered in a 32-pin HTSSOP PowerPAD package.

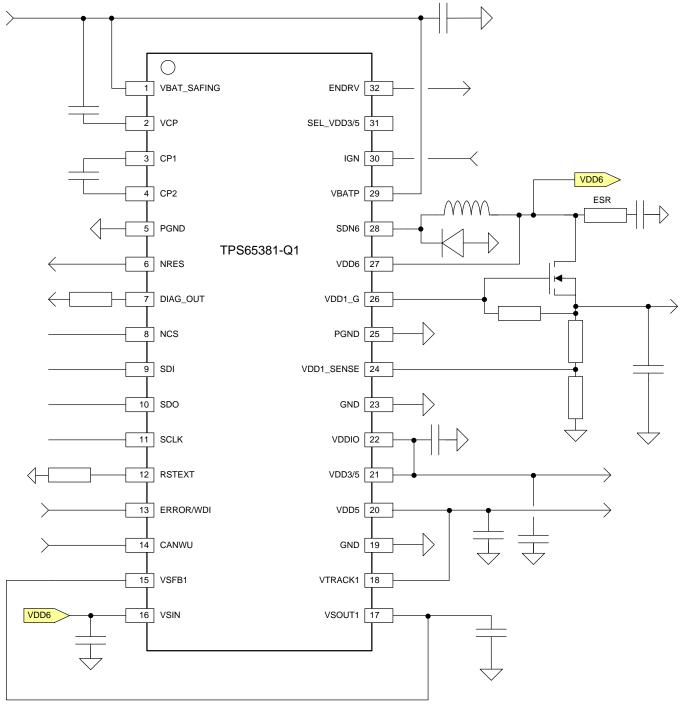
PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS65381-Q1	HTSSOP (32)	11.00 mm × 6.20 mm

## Device Information<sup>(1)</sup>

(1) For all available packages, see the orderable addendum at the end of the datasheet.



## 1.4 Typical Application Diagram



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Figure 1-1. Typical Application Diagram



## **Table of Contents**

1	Devid	ce Overview	1
	1.1	Features	1
	1.2	Applications	2
	1.3	Description	<u>2</u>
	1.4	Typical Application Diagram	<u>3</u>
2	Revis	sion History	<u>4</u>
3	Pin C	Configuration and Functions	<u>16</u>
4	Spec	ifications	<u>18</u>
	4.1	Absolute Maximum Ratings	<u>18</u>
	4.2	ESD Ratings	<u>18</u>
	4.3		<u>19</u>
	4.4	Thermal Information	<u>19</u>
	4.5	Electrical Characteristics	21
	4.6	Timing Requirements	25
	4.7	Switching Characteristics	26
	4.8	Typical Characteristics	<u>27</u>
5	Detai	led Description	<u>28</u>
	5.1	Overview	28
	5.2	Functional Block Diagram	28

	5.3	Feature Description	. 29
	5.4	Device Functional Modes	. 33
	5.5	Register Maps	. 75
6	Appl	ication and Implementation	. 98
	6.1	Application Information	. 98
	6.2	Typical Application	. 98
	6.3	System Examples	106
7	Powe	er Supply Recommendations	111
8	Layo	out	111
	8.1	Layout Guidelines	111
	8.2	Layout Example	113
9	Devi	ce and Documentation Support	114
	9.1	Device Support	114
	9.2	Documentation Support	114
	9.3	Community Resources	114
	9.4	Trademarks	114
	9.5	Electrostatic Discharge Caution	114
	9.6	Glossary	114
10		hanical, Packaging, and Orderable	
	Infor	mation	<u>114</u>

## 2 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (July 2015) to Revision F P	Page
<ul> <li>Added clarity to the PIN Function table descriptions</li></ul>	16 19 19
<ul> <li>Added VBAT_SAFING input supply voltage range for normal operation RECOMMENDED OPERATING CONDITIONS table</li> <li>Added clarification in statement for the ELECTRICAL CHARACTERISTICS table by adding VBAT_SAFING</li> </ul>	<u>19</u>
<ul> <li>recommended operating range in addition to VBATP recommended operating range</li></ul>	<u>21</u>
<ul> <li>6.23</li> <li>Added clarification on direct loading of VDD6 in the I<sub>VDD6</sub> <i>Electrical Characteristics</i> table</li> <li>Changed the Test Condition column to parameter description the <i>ELECTRICAL CHARACTERISTICS</i> table for</li> </ul>	<u>21</u> <u>21</u>
<ul> <li>2.2, 3.1, 3.2, 5.1, 5.3a, 5.4, 9.3.</li> <li>Added clarification on resistor divider on regulation tolerance of VDD1 in the VDD1 section of the <i>Electrical Characteristics</i> table</li> </ul>	<u>21</u> <u>22</u>
<ul> <li>Deleted test condition from T<sub>J</sub> the <i>Electrical Characteristics</i> table for 5.5 because it is same as overall electrical characteristics table</li> <li>Changed Test Condition for input to sensor supply to VSIN from VBATP in the <i>Electrical Characteristics</i> for</li> </ul>	<u>23</u>
<ul> <li>parameters 5.6, 5.7, 5.8</li> <li>Changed the description for indication of VBATP_UV (6.1, 6.2) in the <i>ELECTRICAL CHARACTERISTICS</i> table.</li> <li>Added the condition of VBATP = VBAT_SAFING to 6.1, 6.2, 6.3, 6.4, 6.5, 6.8, 6.9, 6.10, 6.11, 6.12, 6.13, 6.14, 0.45, 0.</li></ul>	
<ul> <li>6.15, 6.16, 6.17 in the <i>ELECTRICAL CHARACTERISTICS</i> table.</li> <li>Added the condition of VBATP = VBAT_SAFING = 12 V to 7.1, 7.2, 7.3, 7.4, 7.7 and 7.8 the <i>ELECTRICAL CHARACTERISTICS</i> table.</li> </ul>	23 24
<ul> <li>Changed test condition for the I_IGN parameter (7.4) to 36 V, added clarification that VBATP = VBAT_SAFING = 36 V in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Changed test condition for the I_CANWU parameter (7.7) to 36 V, added clarification that VBATP = VBAT_SAFING</li> </ul>	
VBAT_SAFING = 36 V in the ELECTRICAL CHARACTERISTICS table	24

**INSTRUMENTS** 

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•	Added clarification for C <sub>pump</sub> and C <sub>store</sub> connections in the <i>Charge Pump section of the ELECTRICAL</i> CHARACTERISTICS table	24
•	Changed the Test Condition for NRES output low (paramater 9.1) level from 5mA to 2mA in the <i>ELECTRICAL CHARACTERISTICS</i> table	24
•	Added clarification in statement for the Timing Requirements table by adding VBAT_SAFING recommended	
•	operating range in addition to VBATP recommended operating range Changed description of parameter from Test Condition column to a footnote on the parameter in the <i>Timing</i>	<u>25</u>
•	Requirements table for parameters 6.7, 11.1	<u>25</u>
•	table	<u>25</u>
•	operating range in addition to VBATP recommended operating range	<u>26</u>
•	Added clarification of resistor divider feedback impact in the <i>VDD1 Linear Regulator</i> section Changed pin name to VTRACK1 for pin determining tracking or non-tracking mode in <i>VSOUT1 Linear Regulator</i>	30
•	section describing what occurs after completion of the VDDx ramp-up	<u>31</u>
	with the power supply and do not need IGN or CANWU	$\frac{32}{22}$
•	Changed the <i>Power-Up and Power-Down Behavior</i> image for clarity Changed the VDD6 UV bit to D6 from D7 in the <i>Voltage Monitoring Overview</i> table	36
•	Changed the name for VSOUT1 current-limit to VSOUT1_CL in the <i>Internal Error Signals</i> table Changed all references to the sensor supply to VSOUT1 for consistency	<u>38</u> 38
•		$\frac{\frac{30}{40}}{41}$
•	Changed to clarify LBIST functionality in the Logic Built-In Self-Test (LBIST) section	
•	Changed the impact on device behaviour for VSOUT1 thermal protect and overcurrent in the <i>Thermal and</i> Overcurrent Protect Overview table	42
•	Changed the name for VSOUT1 current-limit to VSOUT1_CL in the <i>Digital MUX Selection</i> table Changed and clarified Watchdog timer text in the <i>Watchdog Timer (WDT)</i> section	46
•	Changed the all references of ERROR/WDTI pin to ERROR/WDI pin for consistency	48
•	Added clarification on the watchdog fail counter and reset event requirements in the Watchdog Fail Counter, Status, and Fail Event section	48
•	Added the Watchdog Sequence section	49
•	Changed and clarified the equations for watchdog WINDOW 1 and WINDOW 2 (t <sub>WOW</sub> and t <sub>WCW</sub> ) timing <i>Watchdog Sequence</i> section	49
•	Added the MCU to Watchdog Synchronization section	50
•	Added note on TIME_OUT flag not latching during active SPI frame (nCS low) in the <i>Trigger Mode (Default Mode)</i> section	50
•	Added clarification of the impact of a bad event on the watchdog sequence in the <i>Trigger Mode Section</i> and updated the images	53
•	Added note on TIME_OUT flag not latching during active SPI frame (nCS low) in the Q&A Mode section	
•	Changed and clarified the watchdog in Q&A mode answer sequence requirements in the Watchdog Q&A Related Definitions section	55
•	Changed the <i>Watchdog Sequence in Q&amp;A Mode</i> image in the <i>Watchdog Sequence in Q&amp;A Mode</i> section to update the Answer-3, Answer-2, Answer-1 requirements	56
•	Added for clarification the Device Controller State Diagram	
•	Changed SAFETY_ERR_STATUS to SAFETY_ERR_STAT so all references to this register are consistent	
•	Added clarification on using the DIAG_EXIT_MASK bit for sofware debug to the end of the DIAGNOSTIC	
•	Added note to explain conditions leading to inadvert setting of SDO ERROR bit in the Device Status Flag Byte	<u>74</u>
•	Response section	76
	Changed DEV_STATE to DEV_STAT for Device Status in Register table for consistency	
•	Deleted VSOUT1_ILIM in the SAFETY_STAT_1 Register table and made bit D3 a reserved bit (RSV)	
•	Changed VDD_3_5_SEL description in SAFETY_FUNC_CFG Register table	
•	Changed and clarified the WDT_TOKEN_FDBCK Register table	
•	Changed and clarified the WDT_WIN1_CFG Register table	
•	Changed and clarified the WDT_WIN2_CFG Register table	
•	Changed and clarified the WDT_TOKEN_VALUE Register table	94
•	Changed and clarified the WDT_STATUS Register table	
•	Changed and clarified the WDT ANSWER Register table	

5

- Changed and clarified the Software Flowchart for Configuring and Synchronizing the MCU With the Watchdog in Added the Software Flowchart for Configuring and Synchronizing the MCU With the Watchdog in Trigger Mode
- flowchart ..... 110 Added clarity for VBAT\_SAFING in the *Power Supply Recommendations* section..... 111

#### Changes from Revision D (May 2015) to Revision E

Changed the maximum UV value for VDD1 from 0.97 to 0.98 in the Voltage Monitoring Overview table. Also Changed the MAX value for VDD1\_UVN from 0.97 to 0.98 in the Internal Error Signals table. Also updated the Added clarification on the watchdog fail counter and reset event requirements in the Watchdog Enable Function 48 image ..... Added clarification on the watchdog fail counter and reset event requirements in the Device Controller State 72 Diagram.....

### Changes from Revision C (March 2015) to Revision D

Changed MIN value of VDD1<sub>SENSE</sub>(4.2) from -2% to -1% in the *Electrical Characteristics* table ..... 22 Changed MAX value of VDD1 undervoltage level (6.16) from 0.97 to 0.98 in the Electrical Characteristics table ... 24 

## Changes from Revision B (July 2014) to Revision C

•	Changed Applications listed in the Applications Section	. 2
•	Deleted the nominal storage temperature value of 27°C	18
•	Changed the Handling Ratings to ESD Ratings and moved T <sub>stg</sub> into the Absolute Maximum Ratings table	18
•	Added clarification notes on output capacitance and ESR for VDD6 in the ELECTRICAL CHARACTERISTICS	<u></u>
	table	<u>21</u>
•	Added the <i>Typical Characteristics</i> section	27
•	Added clarification of ESR needed on VDD6 output capacitance in the <i>Functional Block Diagram</i>	28
•	Added clarification on effective output capacitance and ESR in the VDD6 Buck Switch-Mode Power Supply	20
	section	20
•	Added clarification on the IGN and CANWU pins with respect to transients <i>Wake-Up</i> section	<u>29</u> 32
	Added start-up delay to VCP in the Power-Up and Power-Down Behavior	33
	Added SPI Interface Note on use of the SPI while DIAG_OUT MUX is enabled in the <i>Diagnostic Output Pin</i>	<u>55</u>
•	DIAG OUT section	43
•	Added clarification on the watchdog fail counter and reset event requirements in the WDT Fail Counter, WDT	45
•	Status, and WDT Fail Event section	48
•	Changed the RT bits from 4:0 to 6:0 in the $T_{WCW}$ calculation in the WDTI Configuration With an External Trigger	40
•	Input (Default Mode) section	51
•	Deleted the RT bits from 4:0 to 6:0 in the $T_{WCW}$ calculation in the <i>Watchdog Token-Response Sequence Run</i>	<u><u></u></u>
•	section and changed the second calculation from $T_{WOW}$ to $T_{WCW}$	55
•	Changed WDT_ANSW_CNT answer order in Set of 4-Bit WD Token Values and Corresponding 8-Bit	<u> </u>
-	Responses table.	61
•	Changed 4-bit watchdog answer conter to 2-bit watchdog answer counter (WDT_ANSW_CNT) in Watchdog	01
-	Token-Response Sequence Run and WDT_STATUS Register Updates section .	61
•	Deleted logic BIST activated by MCU in SAFE state in the MCU Error Signal Monitor (MCU ESM)	63
	Deleted permanently text for the CRC check in the Device Configuration Register Protection section	67
	Changed CRC check to return to step one for continuous check in the <i>Device Configuration Register Protection</i>	<u>07</u>
-	section	60
•	Added clarification on the watchdog fail counter and reset event requirement in the Reset and Enable Circuit	<u>69</u>
•		70
	image	<u>70</u>
•	Added or POST_RUN_RST = 1 & IGN_PWRL = 1 & re-cranking on IGN to <i>Global RESET Conditions</i> text	70
	bubble of the Device Controller State Diagram image	72 73
•	Added clarification on watchdog fail counter text to the watchdog reset sub-bullet in the RESET STATE list	13

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Page

Page

Page

TEXAS INSTRUMENTS

٠	Changed status bit STAT[1] function in <i>Device Status Flag Byte Response</i> table	. 76
٠	Added clarification for watchdog failure in the SAFETY_STAT_2 Register table	. 83
٠	Added clarification for watchdog failure in the SAFETY_STAT_4 Register table	
٠	Added ERROR/WDI text to D[5] cleared to description in the SAFETY_ERR_STAT Register table	
٠	Added watchdog fail counter text to D[4] cleared to description in the SAFETY_ERR_STAT Register table	
٠	Changed the calculation in the WDT_WIN1_CFG Register table	. 93
٠	Changed the calculation in the WDT_WIN2_CFG Register table	
٠	Changed data for SW_LOCK and SW_UNLOCK commands which were reversed in the SPI Command Table	
٠	Added the Typical Application section	
٠	Clarified ESR needed on VDD6 output capacitance in the Typical Application Diagram	. 99
٠	Added the System Examples section	106
٠	•	111

#### Changes from Revision A (December 2013) to Revision B

#### Page

• •	Deleted the phrase <i>safety critical</i> from the document	<u>1</u> <u>1</u>
•	section Changed the pin type for the VDD3/5 pin from I to PWR Changed the max value for the Charge-pump voltages from 50 to 52 V in the ABSOLUTE MAXIMUM RATINGS	2 <u>17</u>
•	Added the <i>Handling Ratings</i> table which now contains the storage temperature and ESD ratings	<u>18</u> <u>18</u>
•	CONDITIONS Moved operating ambient temperature range from the Absolute Maximum Ratings table to the Recommended Operating Conditions table	<u>19</u> 19
•	Changed changed <i>no undervoltage</i> to <i>no NRES event</i> and added VSOUT to the input supply voltage range on VBATP specification in the <i>Recommended Operating Conditions</i>	<u>19</u> <u>19</u>
•		<u>19</u> <u>20</u>
•	and added reference to R1.2 Deleted letter A from beginning of POS number in the VDD6-BUCK With Internal FET and VDD1 – LDO With	<u>21</u> <u>21</u> 21
•	Added the test condition to the dVDD5/dt parameter in the <i>ELECTRICAL CHARACTERISTICS</i> table Changed the typ value from 3.35 to 3.3 and 5 for the VDD3/5 output voltage parameter in the <i>ELECTRICAL</i>	<u>21</u>
•	CHARACTERISTICS table Changed the unit from † to V for the 3.3, VDD3/5 output voltage dynamic parameter in the <i>Electrical</i> <i>Characteristics</i> table	<u>22</u> 22
• • •	Changed the parameter of 3.8 in the <i>Electrical Characteristics</i> table from VDD5 to VDD6 Changed the parameter of A4.11 in the <i>Electrical Characteristics</i> table from VBATP to VDD6 Changed MVVSOUT1 min and max values from –35 and 35 to –25 and 25 in the <i>Electrical Characteristics</i> table Changed the max value for temperature range listed in the VdrS1 parameter test condition from 165 to 150 in	22 22 23
•	the <i>Electrical Characteristics</i> table Changed the MIN and MAX values of the LdReg <sub>VSOUT1</sub> parameter from –25 and 25 to –35 and 35 in the	<u>23</u>
•	Electrical Characteristics table	<u>23</u>
•	Characteristics table	<u>23</u>
• •	Changed min value from 300 to 350 for the VENDRY_NRES_TH (9.5) parameter in the ELECTRICAL	
	CHARACTERISTICS table	<u>24</u>

7

TPS65381-Q1 SLVSBC4F - MAY 2012 - REVISED MAY 2016 TEXAS INSTRUMENTS www.ti.com

•	Added note reference and test condition to the V <sub>DIGIN_HIGH</sub> parameter (10.1) in the <i>ELECTRICAL</i>	
	CHARACTERISTICS table	<u>24</u>
•	Moved timing and switching characteristics out of the <i>Electrical Characteristics</i> table and into a <i>Timing</i>	
	Requirements and Switching Requirements table (respectively). Also moved the capacitance at C <sub>SDO</sub> note to the	05
	Timing Requirements and Switching Requirements tables	<u>25</u>
•	Changed the TYP value to the MAX value of the SPI clock frequency parameter for the VDDIO = 5 V test	25
	condition in the <i>Electrical Characteristics</i> table	25
•	Added image reference to timing and switching requirement parameters	$\frac{26}{26}$
•	Added the Overview section to the Detailed Description section	
•	Moved block diagram into the <i>Detailed Description</i> section and updated block colors	
•	Changed the OV max value for VDD3/5 (3.3 V) from 3.63 to 3.6 in the <i>Voltage Monitoring Overview</i> table	
•	Added nMASK comments to the UV and OV impact on device behavior for VDD1 in the Voltage Monitoring	<u>30</u>
	Overview table	36
•	Moved the Internal Error Signals table to after the Voltage Monitoring Overview table in the Detailed Description	<u></u>
	section	37
•	Changed the TYP value for the AVDD_UVN signal from 3.81 to 3.6 in the Internal Error Signals table. Also	<u>.</u>
	changed the device state from <i>Not changed</i> for NRES and ENDRV to <i>LOW</i> , and for State to <i>STAND-BY</i>	37
•	Changed the TYP value for the VCP12_UVN signal from 7.32 to 7.43 in the <i>Internal Error Signals</i> table	
•	Changed the TYP value for the VCP12_OV signal from 14 to 14.2 in the Internal Error Signals table	
•	Changed the typ value for VCP_OV from 20 to 21 in the Internal Error Signals table	
•	Changed NUV on signal names to UVN throughout	
•	Changed the MIN value for the LOCLK signal from 0.740.7452 to 0.742 in the Internal Error Signals table	37
•	Changed the VBATP_OV MIN and MAX values from 29 to 34.7 and 32 to 36.7 (respectively) in the Internal	
	Error Signals table	38
٠	Changed the device state of the VDD3_5_OT bit from STANDBY to include change	38
•	Changed the max values for VDD5_CL and VDD3_5_CL from 600 to 650 in the Internal Error Signals table	
•	Added the DVDD_UV signal to the Internal Error Signals table	<u>38</u>
٠	Changed	<u>38</u>
•	Deleted Watchdog function configuration from the post-BIST-reset initialization list in the Logic Built-In Self-Test	
	(LBIST) section	<u>41</u>
•	Changed VCP voltage range from 0.8 to 5.5 to 0.6 to 4	<u>44</u>
•	Replaced the VSFB1 sensor-supply feedback voltage row wit the VSOUT1 sensor-supply voltage row in the	
	Analog MUX Selection Table	<u>44</u>
•	Changed the Voltage Range / Accuracy value for both MAIN_BG and VMON_BG from 1.226 to 2.5 V in the	
•	Analog MUX Selection table	<u>44</u>
•	Digital MUX (DMUX) section	47
•	Deleted Bits INT_CON[2:0] in DIAG_CFG_CTRL register must be set to 111 list item from the SDO diagnostic	41
-	check sequence in the MUX interconnect check section	47
•	Changed the RT bits from 4:0 to 6:0 in the $T_{WCW}$ calculation in the WDTI Configuration With an External Trigger	
	Input (Default Mode) section	51
•		53
•	Added + 1 to the duration time program calculations in the <i>Watchdog Token-Response Sequence Run</i> section	
	and changed the second calculation from $T_{WOW}$ to $T_{WCW}$	55
•	Changed the filter time for the ERROR/WDI deglitch from 15-s to 15-µs in the MCU Error Signal Monitor (MCU	_
	ESM) section	63
•	Changed the low-pulse duration increment from 15-s to 15-µs in the PWM Mode section	
•	Changed the Reset and Enable Circuit figure to reflect overtemperature behavior.	70
٠	Added _UV to the nMASK_VDD1_OV name in the Reset and Enable Circuit image	70
•	Added _UV to the nMASK_VDD1_OV name in DIAGNOSTIC and ACTIVE state text box of the Device	
	Controller State Diagram image	<u>72</u>
•	Deleted WDT failure text from the first list item in the SAFE State section	
•	Moved all of the registers into one Register Map section	
•	Changed D0 from 1 to 0 in the DEV_REV Register table	
•	Changed D1 and D0 from 0 to X in the DEV_STATE Register table	
•	Changed the deglitched minimum time from 7.7 to 7.5 for the IGN bit description in the DEV_STATE register	
•	Changed D7 from RSV and 1 to VDD_3_5_SEL and X in the <i>DEV_CFG1 Register</i> table	
•	Changed D6 from nMASK_VDD_UV and 1 to nMASK_VDD_UV_OV and 0 in the <i>DEV_CFG1 Register</i> table	<u>79</u>
•	Changed the default value of the nMASK VDD1 UV OV bit from 1 to 0 and the VDD1 bit value from 0 to 1 in	

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		<u>79</u>
•	Changed bit D5 name from MASK_VBAT_OV to MASK_VBATP_OV in the DEV_CFG2 Register table	<u>79</u>
•	Changed VDD6, clearing, and re-enabling text from the D[7] description when EN_VDD3/5_OT is set to '1' and	70
•	changed to <i>when set to ""</i> in the <i>DEV_CFG2 Register</i> table Changed the D[7] description when EN_VDD3/5_OT is set to '0' by removing the SAFETY_STAT_REG1, VDD6	<u>79</u>
-	and re-enable text in the DEV_CFG2 Register table. Also changed from when set to '0' to when set to '1'	79
•	Changed D[3:0] description in the <i>DEV_CFG2 Register</i> table from <i>bits are not read/writable</i> to <i>bits are</i>	<u></u>
	read/writable	79
•	Deleted after SPI read access from the clear to 0 description of each bit in the VMON_STAT_1 Register	
•	Deleted after SPI read access from the clear to 0 description of each bit in the VMON_STAT_2 Register	
•	Deleted after SPI read access from the clear to 0 description of each bit in the SAFETY_STAT_1 Register	
•	Deleted <i>after SPI read access</i> from the clear to 0 description of each bit in the <i>SAFETY_STAT_2 Register</i>	
	Changed the name of bit D5 in the SAFETY_STAT_3 register from NRES_IN to NRES_ERR	
•	Changed the D[5] NRES_IN, Reset input status, register description to NRES_ERR, Reset input error and	<u><u><u></u></u></u>
	change first description for setting this bit to 1	84
•	Updated cleared to 0 description of the LBIST_ERR bit in the SAFETY_STAT_3 register	84
•	Added DIAGNOSTIC state description for setting bit D[3] and D[2] to 1	<u>84</u>
•	Changed SPI read access to internal NPOR from the LOCLK bit description in the SAFETY_STAT_4 Register	
•	Changed bit D7 and bit D6 from 1 to 0 in the SAFETY_ERR_CFG Register table	<u>86</u>
•	Changed the SAFETY_STAT4 register bit from D4 to D5 in the ABIST_EN[1:0] descriptions in the SAFETY_BIST_CTRL Register table	87
•	Changed names of protected registers in the CRG_CRC_EN bit description in the SAFETY_CHECK_CTRL	<u>01</u>
	Register.	88
•	Changed monitored to not monitored in the NO_ERROR bit description for setting this bit to 1 in the	
•	Changed CTRL to CFG in the read and write commands of the SAFETY_FUNC_CFG Register	
•	Changed D7 from 0 to 1 in the SAFETY_FUNC_CFG Register table	
•	Changed D4 from 1 to 0 in the SAFETY_FUNC_CFG Register table Changed D0 from 0 to X in the SAFETY_FUNC_CFG Register table	
•	Updated the WD_RST_EN bit description for setting this bit to 0 in the SAFETY_FUNC_CFG Register	
•	Changed 15 seconds to 15 µs in the SAFETY_ERR_PWM_H Register table description	90
•	Changed the time reference amount from 15 s to 15 µs in the PWML[7:0] bit description for when ERR_CFG is	
	set to 0 in the SAFETY_ERR_PWM_L Register	<u>90</u>
•		<u>90</u>
•	Deleted <b>Note</b> : With configuration 001 setting for INT_CON[2:0] bits text from the SPI_SDO description in the	
	DIAG_CFG_CTRL Register. Also changed the 111 description of the INT_CON[2:0] from controlling the state of the SPI_SDO output buffer to Not applicable	92
•	Included bit 2 to all WDT_FAIL_CNT bit references	<u>92</u> 94
•	Changed command for the WDT_ANSWER Register from Read to Write	
•	Changed the default setting of VSOUT1_EN from 1 to in the SENS_CTRL Register	
•	Changed Moved the Application Information section into the Application and Implementation section and added	
	product folder references	<u>99</u>

#### Changes from Original (May 2012) to Revision A

9

	_
<ul> <li>Changed current limit for 6-V pre-regulator from 1.5 A to 1.3 A in the <i>FEATURES</i> list</li></ul>	
<ul> <li>Changed document status from <i>Product Preview</i> to <i>Production Data</i></li></ul>	2

TPS65381-Q1 SLVSBC4F - MAY 2012 - REVISED MAY 2016

<ul> <li>Changed to data manual template to include table of contents and section numbers</li></ul>	. <u>3</u> <u>16</u> <u>18</u> <u>18</u> <u>18</u> <u>18</u>
<ul> <li>Added ADC, VDD6, to <i>Typical Application Diagram</i>.</li> <li>Changed PGND type from input to ground in <i>PIN FUNCTIONS</i> table</li> <li>Changed POS numbers in <i>ABSOLUTE MAXIMUM RATINGS</i> table for adjustments</li> <li>Changed POS numbers in <i>ABSOLUTE MAXIMUM RATINGS</i> table for adjustments</li> <li>Added Charge-pump overdrive voltage to the <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted DMUXO from Logic I/O voltage list (M1.15) in the <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Changed unit for CDM on corner pins (750) from kV to V in the <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted T<sub>J</sub> min value of -40 from <i>ABSOLUTE MAXIMUM RATINGS</i> table</li> <li>Deleted VDDIO internal pullup diode note from the <i>RECOMMENDED OPERATING CONDITIONS</i> table.</li> <li>Added values to the current consumption parameter in the <i>RECOMMENDED OPERATING CONDITIONS</i> table.</li> <li>Changed condition statement for the <i>ELECTRICAL CHARACTERISTICS</i> table by adding T<sub>A</sub> over junction temperature with up to 150°C</li> <li>Added VDD6 output voltage to I<sub>VDD6</sub> parameter (A1.2) in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Changed example to V<sub>dropout6</sub> (A1.3) test condition in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> </ul>	. <u>3</u> <u>16</u> <u>18</u> <u>18</u> <u>18</u> <u>18</u>
<ul> <li>Changed POS numbers in <i>ABSOLUTE MAXIMUM RATINGS</i> table for adjustments</li></ul>	. <u>18</u> . <u>18</u> . <u>18</u>
<ul> <li>Changed POS numbers in <i>ABSOLUTE MAXIMUM RATINGS</i> table for adjustments</li></ul>	. <u>18</u> . <u>18</u>
<ul> <li>Added Charge-pump overdrive voltage to the ABSOLUTE MAXIMUM RATINGS table</li></ul>	. 18
<ul> <li>Deleted DMUXO from Logic I/O voltage list (M1.15) in the ABSOLUTE MAXIMUM RATINGS table</li></ul>	
<ul> <li>Deleted T<sub>J</sub> min value of -40 from ABSOLUTE MAXIMUM RATINGS table</li></ul>	10
<ul> <li>Changed unit for CDM on corner pins (750) from kV to V in the ABSOLUTE MAXIMUM RATINGS table</li></ul>	
<ul> <li>Deleted T<sub>J</sub> min value of -40 from ABSOLUTE MAXIMUM RATINGS table</li></ul>	
<ul> <li>Deleted VDDIO internal pullup diode note from the <i>RECOMMENDED OPERATING CONDITIONS</i> table</li> <li>Added values to the current consumption parameter in the <i>RECOMMENDED OPERATING CONDITIONS</i> table .</li> <li>Changed condition statement for the <i>ELECTRICAL CHARACTERISTICS</i> table by adding T<sub>A</sub> over junction temperature with up to 150°C</li> <li>Added VDD6<sub>ripple</sub> parameter to the <i>ELECTRICAL CHARACTERISTICS</i> table</li></ul>	
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<ul> <li>Changed condition statement for the <i>ELECTRICAL CHARACTERISTICS</i> table by adding T<sub>A</sub> over junction temperature with up to 150°C</li> <li>Added VDD6<sub>ripple</sub> parameter to the <i>ELECTRICAL CHARACTERISTICS</i> table</li></ul>	
<ul> <li>temperature with up to 150°C</li> <li>Added VDD6<sub>ripple</sub> parameter to the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Added VDD6 output voltage to I<sub>VDD6</sub> parameter (A1.2) in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Changed example to V<sub>dropout6</sub> (A1.3) test condition in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> </ul>	. <u>19</u>
<ul> <li>Added VDD6<sub>ripple</sub> parameter to the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Added VDD6 output voltage to I<sub>VDD6</sub> parameter (A1.2) in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> <li>Changed example to V<sub>dropout6</sub> (A1.3) test condition in the <i>ELECTRICAL CHARACTERISTICS</i> table</li> </ul>	~ ~ ~
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Changed example to V <sub>dropout6</sub> (A1.3) test condition in the ELECTRICAL CHARACTERISTICS table	. 21
	21
	<u>21</u>
<ul> <li>Changed I<sub>VDD6_limit</sub> parameter description from current-limit to peak current in the ELECTRICAL CHARACTERISTICS table.</li> </ul>	24
	<u>21</u>
<ul> <li>Changed A1.5 from F<sub>sw_VDD6</sub>, switching frequency to f<sub>clk_VDD6</sub>, clock frequency, added note, and deleted test condition from the <i>ELECTRICAL CHARACTERISTICS</i> table. Also added test condition</li> </ul>	. 21
• Changed test condition for DC <sub>VDD6</sub> parameter (A1.6) from VBATP > 7 V to $0 < I_{VDD6} < 1.3$ A in the <i>ELECTRICAL</i>	21
CHARACTERISTICS table.	21
<ul> <li>Added Hysteresis parameter, min and max values to Tprot<sub>VDD6</sub> (A1.7) in the ELECTRICAL CHARACTERISTICS</li> </ul>	21
table. Changed test condition from Global shutdown to Protection of VDD6, shared with VDD3/5 thermal	
protection. for both Tprot <sub>VDD6</sub> parameters	21
<ul> <li>Added Hysteresis parameter, min and max values to Tprot<sub>VDD5</sub> (2.13) in the ELECTRICAL CHARACTERISTICS</li> </ul>	
table. Changed test condition from VDD5 switch-off to Protection of VDD5. In case of detected over-temperature,	
only VDD5 will be switched-off for both Tprot <sub>VDD5</sub> parameters	. 21
Added VDD3/5 end-value to test condition for the dVDD35/dt parameter (3.11) in the ELECTRICAL	
CHARACTERISTICS table	22
<ul> <li>Added Hysteresis parameter, min and max values to Tprot<sub>VDD3/5</sub> (3.13) in the ELECTRICAL</li> </ul>	
CHARACTERISTICS table. Changed test condition from Global shutdown to Protection of VDD3/5, treated as	
global thermal shutdown (shutdown for all regulators) for both Tprot <sub>VDD3/5</sub> parameters	22 22
Added test condition to the dVDD1/dt parameter (A4.14) in the ELECTRICAL CHARACTERISTICS table	. <u>22</u>
<ul> <li>Added VSOUT1 text to test condition for VSOUT1 parameter (5.1) in the ELECTRICAL CHARACTERISTICS</li> </ul>	
table	<u>22</u>
<ul> <li>Changed MVVSOUT1 min and max values from –15 and 15 to –35 and 35 in the ELECTRICAL</li> </ul>	
CHARACTERISTICS table	<u>23</u>
Added min and max values for the Threshold for tracking/non-tracking parameter in the ELECTRICAL	
CHARACTERISTICS table	<u>23</u>
<ul> <li>Added Hysteresis parameter, min and max values to Tprot<sub>VSOUT1</sub> (5.13) in the ELECTRICAL</li> <li>OUARA OTERIOTION table. Observed test and titles from VOSOUT1 (5.13) in the ELECTRICAL</li> </ul>	
CHARACTERISTICS table. Changed test condition from VSOUT1 switch-off to Protection of Sensor Supply.	
Only VSOUT1 switch-off for both Tprot <sub>VSOUT1</sub> parameters	<u>23</u>
• Changed min and max values for VBATP_OV <sub>rise</sub> parameter from 29.5 and 32.5 to 34.7 and 36.7 (respectively) in the ELECTRICAL CHARACTERISTICS table. Also added test apadition	22
<ul> <li>the ELECTRICAL CHARACTERISTICS table. Also added test condition</li></ul>	
<ul> <li>Changed min and max values for VBATP_OV<sub>fall</sub> parameter from 29 and 32 to 34.4 and 36.3 (respectively) in the</li> </ul>	20
ELECTRICAL CHARACTERISTICS table. Also added test condition	. <u>23</u>
<ul> <li>Added Hysteresis parameter, min and max values to VDD5_UV (6.8) in the ELECTRICAL CHARACTERISTICS</li> </ul>	
table.	
Changed max value for VDD5_OV from 5.5 to 5.45 in the ELECTRICAL CHARACTERISTICS table	
<ul> <li>Added Hysteresis parameter, min and max values to VDD5_OV (6.10) in the ELECTRICAL</li> </ul>	23
CHARACTERISTICS table.	23
<ul> <li>Changed min value for VDD3/5_UV with test condition of 3.3-V setting (undervoltage) from 2.97 to 3 in the</li> </ul>	<u>23</u> 23
ELECTRICAL CHARACTERISTICS table	<u>23</u> 23
• Changed max value for VDD3/5_UV with test condition of 5-V setting (undervoltage) from 4.8 to 4.85 in the	<u>23</u> <u>23</u> <u>23</u>
ELECTRICAL CHARACTERISTICS table	23 23 23 23 23 23

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•	Added Hysteresis parameter for 3.3 and 5 V settings, min and max values to VDD3/5_UV (6.12) in the ELECTRICAL CHARACTERISTICS table.	23
•	Changed max value for VDD3/5_OV with test condition of 3.3-V setting from 3.63 to 3.6 in the <i>ELECTRICAL CHARACTERISTICS</i> table	23
•	Added Hysteresis parameter for 3.3 and 5 V settings, min and max values to VDD3/5_OV (6.14) in the	_
•	ELECTRICAL CHARACTERISTICS table. Added Hysteresis parameter, min and max values to VDD1_UV (6.16) in the ELECTRICAL	<u>23</u>
	CHARACTERISTICS table. Changed test condition from Sensed on VDD1_SENSE pin to Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2) for both	
	VDD1_UV parameters	<u>24</u>
•	Added Hysteresis parameter, min and max values to VDD1_OV (6.17) in the ELECTRICAL CHARACTERISTICS table. Changed test condition from Sensed on VDD1_SENSE pin to Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2) for both	04
•	VDD1_OV parameters	<u>24</u>
	CHARACTERISTICS table. Changed test condition from Sensed on VSFB1 pin to Sensed on VSFB1 pin	•
•	Relative thresholds are: for both VSOUT1_UV parameters	<u>24</u>
	CHARACTERISTICS table. Changed test condition from Sensed on VSFB1 pin to Sensed on VSFB1 pin Relative thresholds are: for both VSOUT1_UV parameters	24
•	Added Hysteresis parameter, min and max values to VDD6_UV (6.22) in the ELECTRICAL	<u></u>
	CHARACTERISTICS table. Also added test condition for both VDD6_UV parameters	<u>24</u>
•	Added Hysteresis parameter, min and max values to VDD6_OV (6.23) in the <i>ELECTRICAL</i> <i>CHARACTERISTICS</i> table. Also added test condition for both VDD6_OV parameters	24
•	Added test condition to the I_IGN parameter in the the ELECTRICAL CHARACTERISTICS table(7.4)	
•	Changed I_CAN parameter (7.7) to I_CANWU and added test condition to the <i>ELECTRICAL</i> CHARACTERISTICS table.	24
•	Changed I_CAN_rev (7.8) max value from 1 to –1 in the <i>ELECTRICAL CHARACTERISTICS</i> table	24 24
•	Added test condition for I <sub>CP</sub> (8.2) in the ELECTRICAL CHARACTERISTICS table	24
•	Added min and max values for f <sub>CP</sub> (8.3) in the <i>ELECTRICAL CHARACTERISTICS</i> table	24
•	Deleted min value of 11 for the R <sub>dson_ENDRV_NRES</sub> (9.2a) parameter in the <i>ELECTRICAL CHARACTERISTICS</i> table	24
•	Added input and logic 1 to the V <sub>ENDRV_NRES_TH</sub> parameter (9.5) description in the <i>ELECTRICAL</i> CHARACTERISTICS table	<u>24</u>
•	Deleted max value from 500 to 450 for the V <sub>ENDRV NRES TH</sub> (9.5) parameter in the ELECTRICAL	
•	CHARACTERISTICS table	<u>24</u>
•	CHARACTERISTICS table	<u>24</u>
-	CHARACTERISTICS table. Also added parameter name	24
•	Changed 10.4 from empty to the R <sub>DIAGOUT_AMUX</sub> parameter to the <i>ELECTRICAL CHARACTERISTICS</i> table	<u>25</u>
•	Added pin note to the V <sub>DIGOUT_HIGH</sub> parameter (10.5) in the <i>ELECTRICAL CHARACTERISTICS</i> table Added pin note to the V <sub>DIGOUT_LOW</sub> parameter (10.6) in the <i>ELECTRICAL CHARACTERISTICS</i> table	25
•	Added pin hole to the $v_{\text{DIGOUT_LOW}}$ parameter (10.6) in the ELECTRICAL CHARACTERISTICS table	
•	Added for MCU error signal monitor to the $t_{ERROR_WDI_deglitch}$ parameter (12.1) in the <i>ELECTRICAL</i>	20
_	CHARACTERISTICS table	<u>25</u>
•	Changed max value for the t <sub>ERROR_WDI_deglitch</sub> parameter (12.1) from 15.75 to 16.25 in the <i>ELECTRICAL CHARACTERISTICS</i> table	25
•	Added t <sub>WD pulse</sub> parameter to the ELECTRICAL CHARACTERISTICS table	25
•	Added two test conditions to the f <sub>SPI</sub> parameter (13.1) and removed the single max value of 8 to replace it with	
•	the max value for each condition in the <i>ELECTRICAL CHARACTERISTICS</i> table	<u>25</u>
	the min value for each condition in the ELECTRICAL CHARACTERISTICS table	25
•	Added test condition to the f <sub>Syscik</sub> parameter (11.1) in the ELECTRICAL CHARACTERISTICS table	25
•	Changed max value for t <sub>susi</sub> (13.7) to min value in the ELECTRICAL CHARACTERISTICS table. Also changed	
•	parameter description from rising edge to falling edge of SCLK Changed min value from 250 to 788 for the t <sub>hics</sub> parameter (13.10) in the <i>ELECTRICAL CHARACTERISTICS</i>	<u>26</u>
•	table. Also added NCS high text to parameter description	<u>26</u>
5	table	<u>26</u>

•	Changed max value of $t_{d1}$ from 30 to 53.3 in the <i>ELECTRICAL CHARACTERISTICS</i> table Changed max value of $t_{d2}$ from 30 to 85.7 in the <i>ELECTRICAL CHARACTERISTICS</i> table. parameter	<u>26</u>
•	description from falling edge to rising edge of SCLK Changed t <sub>tri</sub> parameter (13.11) description from Hi-Z state to tristate in the <i>ELECTRICAL CHARACTERISTICS</i>	<u>26</u>
	table	26
٠	Changed max value of t <sub>tri</sub> (13.11) from 15 to 25 in the <i>ELECTRICAL CHARACTERISTICS</i> table	<u>26</u> 26
•	Added t <sub>d2</sub> to right side of SPI Timing Parameters diagram	26
•	Added the SPI SDO Buffer Source/Sink Current graph after the ELECTRICAL CHARACTERISTICS table	27
•	Changed block diagram	28
•	Added condition for when the N-channel MOSFET turns on to the second paragraph in the VDD6 Buck Switch- Mode Power Supply section	<u>20</u> 29
	Deleted clearing out of SAFETY_STAT from re-enable VDD5 paragraph and changed SENS_CTRL bit from 4 to	29
•		~~~
	D4 in the VDD5 Linear Regulator section.	<u>29</u>
•	Added the default VDD1 paragraph to the end of the VDD1 Linear Regulator section	<u>31</u>
•	Added sentence to the first paragraph in the VSOUT1 Linear Regulator section describing what occurs after	
	completion of the VDDx ramp-up	31
•	Changed tracking offset from ±15 to ±35 in the VSOUT1 Linear Regulator section	31
•	Added SPI command setting to the seventh paragraph in the VSOUT1 Linear Regulator section	
•	Added DIAGNOSTIC state text to the <i>Wake-Up</i> section	32
•	Changed second paragraph in the <i>Wake-Up</i> section: changed edge-sensitive to level-sensitive and pulse	<u>02</u>
•	duration to deglitch time.	22
		32
•	Added during a power-up event to the Reset Extension section and removed VDD1 from the description	<u>32</u>
•	Deleted open-connect and RESET state sentence from the last paragraph in the Reset Extension section	<u>32</u>
٠	Changed Power-Up and Power-Down Behavior image in the Power-Up and Power-Down Behavior section	33
٠	Added notes to the IGN Power Latch and POST-RUN Reset image in the Power-Up and Power-Down Behavior	
	section	<u>34</u>
•	Deleted reset driver from ENDRV bullet in the Safety Functions and Diagnostics Overview section	35
•	Added the Voltage Monitoring Overview table and table reference to the Voltage Monitor (VMON) section	35
•	Added Internal Error Signals table	37
	Deleted loss-of-power note and cleared-latched bullet from the clock failure list in the Loss-of-Clock Monitor	<u> </u>
	(LCMON) section	39
•	Added SPI register bit to the latched bullet in the clock failure list in the Loss-of-Clock Monitor (LCMON) section	
•	Added ABIST case paragraphs following the Analog BIST Run States image	<u>40</u>
•	Moved Logic Built-In Self-Test (LBIST) section from after DMUX tables and added initialized registers list	41
•	Deleted VDD5 and VSOUT1 supplies from first paragraph of the Junction Temperature Monitoring and Current	
	Limiting section	<u>41</u>
٠	Added VSOUT1 supplies paragraph to the Junction Temperature Monitoring and Current Limiting section	41
•	Deleted STANDBY State text from the Junction Temperature Monitoring and Current Limiting section and	_
	changed to regulated supplies. Also added ENDRV pin	42
•	Changed third paragraph of the Junction Temperature Monitoring and Current Limiting section to include NRES	
	asserted low and VDD5 reenable	42
•	Added Thermal and Overcurrent Protect Overview table and table reference to the Junction Temperature	
- 1	Monitoring and Current Limiting section	42
•	Added analog and digital signals and notes to the <i>Diagnostic Output Pin DIAG_OUT</i> image in the <i>Diagnostic</i>	44
-	Output Pin DIAG_OUT section	40
		<u>43</u>
•	Added added diasabled sate description for the DIAG_OUT pin in the last paragraph of the <i>Diagnostic Output</i>	
	Pin DIAG_OUT section	<u>43</u>
•	Added ± percentage to the divide ratio values (except for MAIN_BG and VMON_BG) the Analog MUX Selection	
	table	<u>44</u>
٠	Added accuracy and corresponding table note to the voltage range column in the Analog MUX Selection table	44
•	Added the max output resistance column to the Analog MUX Selection table	
•	Changed the DIAG_MUX_SEL column and header in the Analog MUX Selection table	
•	Added the voltage/signal name for signal number A.7 from BG1 to MAIN_BG in the Analog MUX Selection table	
•	Added additional text and note to further explain the <i>Analog MUX Selection</i> Table	
•		
		<del>44</del>
•	Added diagnostic check text, Diagnostic MUX Output state (by MUX_OUT bit), and MUX interconnect check	47
	section after DMUX tables	<u>47</u>
•	Changed the Watchdog Enable Function image in the WDT Fail Counter, WDT Status, and WDT Fail Event	
	section	
٠	Added watchdog fail counter text after the Watchdog Status for Fail Counter Value Range table	<u>48</u>

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•	Changed trigger events paragraph (third) in the WDTI Configuration with External Trigger Input (Default Mode) section	50
•	Added SPI register names and DIAGNOSTIC state to the open and close window programming sentence in the	<u>50</u>
	WDTI Configuration with External Trigger Input (Default Mode) section	<u>51</u>
•	Added the WDTI window sequencing and SPI SW_LOCK paragraphs in the WDTI Configuration with External Trigger Input (Default Mode) section	51
•	Added the WDTI rising edge paragraph in the WDTI Configuration with External Trigger Input (Default Mode)	<u>.</u>
	section and added t <sub>WD_pulse</sub> filter time paragraph Added image to the WDTI Configuration with External Trigger Input (Default Mode) section	51
•	Added image to the WDTI Configuration with External Trigger Input (Default Mode) section	<u>52</u> 53
•	Deleted ASIC reference in the first paragraph of the Watchdog Question /and Answer Configuration Through	
	SPI section	<u>54</u>
•	Added starts a new watchdog token-response sequence run to the no-response event description in paragraph four of the Watchdog Question /and Answer Configuration Through SPI section	54
•	Added 4-bit word bullet to the Watchdog Token Request definition list in the Watchdog-Timer-Related SPI Event	<u>.</u>
	Definitions section	<u>55</u>
•	Added 32-bit word bullet to the Watchdog Token Timer Request definition list in the Watchdog-Timer-Related SPI Event Definitions section	55
•	Added Watchdog Token-Response Sequence Run section to replace the Watchdog Timer Configuration for	<u></u>
	Question and Answer Configuration section	<u>55</u>
•	Changed the WDT Token and Response Sequence Run image in the Watchdog Token-Response Sequence Run section	56
•	Added the 4-bit question paragraph to the Watchdog Token Value Generation (or Watchdog Question	<u> </u>
	Generation) section	<u>57</u>
•	Added the Watchdog TOKEN Generation image and following text in the Watchdog Timer Configuration for Question and Answer Configuration section	58
•	Added Answer Comparison and Reference Answer section	60
•	Changed WDT answer column header names - switched response 0 and response 3, switched response 2 and	
	response 1 in the Set of 4-Bit WD Token Values and Corresponding 8-Bit Responses table. Added token registerDevice Configuration Register Protection name and value to token column.	61
•	Added Watchdog Token-Response Sequence Run and WDT_STATUS Register Updates section	62
•	Added activation and deactivation paragraph in the MCU Error Signal Monitor (MCU ESM) section	<u>62</u>
•	Added DIAGNOSTIC and ACTIVE state paragraph in the <i>MCU Error Signal Monitor (MCU ESM)</i> section Added deglitched and snychronized paragraph in the <i>MCU Error Signal Monitor (MCU ESM)</i> section	<u>63</u> 63
•	Added ERROR/WDI pin implementation text in the MCU Error Signal Monitor (MCU ESM) section	<u>63</u>
•	Added the first paragraph in the PWM Mode section and added the detect and no detect statements	<u>65</u>
•	Added monitoring lists to the PWM Mode section	<u>65</u>
-	detection to the <i>PWM Mode</i> section	66
•	Added CFG_CRC_ERR flag text to the Device Configuration Register Protection section	67
•	Changed CRC-8 polynomial from X8 + X7 + X6 + X4 + X2 + 1 to X8 + X2 + X1 + 1 in the <i>Device Configuration</i> <i>Register Protection</i> section	67
•	Added 64-bit string text and protected registers list in the <i>Device Configuration Register Protection</i> section	67
•	Added CRC Bus Structure table in the Device Configuration Register Protection section	
•	Added CRC calculation text, image, and table in the <i>Device Configuration Register Protection</i> section	
•	Changed the Reset and Enable Circuit image in the Enable and Reset Driver Circuit section	
•	Added ENDRV pulled low paragraph to the Enable and Reset Driver Circuit section	70
•	Changed timing-response diagram description from RESET condition to any VDDx UV or OV condition in the Enable and Reset Driver Circuit section	71
•	Added RESET condition image in the <i>Enable and Reset Driver Circuit</i> section and replaced it with the any VDDx	<u></u>
	UV or OV condition image	<u>71</u>
•	Changed <i>Device Controller State Diagram</i> image Changed <i>IGN and CANWU driven low</i> bullet item to deglitched IGN, IGN_PWRL, and CANWU_L with values in	<u>72</u>
-	the STANDBY STATE section	73
•	Added Internal NPOR (power-on reset) bullet item in the STANDBY STATE section	73
•	Added ramping up sub-bullet to the first item in the <i>RESET STATE</i> list	
•	Deleted the ACTIVE state bullet in the RESET STATE list	
•	Added watchdog fail counter text to the watchdog reset sub-bullet in the <i>RESET STATE</i> list	

TPS65381-Q1 SLVSBC4F - MAY 2012 - REVISED MAY 2016 TEXAS INSTRUMENTS

www.ti.com

٠	Added VDD5 sub-bullet in the RESET STATE list	
•	Added RESET State transition paragraph to the RESET STATE list	73
•	Added NRES pulled up to the Enters RESET state bullet in the DIAGNOSTIC STATE list	73
•	Added VSOUT1, watchdog and ERROR/WDI, watchdog failure counter, and ENDRV pin bullets in the	
	DIAGNOSTIC STATE list	73
•	Added DIAG_EXIT_MASK and DIAG_EXIT text to the end of the DIAGNOSTIC STATE list	73
•	Changed two bullets in the ACTIVE STATE list and added three additional bullets	74
•	Added ACTIVE state read-back error, stays in Safe state, NRES, and VDDx bullets in the SAFE STATE list	74
•	Added uncontrolled transition sub-bullet to the enters DIAGNOSTIC state bullet in the SAFE STATE list	
•	Added STATE TRANSITION PRIORITIES section	75
•	Deleted Enters from RESET, DIAGNOSTIC, or ACTIVE state after ABIST or LBIST failure bullet from the SPI 4-	
		75
٠	Changed speed from 10 to 6 Mbit/s in the SPI Interface section	75
٠	Added minimum time sentence to paragraph after the SPI Command Transfer Phase table	
•	Deleted paragraph describing the possibility of mixing two access modes in the SPI Data-Transfer Phase section	76
•	Added minimum time sentence to paragraph after the SPI Data-Transfer Phase table	76
•	Added status bit paragraph and note after the Device Status Flag Byte Response table	76
•	Changed D5 from 0 to 1 in the DEV_REV Register table	78
٠	Changed D0 from 0 to 1 in the DEV_REV Register table	78
•	Changed D0 from 0 to 1 in the DEV_ID Register table	78
٠	Changed reset value text to D[1] and D[0] descriptions in the DEV_STATE Register table	<u>78</u>
٠	Changed D6 from MASK_VDD_OV and 1 to nMASK_VDD_UV_OV and 0 in the DEV_CFG1 Register table	79
٠	Added ground and no ground to the SEL_VDD3/5 description for both 5 V and 3.3 V in the DEV_CFG1 Register	
	table	<u>79</u>
•	Added value in RESET State text in the DEV_CFG1 Register table	
•	Added READ-ONLY the DEV_CFG1 Register table	
•	Added after first start-up text to D[6] if VDD1 text in the DEV_CFG1 Register table	
•	Switched the names of D5 and D4 in DEV_CFG2 Register table	<u>79</u>
•	Changed EN_VDD3/5_OT description by removing extra text after set to 1 and adding two more bullets in the	
		79
•		<u>79</u>
•	Changed AVDD_VMON_ERR description from error status to power-good status in the VMON_STAT_1	00
	Register table	<u>80</u>
•	• • • •	80
	Changed set to 1 text of D[0] in the VMON_STAT_1 Register table fro	80
•	Changed m when error is detected to when voltage monitor > main band gap	
•	Changed name of D6 from VDD3_ILIM to VDD3_5_ILIM in the SAFETY_STAT_1 Register table	
•	Added note to D[7] description in the SAFETY_STAT_1 Register table	
•	Added EEPROM bullet to D[5] description in the SAFETY_STAT_2 Register table	
•	Added DIAGNOSTIC and ACTIVE State text to D[2:0] default bullet in the SAFETY_STAT_2 Register table	
•	Added cleared to text to the D[5] description in the SAFETY_STAT_3 Register table	
•	Changed D7 and D6 from 1 to 0 in the SAFETY_STAT_4 Register table	
•	Changed name of D0 from TRIM_ERR to TRIM_ERR_VMON in the SAFETY_STAT_4 Register table	85
•	Added also and the bullet and mate to DIZ 01 description in the OAFFTY OTAT A Design tentels	
	Added cleared to bullet and note to D[7:6] description in the SAFETY_STAT_4 Register table	85
•	Changed set to text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register	<u>85</u>
•	Changed set to text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register table	85
•	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register table	85
	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register table	<u>85</u> 85
•	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register table	85 85 85
•	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4</i> <i>Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table	85 85 85 85 85
• • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the SAFETY_STAT_4 Register table Added ERROR_PIN_FAIL text to D[3] cleared description in the SAFETY_STAT_4 Register table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the SAFETY_STAT_4 Register table Deleted SPI read access from D[1] <i>cleared to</i> description in the SAFETY_STAT_4 Register table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the SAFETY_STAT_4 Register table	85 85 85 85 85 85 85
• • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4</i> <i>Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table	85 85 85 85 85 85 85 85 85
• • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4</i> <i>Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table Changed threshold from max to min for the 0000 setting description in the <i>SAFETY_ERR_CFG Register</i> table	85 85 85 85 85 85 85 85 85 86
• • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4</i> <i>Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table Changed threshold from max to min for the 0000 setting description in the <i>SAFETY_ERR_CFG Register</i> table Changed D7 and D6 from 1 to 0 in the <i>SAFETY_BIST_CTRL Register</i> table	85 85 85 85 85 85 85 85 85 85 86 87
• • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4</i> <i>Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table Changed threshold from max to min for the 0000 setting description in the <i>SAFETY_ERR_CFG Register</i> table Changed D7 and D6 from 1 to 0 in the <i>SAFETY_BIST_CTRL Register</i> table Changed D3 from LOCLK_EN to RSV in the <i>SAFETY_BIST_CTRL Register</i> table	85 85 85 85 85 85 85 85 85 85 86 87 87
• • • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4 Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table Changed threshold from max to min for the 0000 setting description in the <i>SAFETY_ERR_CFG Register</i> table Changed D7 and D6 from 1 to 0 in the <i>SAFETY_BIST_CTRL Register</i> table Changed D3 from LOCLK_EN to RSV in the <i>SAFETY_BIST_CTRL Register</i> table	85 85 85 85 85 85 85 85 85 86 87 87 87 87
• • • • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table	85 85 85 85 85 85 85 85 85 86 87 87 87 87 87
• • • • •	Changed <i>set to</i> text to include error-signal monitoring in the D[3] description in the <i>SAFETY_STAT_4 Register</i> table Added ERROR_PIN_FAIL text to D[3] cleared description in the <i>SAFETY_STAT_4 Register</i> table Added Watchdog Fail Counter text to the D[2] <i>set to</i> and <i>cleared to</i> descriptions in the <i>SAFETY_STAT_4 Register</i> table Deleted SPI read access from D[1] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed SPI read access to NPOR in the D[0] <i>cleared to</i> description in the <i>SAFETY_STAT_4 Register</i> table Changed D4 from 1 to 0 and D1 and D0 from 0 to 1 in the <i>SAFETY_STAT_5 Register</i> table Changed threshold from max to min for the 0000 setting description in the <i>SAFETY_ERR_CFG Register</i> table Changed D7 and D6 from 1 to 0 in the <i>SAFETY_BIST_CTRL Register</i> table Changed D3 from LOCLK_EN to RSV in the <i>SAFETY_BIST_CTRL Register</i> table	85 85 85 85 85 85 85 85 85 86 87 87 87 87 87

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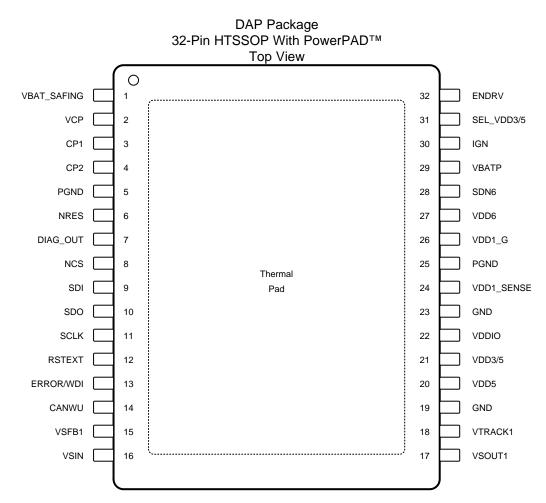
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	table	88
•	Added device state, ENDRV and NRES to D[6] description in the SAFETY_CHECK_CTRL Register table	88
•	Changed D[3] from not read/writable to read/writable in the SAFETY_CHECK_CTRL Register table	88
•	Added ERROR_PIN_FAIL sub-bullet to D[2] descriptionin the SAFETY_CHECK_CTRL Register table	88
•	Changed D7 from 0 to 1 in the SAFETY_FUNC_CFG Register table	89
•		89
•	Changed D0 from 0 to X in the SAFETY_FUNC_CFG Register table	
•	Added SAFE state-time sub-bullet to the D[7] description in the SAFETY_FUNC_CFG Register table	
•	Changed D[6] description from error-pin to Error-Signal Monitor in the SAFETY_FUNC_CFG Register table	
•	Deleted watchdog pin from the D[6] description in the SAFETY_FUNC_CFG Register table	89
•	Added note text to the D[4] description in the SAFETY_FUNC_CFG Register table	
•	Added STANDBY state text to the D[4] description in the SAFETY_FUNC_CFG Register table	
•	Deleted <i>enabling/disabling the watchdog</i> bullet from the D[3] description in the SAFETY_FUNC_CFG Register	00
	table	89
•	Added bullets to the D[2] description in the SAFETY_FUNC_CFG Register table	
•	Changed D[1] from not read/writable to read/writable in the SAFETY_FUNC_CFG Register table	
•	Added READ-ONLY bullet, RESET STATE sub-bullet, and connected and not-connected text to the D[0]	03
•	description in the SAFETY_FUNC_CFG Register table	89
•	Added ERROR/WDI and SAFE state text to the D[5] set to description in the SAFETY_ERR_STAT Register table.	
•	Added WD_RST_EN text to D[4] set to description in the SAFETY_ERR_STAT Register table	<u>90</u>
•	Added watchdog fail counter text to D[4] <i>cleared to</i> description in the SAFETY_ERR_STAT Register table	<u>90</u> 90
	Added equation and oscillator text to the SAFETY_ERR_PWM_H Register table description	
•	Changed D4, D2, and D0 from 0 to 1 in the SAFETY_ERR_PWM_L Register description	
	Added equations and oscillator text to the SAFETY_ERR_PWM_H Register table description Changed D4 from 1 to 0 in the SAFETY_PWD_THR_CFG Register table	
•	Changed _THR to PWD names for D3:D0 in the SAFETY_PWD_THR_CFG Register table	
	Changed D7, D5, and D3 from 1 to 0 in the SAFETY_CFG_CRC Register table	
•	Changed D4 from 0 to 1 in the SAFETY_CFG_CRC Register table	
•	Changed D[7] description from high-impedance to tri-stated in the DIAG_CFG_CTRL Register table	
•	Added SDO diagnostics from D[1:0] description to the D[6] description in the DIAG_CFG_CTRL Register table	
	Changed D2 from 1 to 0 in the WDT_TOKEN_FDBCK Register table	
•	Added bullets to the D[7:4] description in the WDT_TOKEN_FDBCK Register table	
•	Added new TOKEN seed bullet and sub-bullets to the D[3:0] description in the WDT_TOKEN_FDBCK Register	<u>93</u>
•	table	93
•	Changed D6:D0 from 0 to 1 in the WDT_WIN1_CFG Register table	
•	Changed D4:D3 from 0 to 1 in the WDT_WIN2_CFG Register table	
	Changed D7 from 0 to 1 in the WDT_TOKEN_VALUE Register table	
•	Changed MCU sub-bullet from D[7] description to replace Q&A sub-bullet in the D[3:0] description of the	<u>94</u>
-		94
•	Changed D7:D6 from 0 to 1 in the WDT_STATUS Register table	
•	Changed D7:D6 from RSV to WD_WRONG_CFG in the WDT_STATUS Register table	
	Changed set to text of the D[5] description in the WDT_STATUS Register table	
	Changed D[4] note from recommendation to clear bit to remains set to 1 in the SENS_CTRL Register table	
	Added 8-bit hex column to the SPI Command Table	95 96
		<u>96</u> 99
•	Changed Typical Application Diagram image	<u>99</u>

## 3 Pin Configuration and Functions

The pin configuration drawing in this section is not to scale. For package dimensions, see the mechanical data in Section 10.



### **Pin Functions**

	PIN TYPE		DECODIDATION		
NO.	NAME	ITPE	DESCRIPTION		
1	VBAT_SAFING	PWR	Battery (supply) input for monitoring (VMON) and BG2 functions (must be reverse protected), should be connected to VBATP		
2	VCP	PWR	Charge-pump output voltage		
3	CP1	PWR	Charge-pump external capacitor, high-voltage side		
4	CP2	PWR	Charge-pump external capacitor, low-voltage side		
5	PGND	GND	Ground (power)		
6	NRES	0	Cold-reset (NPOR_RST) output signal for the microcontroller (µC)		
7	DIAG_OUT	0	Diagnostic MUX output for MCU ADC and digital IO (multiplexed analog and digital signal output)		
8	NCS	_	SPI chip select (active-low)		
9	SDI	-	SPI serial data IN		
10	SDO	0	SPI serial data OUT		
11	SCLK	-	SPI clock		
12	RSTEXT	I	Configuration pin for reset extension		
13	ERROR/WDI		Error input signal from MCU / window watchdog input trigger		

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## Pin Functions (continued)

PIN		TYPE	DECODIDION	
NO.	NAME	ITPE	DESCRIPTION	
14	CANWU	Ι	Wake-up input signal from CAN transceiver	
15	VSFB1	Ι	Feedback input reference for sensor supply regulator	
16	VSIN	PWR	Sensor-supply regulator (VSOUT1) input supply voltage	
17	VSOUT1	PWR	Sensor-supply regulator output voltage	
18	VTRACK1	Ι	Tracking input reference for sensor-supply regulator (VSOUT1)	
19	GND	GND	Ground (analog)	
23	GND	GND	Ground (analog)	
20	VDD5	PWR	VDD5 regulator output voltage	
21	VDD3/5	PWR	VDD3/5 regulator output voltage	
22	VDDIO	PWR	evel for pins to and from the MCU	
24	VDD1_SENSE	ļ	reference for VDD1 regulator (feedback) and input for UV/OV monitoring of VDD1 tor	
25	PGND	GND	bund (power)	
26	VDD1_G	0	Gate drive of external FET for VDD1 regulator	
27	VDD6	PWR	VDD6 switch-mode regulator feedback input and supply input for integrated VDD5 and VDD3/5 regulators	
28	SDN6	PWR	Switching node for VDD6 switch-mode regulator	
29	VBATP	PWR	Battery (supply) voltage (must be reverse protected), main power supply input for device	
30	IGN	Ι	Wake-up signal from ignition (key) or other source	
31	SEL_VDD3/5	I	Input selects voltage level for VDD3/5 regulator (SEL_VDD3/5 pin open: 3.3-V regulation from VDD3/5, SEL_VDD3/5 pin GND: 5-V regulation from VDD3/5)	
32	ENDRV	0	Enable output signal for peripherals (for example, motor-driver IC).	
_	Thermal pad	_	Place thermal vias to large ground plane and connect to GND and PGND pins.	

## 4 Specifications

## 4.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

POS			MIN	MAX	UNIT
M1.1	Protected-battery voltage	VBATP, VBAT_SAFING, VSIN	-0.3	40	V
M1.2	Charge-pump voltage	VCP, CP1	-0.3	52	V
M1.3	Charge-pump pumping capacitor voltage	CP2	-0.3	40	V
M1.3a	Charge-pump overdrive voltage	VCP-VBATP	-0.3	16	V
M1.4	VDD6 switching-node voltage	SDN6	-0.3	40	V
M1.5	VDD6 output voltage	VDD6	-0.3	40	V
M1.6	VDD5 output voltage	VDD5	-0.3	7	V
M1.7	VDD3/5 output voltage	VDD3/5	-0.3	7	V
M1.8	VDD1_G voltage	VDD1_G	-0.3	15	V
M1.10	VDD1_SENSE voltage	VDD1_SENSE	-0.3	7	V
M1.11	Sensor supply tracking voltage	VTRACK1	-0.3	40	V
M1.12	Sensor supply feedback voltage	VSFB1	-2	40	V
M1.13	Sensor supply output voltage	VSOUT1	-2	40	V
M1.14	Analog/digital ref. output voltage	DIAG_OUT	-0.3	7	V
M1.15	Logic I/O voltage	VDDIO, ERROR/WDI, ENDRV, NRES, NCS, SDI, SDO, SCLK, RSTEXT	-0.3	7	V
M1.16		SEL_VDD3/5	-0.3	40	V
M1.17	IGN wake-up	IGN	-7	40	V
M1.18	CAN wake-up	CANWU	-0.3	40	V
M1.19	Operating virtual junction temperat	ure range, T <sub>J</sub>		150	°C
	Storage temperature, T <sub>stg</sub>		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the network ground pin unless otherwise noted.

## 4.2 ESD Ratings

POS.					VALUE	UNIT
M1.21	V <sub>(ESD)</sub> Electrostatic discharge			All pins except VSOUT1 (17) and VSFB1 (15)	±2000	
M1.20		Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	On sensor supply pins VSOUT1 (17) and VSFB1 (15)	±4000	V	
M1.22		Vison	Charged device model (CDM) per AEC 0400 011	Corner pins (1, 16, 17, and 32)	±750	
M1.23			Charged device model (CDM), per AEC Q100-011	All pins	±500	

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 Specification



## 4.3 Recommended Operating Conditions

Over operating temperature range and with respect to the GND and PGND (GND = PGND) pins (unless otherwise noted)

POS		MIN	MAX	UNIT
M1.20a	Operating ambient temperature, T <sub>A</sub>	-40	125	°C
R1.1	Input supply voltage on VBATP pins for initial power up	5.8		V
R1.2	Input supply voltage on VBATP <sup>(1)</sup> – VSOUT1 configured as 5 V or higher, VDD3/5 configured as 5 V and VDD5 regulators are in undervoltage when VBATP is between 5.8 V and 6.6 V. – The VDD3/5 regulator undervoltage event causes NRES to be pulled low	5.8 <sup>(1)</sup>	36	V
R1.3	Input supply voltage on VBATP – VDD6, VDD5 regulators in low dropout, VDD3 and VDD1 regulator outputs functional (no undervoltage). VSOUT1 either functional or in low dropout, depending on configuration.	4.5		V
R1.3a	Input supply voltage for VBAT_SAFING (when below minimum, device does not start up and NRES, ENDRV is pulled low)	4.2	36	V
R1.3b	Input supply voltage on VBAT_SAFING for normal operation	5.8	36	V
R1.4	VDDIO supply-voltage range	3.3	5	V
R1.5	Current consumption in standby mode (all regulator outputs disabled) IGN = 0 V, CANWU = 0 V, 5.8 V $\leq$ VBAT $\leq$ 20 V for T <sub>J</sub> $<$ 85°C or 5.8 V $\leq$ VBAT $\leq$ 14 V tor T <sub>J</sub> = 125°C		75	μA

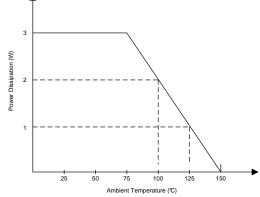
(1) Under slow VBAT ramp-down and when VDD3/5 rails is configured as a 5-V rail, the NRES output can be pulled low when VBAT is at approximately 6.3 V. This occurs because of an undervoltage transient on the VDD3/5 rail. Under slow VBAT ramp-up and when VDD3/5 rail is configured as a 5-V rail, the NRES output can be pulled low when VBAT is at approximately 6.6 V. This occurs because of an undervoltage transient on VDD3/5 rail. Under similar conditions, undervoltage transients are observed on VDD5 and VSOUT1 rails (refer to the Application Report, *Device Behavior Under Slow VBAT Ramp-Up and Ramp-Down*, SLVA643).

#### 4.4 Thermal Information

		TPS65381-Q1	
	THERMAL METRIC <sup>(1)</sup>	DAP (HTSSOP)	UNIT
		32 PINS	
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	31.4	°C/W
R <sub>0JCtop</sub>	Junction-to-case (top) thermal resistance	14.3	°C/W
$R_{ extsf{ heta}JB}$	Junction-to-board thermal resistance	15.3	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	0.3	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	15.2	°C/W
R <sub>θJCbot</sub>	Junction-to-case (bottom) thermal resistance	0.6	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.





- (1) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature ( $T_Amax$ ) is dependent on the maximum operating junction temperature ( $T_Jmax$ ), the maximum power dissipation of the device in the application ( $P_Dmax$ ), and the junction-to-ambient thermal resistance of the part/package in the application ( $R_{\theta JA}$ ), as given by the following equation:  $T_Amax = T_Jmax (R_{\theta JA} \times P_Dmax)$ .
- (2) Maximum power dissipation is a function of  $T_Jmax$ ,  $R_{\theta JA}$  and  $T_A$ . The maximum-allowable power dissipation at any allowable ambient temperature is  $P_D = (T_Jmax T_A) / R_{\theta JA}$ .

#### Figure 4-1. Derating Profile for Power Dissipation Based on High-K JEDEC PCB

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## 4.5 Electrical Characteristics

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and with VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VDD6-E	BUCK With Interr	nal FET					
AN	C <sub>VDD6</sub>	Value of output ceramic capacitor <sup>(1)</sup>	ESR range 100 m $\Omega$ to 300 m $\Omega^{(2)}$	22		47	μF
AN	L <sub>VDD6</sub>	Value of inductor		22	33		μH
1.1	VDD6	VDD6 output voltage	Average DC value excluding ripple and load transients, VBAT > 7 V, 0 < $I_{VDD6}$ < 1.3 A, including dc line and load regulation, temperature drift, and long-term drift where VBAT = VBATP = VBAT_SAFING	-10%	6	10%	V
1.1a	VDD6 <sub>ripple</sub>	VDD6 ripple voltage	Peak-to-peak, ensured by design VBATP = VBAT_SAFING = 14 V, L = 33 $\mu$ H, C = 22 $\mu$ F		200		mV
1.2	I <sub>VDD6</sub>	VDD6 output current $I_{VDD5} + I_{VDD3} + I_{VDD1} + I_{VSOUT1}^{(3)}$				1.3	А
1.3	V <sub>dropout6</sub>	VDD6 output dropout voltage $V_{dropout6} = (VBATP - SDN6)$	$I_{VDD6} = 1.3 \text{ A}$ (example: $R_{DS(on)} = 0.46 \Omega$ )			0.6	V
1.4	I <sub>VDD6_limit</sub>	Peak current out of SDN6 pin		1.5		2.5	А
1.5	$f_{\rm clk\_VDD6}$	Clock Frequency (4)		-10%	440	10%	kHz
1.6	DC <sub>VDD6</sub>	t <sub>or</sub> /t <sub>period</sub>	0 < I <sub>VDD6</sub> < 1.3 A VDD6 enters dropout mode for VBATP < 7 V	7%		100%	
1.7	Torot	Temperature protection threshold <sup>(5)</sup>		175		210	°C
1.7	Tprot <sub>VDD6</sub>	Hysteresis		10		20	°C
VDD5 –	LDO With Interr	nal FET					
AN	C <sub>VDD5</sub>	Value of output ceramic capacitor	ESR range 0 m $\Omega$ to 100 m $\Omega$	1		5	μF
2.1	VDD5	VDD5 output voltage <sup>(6)</sup>	0 < I <sub>VDD</sub> 5 < 300 mA	-2%	5	2%	V
2.2	I <sub>VDD5</sub>	VDD5 output current, including load from the internal resistor of 660 $\Omega$ (typ.)				300	mA
2.3	VDD5 <sub>dyn</sub>	VDD5 output voltage dynamic	Load step 10% to 90% in 1 $\mu$ s, with 5- $\mu$ F C <sub>VDD5</sub>	4.85	5	5.15	V
2.4	VDD5 <sub>max</sub>	Maximum VDD5 output voltage during VBATP step from 5.5 V to 13.5 V within 10 µs	$C_{VDD5}$ = 5 µF, I <sub>VDD5</sub> < 300 mA			5.5	V
2.5	V <sub>dropout5</sub>	VDD5 output dropout voltage $V_{dropout5} = (VDD6-VDD5)$	I <sub>VDD5</sub> < 300 mA			0.3	V
2.6	PSRR <sub>VDD5</sub>	Power supply rejection ratio	$\begin{array}{l} 50 < f < 20 \text{ kHz,VBATP} = 10 \text{ V, U} = 4 \text{ Vpp,} \\ C_{\text{VDD5}} = 5 \mu\text{F}, 0 < I_{\text{VDD5}} < 300 \text{ mA} \end{array}$	40			dB
2.7	LnReg <sub>VDD5</sub>	Line regulation ( $I_{VDD5}$ constant)	0 < I <sub>VDD5</sub> < 300 mA, 8 V < VBATP < 19 V	-25		25	mV
2.8	LdReg <sub>VDD5</sub>	Load regulation (VDD6 constant)	0 < I <sub>VDD5</sub> < 300 mA, 8 V < VBATP < 19 V	-25		25	mV
2.9	TmpCo <sub>VDD5</sub>	Temperature drift	Normalized to 25°C value	-0.5%		0.5%	
2.11	dVDD5/dt	dV/dt at VDD5 at startup	Between 10%-90% of VDD5 end-value	5		50	V/ms
0.40	Trat	Temperature protection threshold <sup>(7)</sup>		175		210	°C
2.13	Tprot <sub>VDD5</sub>	Hysteresis		10		20	°C
2.14	I <sub>VDD5_limit</sub>	Current-limit		350		650	mA

(1) Capacitance is effective capacitance after derating for operating voltage, temperature and lifetime.

(2) ESR is total effective series resistance of the capacitors and if necessary added series resistor.

(3) I<sub>VDD6</sub> is the load current from VDD5, VDD3\_5, VDD1 and VSOUT1 on VDD6 regulator; VDD6 is not recommended to be loaded directly for applications or peripherals that cannot operate with wider tolerance and ripple since VDD6 is a pre-regulator. However, LDOs or DC-DC converters may be connected directly as along as the total load current on VDD6, I<sub>VDD6</sub>, does not exceed the specification for VDD6 load current.

(4) Actual switching on SND6 depends on whether output voltage on VDD6 is above or below PWM comparator threshold at the moment of the rising edge of the  $F_{clk\_VDD6}$  clock.

(5) Protection of VDD6, shared with VDD3/5 thermal protection.

(6) VDD5 output regulation includes line and load regulation, temperature drift.

(7) Protection of VDD5. In case of detected over-temperature, only VDD5 will be switched-off.

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and with VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
VDD3/5	- LDO With Inter	nal FET	1					
AN	C <sub>VDD3/5</sub>	Value of output ceramic capacitor	ESR range 0 m $\Omega$ to 100 m $\Omega$		1		5	μF
3.1	VDD3/5	VDD3/5 output voltage, SEL_VDD3/5 pin: open = 3.3 V setting, ground = 5 V setting	0 < I <sub>VDD3/5</sub> < 300 mA		-2%	3.3 5	+2%	v
3.2	I <sub>VDD3/5</sub>	VDD3/5 output current, including load from the internal resistor of 440 $\Omega$ (typ.) for 3.3 V setting or 660 $\Omega$ (typ.) for 5 V setting				300	mA	
3.3	VDD3/5 <sub>dyn</sub>	VDD3/5 output voltage dynamic	Load step 10% to 90% in 1 $\mu s,$ with 5 $\mu F$ $C_{\text{VDD3/5}}$	3.17 4.85	3.3 5	3.43 5.15	v	
3.4	VDD3/5 <sub>max</sub>	Maximum VDD3/5 output voltage during VBATP step from 5.5 V to 13.5 V within 10 $\mu s$	$C_{VDD3/5} = 5 \ \mu F, \ I_{VDD3/5} < 300 \ mA$			3.6 5.5	V	
3.5	Vdropout3/5	VDD3/5 output dropout voltage Vdropout3/5= (VDD6- VDD3/5)	I <sub>VDD3/5</sub> < 300 mA	5 V Setting			0.3	v
3.6	PSRR <sub>VDD3/5</sub>	Power-supply rejection ratio	$\begin{array}{l} 50 < f < 20 \text{ kHz}, \text{VBATP} = 10 \text{ V}, \text{ U} = 4 \text{ Vpp} \\ C_{\text{VDD3/5}} = 5  \mu\text{F},  0 < \text{I}_{\text{VDD3/5}} < 300 \text{ mA} \end{array}$		40			dB
3.7	LnReg <sub>VDD3/5</sub>	Line regulation ( $I_{VDD3}$ constant)	0 < I <sub>VDD3/5</sub> < 300 mA, 8 V < VBATP < 19 V		-25		25	mV
3.8	LdReg <sub>VDD3/5</sub>	Load regulation (VDD6 constant)	0 < I <sub>VDD3/5</sub> < 300 mA 8 V < VBATP < 19 V		-25		25	mV
3.9	TmpCo <sub>VDD3/5</sub>	Temperature drift	Normalized to 25°C value		-0.5%		0.5%	
3.11	dVDD35/dt	dV/dt at VDD3/5 at start-up	Between 10%-90% of VDD3/5 end-value 5 V Setting				30 50	V/ms
	_	Temperature protection threshold <sup>(8)</sup>			175		210	°C
3.13	Tprot <sub>VDD3/5</sub>	Hysteresis			10		20	°C
3.14	I <sub>VDD3_5_limit</sub>	Current-limit			350		650	mA
3.15	Ipu_SEL_VDD3/5	Pullup current on SEL_VDD3/5 pin					20	μA
VDD1 –	LDO With Extern	nal FET	1					
AN	Vgs(th)	Gate threshold voltage, external FET	ID = 1 mA		0.3		3	V
AN	Ciss	Gate capacitance, external FET	VGS = 0 V				3200	pF
AN	Qgate	Gate Charge ext. FET	VGS = 0 V to 10 V				70	nC
AN	gfs	Forward transconductance, external FET	ID = 50 mA		0.4			S
AN	C <sub>VDD1</sub>	Value of output ceramic capacitor	ESR range 0 m $\Omega$ to 100 m $\Omega$		5		40	μF
4.1	VDD1	VDD1 output voltage, depends on external resistive divider			0.8		3.3	V
4.2	VDD1 <sub>SENSE</sub>	VDD1 reference voltage <sup>(9)</sup>	10 mA < I <sub>VDD1</sub> < 600 mA		-1%	0.8	2%	V
4.3	I <sub>VDD1</sub>	VDD1 output current	Minimum current realized with external resisti	ve divider	10		600	mA
4.4	VDD1 <sub>G</sub>	VDD1_G output voltage	Referenced to GND				15	V
4.5	VDD1 <sub>G_off</sub>	VDD1_G voltage in OFF condition	20 μA into VDD1_G pin				0.3	V
4.6	I_VDD1 <sub>G</sub>	VDD1_G DC load current					200	μΑ
4.7	VDD1 <sub>dyn</sub>	VDD1 output voltage dynamic	Load step 10% to 90% in 1 $\mu s,$ with 40 $\mu F$ $C_{_V}$	DD1	-4%		4%	V
4.8	VDD1 <sub>max</sub>	Maximum VDD1 output voltage during VBATP step from 5.5 V to 13.5 V within 10 $\mu s$	$C_{VDD1} > 6 \ \mu F, \ I_{VDD1} < 600 \ mA$				10%	V
4.9	PSRR <sub>VDD1</sub>	Power-supply rejection ratio	$\begin{array}{l} 50 < f < 20 \text{ kHz}, \text{VBATP} = 10 \text{ V}, \text{ U} = 4 \text{ Vpp}, \\ C_{\text{VDD1}} = 10  \mu\text{F}, \text{ 10 mA} < I_{\text{VDD1}} < 600 \text{ mA} \end{array}$	-	40			dB
4.10	LnReg <sub>VDD1</sub>	Line regulation on VDD1_SENSE ( $I_{VDD1}$ constant)	10 mA < <sub>IVDD1</sub> < 600 mA, 8 V < VBATP < 19 V				7	mV
4.11	LdReg <sub>VDD1</sub>	Load regulation on VDD1_SENSE (VDD6 constant)	10 mA < I <sub>VDD</sub> 1 < 600 mA, 8 V < VBATP < 19 V				7	mV
4.12	TmpCo <sub>VDD1</sub>	Temperature drift	Normalized to 25°C value				0.5%	
4.14	dVDD1/dt	dV/dt at VDD1_SENSE at start-up	Between 10%-90% of VDD1 end-value		0.8		8	V/ms
VSOUT1	- LDO With Pro	tected Internal FET						
AN	C <sub>VSOUT1</sub>	Value of output ceramic capacitor	ESR range 0 m $\Omega$ to 100 m $\Omega$		0.5		10	μF
5.1	VSOUT1	VSOUT1 output voltage, depends on external resistive divider and tracking or non-trakcing mode			3.3		9.5	v

(8) Protection of VDD3/5, treated as global thermal shutdown (shutdown for all regulators).

(9) VDD1 regulation including line and load regulation, temperature drift and long-term drift. Does not include tolerance of resistor divider to set VDD1 output voltage.

Over operating ambient temperature  $T_A = -40^{\circ}C$  to the maximum-operating junction temperature  $T_J = 150^{\circ}C$ , and with VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
5.2	MV <sub>VSOUT1</sub>	For tracking mode: Matching output errorMV <sub>VSOUT1</sub> = (VTRACK1 – VSFB1) <sup>(10)</sup>	0 < I <sub>VSOUT1</sub> < 100 mA	0 < I <sub>VSOUT1</sub> < 100 mA			25	mV
5.3	VSFB1	For non-tracking mode: VSOUT1 reference voltage <sup>(11)</sup>	10 mA < I <sub>VSOUT1</sub> < 100 mA	-2%	2.5	2%	V	
5.3a	VTRACK1 <sub>th</sub>	Threshold for selecting tracking/non-tracking mode (VTRACK1 > VTRACK1 <sub>th_max</sub> V for tracking mode, VTRACK1 < VTRACK1 <sub>th_min</sub> V non-tracking mode)			1.1	1.2	1.3	V
5.3b	VTRACK1 <sub>pd</sub>	Internal pulldown resistance on VTRACK1 pin				100		kΩ
5.4	I <sub>VSOUT1</sub>	VSOUT1 output current, including internal resistor to dissipate minimum current					100	mA
5.5	VdrS1	VSOUT1 dropout voltage VdrS1 = (VSIN-VSOUT1)	0 < I <sub>VSOUT1</sub> < 100 mA				0.75	V
5.6	PSRR <sub>VSOUT1</sub>	Power-supply rejection ratio			40			dB
5.7	LnReg <sub>VSOUT1</sub>	Line regulation (I <sub>VSOUT1</sub> constant)	0 < I <sub>VSOUT1</sub> < 100 mA, 8 V < VSIN < 19 V		-25		25	mV
5.8	LdReg <sub>VSOUT1</sub>	Load regulation (VSIN constant)	0 < I <sub>VSOUT1</sub> < 100 mA, 8 V < VSIN < 19 V		-35		35	mV
5.9	TmpCo <sub>VSOUT1</sub>	Temperature drift	Normalized to 25°C value		-0.5%		0.5%	
5.11	VSOUT1 <sub>SH</sub>	Output short circuit voltage range			-2		40	V
5.12	-I <sub>VSIN</sub>	Output reverse current	VSOUT1 = 14 V and VBATP = 0 V, regulator	switched off			20	mA
		Temperature protection threshold <sup>(12)</sup>			175		210	°C
5.13	Tprot <sub>VSOUT1</sub>	Hysteresis			10		20	°C
5.14	I <sub>VSOUT1_limit</sub>	Current-limit			100		500	mA
Voltage	e Monitoring							
6.1	VBATP_UV <sub>off</sub>	VBATP and VBAT_SAFING level for indication by VBAT_UV comparitor <sup>(13)</sup>	VBATP = VBAT_SAFING		4.2		4.5	V
6.2	VBATP_UVon	VBATP and VBAT_SAFING level for indication by VBAT_UV comparitor <sup>(13)</sup>	VBATP = VBAT_SAFING	5.4		5.8	V	
6.3	VBATP_UV <sub>hys</sub>	Undervoltage hysteresis	VBATP = VBAT_SAFING				1.4	V
6.4	VBATP_OV <sub>rise</sub>	VBATP level for setting VBAT_OV flag <sup>(14)</sup>	VBATP = VBAT_SAFING		34.7		36.7	V
6.5	VBATP_OV <sub>fall</sub>	VBATP level for clearing VBAT_OV flag <sup>(15)</sup>	VBATP = VBAT_SAFING		34.4		36.3	V
		VDD5 undervoltage level	VBATP = VBAT_SAFING		4.5		4.85	V
6.8	VDD5_UV	Hysteresis	VBATP = VBAT_SAFING			140		mV
6.9	VDD5_UV <sub>head</sub>	VDD5 undervoltage headroom (VDD5act – VDD5_UVact)	VBATP = VBAT_SAFING		200			mV
		VDD5 overvoltage level	VBATP = VBAT_SAFING		5.2		5.45	V
6.10	VDD5_OV	Hysteresis	VBATP = VBAT_SAFING			140		mV
6.11	VDD5_OV <sub>head</sub>	VDD5 overvoltage headroom (VDD5_OVact – VDD5act)	VBATP = VBAT_SAFING		200			mV
		3.3-V set	3.3-V setting	3		3.17		
		VDD3/5 undervoltage level	VBATP = VBAT_SAFING	5-V setting	4.5		4.85	V
6.12	VDD3/5_UV			3.3-V setting		100		
		Hysteresis	VBATP = VBAT_SAFING 5-V setting			140		mV
		VDD3/5 undervoltage headroom		3.3-V setting	170			
6.13	VDD3/5_UVhead	(VDD3/5act – VDD3/5_UVact)	VBATP = VBAT_SAFING	5-V setting	200			mV
				3.3-V setting	3.43		3.6	
		VDD5_3 overvoltage level	VBATP = VBAT_SAFING	5-V setting	5.2		5.5	V
6.14	VDD3/5_OV			3.3-V setting	0.2	100	0.0	
		Hysteresis	VBATP = VBAT_SAFING	ATP = VBAT_SAFING		140		mV
			5-V setting		170	140		
6.15	VDD3/5_UVhead	VDD3/5 undervoltage headroom (VDD3/5 OVact – VDD3/5act)	VBATP = VBAT_SAFING					mV
5-V setting				200				

(10) Referenced to VTRACK1 input, including long-term and temperature drift.

- (11) VSOUT1 including line and load regulation, temperature drift and long-term drift.
- (12) Protection of VSOUT1 Sensor Supply. Only VSOUT1 switch-offs off.
- (13) VBATP\_UV<sub>off</sub> and VBATP\_UV<sub>on</sub> are the threshold levels for VBATP where UV will be indicated by the VBAT\_UV bit in VMON\_STAT\_1 register. The VBATP level that will allow device power up is outlined by R1.1.
- (14) Brings device into RESET state and sets flag in SPI
- (15) Clears flag in SPI

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Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and with VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
6.46	VDD1 UV	VDD1 undervoltage level	VBATP = VBAT_SAFING. Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2)	0.94		0.98	VDD1
6.16	001_00	Hysteresis	VBATP = VBAT_SAFING. Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2)		10		mV
6.17	VDD1_OV	VDD1 overvoltage level	VBATP = VBAT_SAFING. Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2)	1.03		1.06	VDD1
0.17		Hysteresis	VBATP = VBAT_SAFING. Sensed on VDD1_SENSE pin. Relative thresholds are with respect to nominal 800-mV VDD1SENSE (Pos 4.2)		9		mV
		VSOUT1 undervoltage level	Sensed on VSFB1 pin. Relative thresholds are: • for non-tracking mode with respect to nominal 2.5-V	0.88		0.94	VSOUT 1
6.19 VSOUT1_UV		Hysteresis	<ul> <li>VSFB1 (Pos 5.3)</li> <li>for tracking mode with respect to voltage applied on VTRACK1 pin.</li> <li>in tracking mode, VSOUT1_UV comparator output is valid for VTRACK1 DC condition.</li> </ul>		23		mV
		VSOUT1 overvoltage level	Sensed on VSFB1 pin. Relative thresholds are: for non-tracking mode with respect to nominal 2.5-V	1.06		1.12	VSOUT 1
6.20	VSOUT1_OV	Hysteresis	<ul> <li>VSFB1 (Pos 5.3)</li> <li>for tracking mode with respect to voltage applied on VTRACK1 pin.</li> <li>in tracking mode, VSOUT1_OV comparator output is</li> </ul>		23		mV
			valid for VTRACK1 DC condition.				
6.22	VDD6_UV	VDD6 undervoltage level <sup>(16)</sup>		5.2	445	5.4	V
		Hysteresis		7.0	115	0.0	mV V
6.23	VDD6_OV	VDD6 overvoltage level <sup>(16)</sup>		7.8	115	8.2	v mV
IGNITIC	ON and CAN WAKE-	Hysteresis UP			115		IIIV
7.1	IGN_WUP	IGN wake-up threshold <sup>(17)</sup>	VBATP = VBAT_SAFING =12 V	2		3	V
7.2	CAN_WUP	CAN wake-up threshold <sup>(17)</sup>	VBATP = VBAT_SAFING =12 V	2		3	V
7.3	WUP_hyst	Wake-up hysteresis	VBATP = VBAT_SAFING =12 V	50		200	mV
7.4	I_IGN	IGN pin forward leakage current	IGN pin at 36 V, VBATP = VBAT_SAFING = 12V			50	μA
7.5	I_IGN_rev	IGN reverse current	IGN at -7 V, VBATP = VBAT_SAFING =12 V			-1	mA
7.7	I_CANWU	CANWU pin forward leakage current	CANWU pin at 36 V, VBATP = VBAT_SAFING = 12V			50	μA
7.8	I_CAN_rev	CANWU reverse current	CANWU at -0.3 V, VBATP = VBAT_SAFING =12 V			-1	mA
Charge	-						
AN	C <sub>pump</sub>	Pumping capacitor (between CP1 and CP2)			10		nF
AN 8.1	C <sub>store</sub> VCP <sub>on</sub>	Storage capacitor (between VCP and VBATP) VCP output voltage in on-state	VBATP > 5.8 V	VBATP +	100	VBATP	nF V
8.2		External load	Load coming from R <sub>GS</sub> of Reverse Battery Protection	4		+ 15	
8.3	I <sub>CP</sub>	Charge-pump switching frequency		225	250	275	
	f <sub>CP</sub> and Enable Outputs	onargo-pump switching including	1	220	200	210	NI 12
9.1	V <sub>NRES_ENDRV_L</sub>	NRES / ENDRV low output level	With external 2-mA open-drain current			0.2	V
9.2	R <sub>NRES_ENDRV_PULLUP</sub>	NRES / ENDRV internal pullup resistance		3		6	
9.2a	R <sub>DS(on)_ENDRV_NRES</sub>	R <sub>DS(on)</sub> NRES/ENDRV pulldown transistor				40	
9.3	R <sub>RSTEXT</sub>	Value of external reset extension resistor , in case of open-connect, device stays in RESET state		0	22		kΩ
9.5	V <sub>ENDRV_NRES_TH</sub>	ENDRV and NRES input readback logic 1 threshold	Read-back muxed to DIAG_OUT pin	350	400	450	mV
Digital	Input / Output						
10.1	V <sub>DIGIN_HIGH</sub>	Digital input, high level <sup>(18)</sup>	Input buffers using internal DVDD supply	2			V
10.2	V <sub>DIGIN_LOW</sub>	Digital input, low level <sup>(18)</sup>	Input buffers using internal DVDD supply			0.8	V
10.2		Digital input hysteresis <sup>(18)</sup>					

(16) Information in SPI register only

(17) For device wake up, VBATP and VBAT\_SAFING must be operating range, Recommended Operating Conditions R1.1 and R1.3a, and then a level on either IGN or CANWU to allow the device to start up, especially when VBATP and VBAT\_SAFING are ramping.
 (18) For pins NCS, SDI, SCLK, ERROR/WDI.

24 Specifications

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and with VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
10.4	R <sub>DIAGOUT_AMUX</sub>	Output resistance at DIAG_OUT pin in AMUX mode	BG1 selected on AMUX, < 200 nA current in or out of DIAG_OUT pin			15	kΩ
10.5	V <sub>DIGOUT_HIGH</sub>	Digital output, high level <sup>(19)</sup>	I <sub>OUT</sub> = -2 mA (out of pin)	VDDIO – 0.2			V
10.6	V <sub>DIGOUT_LOW</sub>	Digital output, low level <sup>(19)</sup>	I <sub>OUT</sub> = 2 mA (into pin)			0.2	V
Serial F	Peripheral Interfac	e					
13.12	R <sub>PULL_UP</sub>	Internal pullup resistor on NCS input pin		40	70	100	kΩ
13.13	R <sub>PULL_DOWN</sub>	Internal pulldown resistor on SDI and SCLK input pins		40	70	100	kΩ

(19) For pins SDO and DIAG\_OUT in DMUX mode.

## 4.6 Timing Requirements

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in the Section 4.3) (unless otherwise noted)

POS				MIN	NOM	MAX	UNIT
VDD5 – I	DO With Internal FE	т					
2.12	t <sub>delayVDD5</sub>	VDD5 voltage stabilization delay	Maximum delay between rising edge on CANWU pin until VDD5 reaches the end-value within 2%			2.5	ms
VDD3/5 -	- LDO With Internal F	ET					
3.12	t <sub>VDD3/5</sub>	VDD3/5 voltage stabilization delay	Maximum delay after CANWU wake-up for VDD3/5 output to settle			2.5	ms
VDD1 – I	DO With External FE	T					
4.15	t <sub>delayVDD1</sub>	VDD1 voltage stabilization delay	Maximum delay after CANWU wake-up for VDD1 output to settle			2.5	ms
Voltage	Monitoring		1				
6.7	VBATP_deglitch	VBATP undervoltage and overvoltage monitor deglitch time		200	240 <sup>(1)</sup>	280	μs
6.18	VDDx_deglitch	VDDx undervoltage and overvoltage monitor deglitch time		10		40	μs
6.21	VSOUT1_deglitch	VSOUT1 undervoltage and overvoltage monitor deglitch time		10		40	μs
IGNITION	and CAN WAKE-UP	(IGN and CANWU)	4 I			I	
7.6	IGN_deg	IGN deglitch filter time		7.5		22	ms
7.9	CANWU_deg	CANWU deglitch filter time		100		350	μs
Reset an	d Enable Outputs						
9.4	t <sub>RSTEXT(22kΩ)</sub>	Reset extension delay	22 kΩ	4.05	4.5	4.95	ms
9.4a	t <sub>RSTEXT(0kΩ)</sub>	Reset extension delay	0 kΩ	0.98	1.4	1.89	ms
Internal 3	System Clock						
11.1	f <sub>Syscik</sub>	System clock frequency (2)		3.8	4	4.2	MHz
Window	Watchdog						
12.1	t <sub>ERROR_WDI_deglitch</sub>	Deglitch time on ERROR/WDI pin for MCU error signal monitor		14.25	15	16.25	μs
12.2	t <sub>WD_pulse</sub>	Deglitch time on ERROR/WDI pin for watchdog-trigger input signal		28	30	32	μs
Serial Pe	ripheral Interface Tin	ning <sup>(3)</sup>	· · · · · · · · · · · · · · · · · · ·				
40.4	4		VDDIO = 3.3 V			5(4)	N411-
13.1	f <sub>spi</sub>	SPI clock (SCLK) frequency	VDDIO = 5 V			6	MHz
13.2		CDI alask pariod	VDDIO = 3.3 V	200			
13.2	.2 t <sub>SPI</sub>	SPI clock period	VDDIO = 5 V	167			ns

(1) 240 µs for VBAT-UV deglitch and 260 µs for VBAT-OV deglitch

- (2) The system clock is also used the derive the clock for the watchdog timer, so the system clock tolerance will also impact the watchdog timer tolerance.
- (3) Capacitance at  $C_{SDO} = 100 \text{ pF}$

(4) MAX SPI Clock tolerance is ±10%

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## Timing Requirements (continued)

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in the Section 4.3) (unless otherwise noted)

POS				MIN	NOM	MAX	UNIT
13.3	t <sub>high</sub>	High time: SCLK logic high duration		45			ns
13.4	t <sub>low</sub>	Low time: SCLK logic low duration		45			ns
13.5	t <sub>sucs</sub>	Setup time NCS: time between falling edge of NCS and rising edge of SCLK		45			ns
13.7	t <sub>susi</sub>	Setup time at SDI: setup time of SDI before the falling edge of SCLK	See Figure 4-2	15			ns
13.9	t <sub>hcs</sub>	Hold time: time between the falling edge of SCLK and rising edge of NCS		45			ns
13.10	t <sub>hics</sub>	SPI transfer inactive time (time between two transfers) during which NCS must remain high		788			ns

## 4.7 Switching Characteristics

Over operating ambient temperature  $T_A = -40^{\circ}$ C to the maximum-operating junction temperature  $T_J = 150^{\circ}$ C, and VBATP = VBAT\_SAFING in the recommended operating range (see R1.2 and R1.3b in Section 4.3) (unless otherwise noted)

POS		PARAMETER	MIN	TYP M	X UN	1IT	
Serial	Peripher	al Interface Timing <sup>(1)</sup>					
13.6	t <sub>d1</sub>	Delay time: time delay from falling edge of NCS to SDO transitioning from tri-state to 0			53	5.3 n:	S
13.8	t <sub>d2</sub>	Delay time: time delay from rising edge of SCLK to data valid at SDO	See Figure 4-2	0	8	5.7 n:	S
13.11	t <sub>tri</sub>	Tristate delay time: time between rising edge of NCS and SDO in tri-state			53	.3 n:	S

(1) Capacitance at C<sub>SDO</sub> = 100 pF

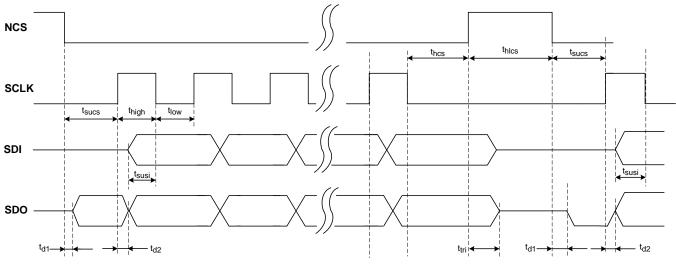
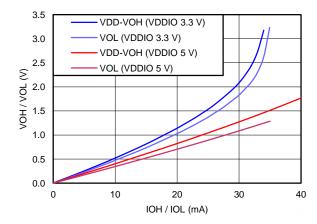


Figure 4-2. SPI Timing Parameters







## 4.8 **Typical Characteristics**

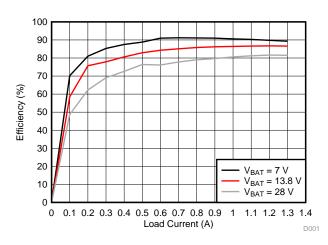


Figure 4-4. VDD6 BUCK Efficiency

## 5 Detailed Description

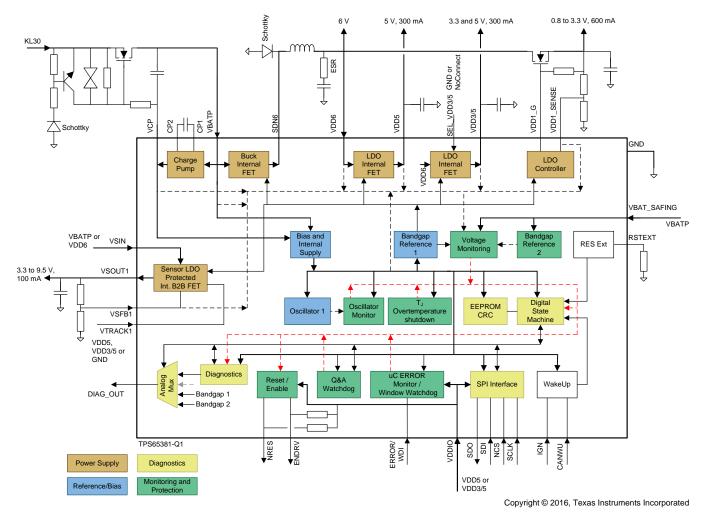
### 5.1 Overview

The device integrates an asynchronous-buck switch-mode power-supply converter with an internal FET that converts the input battery voltage to a 6-V preregulator output which supplies the integrated regulators.

A fixed 5-V linear regulator with an internal FET is integrated to be used as, for example, a CAN supply. A second linear regulator, also with an internal FET, regulates the 6 V to a selectable 5-V or 3.3-V MCU I/O voltage. A linear regulator controller with an external FET and resistor divider regulates the 6 V to an externally adjustable core voltage of between 0.8 V and 3.3 V. A linear regulator with two different modes of operation (tracking mode and non-tracking mode), with short-to-ground and short-to-battery protection and adjustable voltage between 3.3V and 9.5V can be used as a supply for external sensor.

The device monitors undervoltage and overvoltage on all regulator outputs, battery voltage, and internal supply rails. A second band-gap reference, independent from the main band-gap reference used for regulation circuit, is used for the undervoltage and overvoltage monitoring. In addition, regulator current-limits and temperature protections are implemented

The device supports wake-up from IGNITION or wake-up from a CAN transceiver.



## 5.2 Functional Block Diagram



#### 5.3 Feature Description

#### 5.3.1 VDD6 Buck Switch-Mode Power Supply

The purpose of the VDD6 buck switch-mode power supply is to reduce the power dissipation inside the IC. The VDD6 pin converts the ingoing power for the VDD5, VDD3/5, VDD1, and VSOUT1 pins from the battery-voltage domain to the 6-V voltage domain. Therefore the VDD6 pin is intended for use as a preregulator only; the output voltage is less accurate compared to the VDD5, VDD3/5, VDD1, and VSOUT1 pins. The VDD6 output-current capability is dimensioned to supply the VDD5, VDD3/5, VDD1, and VSOUT1 pins at their respective maximum output currents.

This switch-mode power supply (SMPS) operates with fixed-frequency adaptive on-time control pulsewidth modulation (PWM). The control loop of the SMPS is based on a hysteretic comparator. The internal N-channel MOSFET is turned on at the beginning of each cycle when the output voltage on the VDD6 pin is below the PWM comparator threshold. This MOSFET is turned off when the hysteretic PWM comparator resets the latch. When this internal MOSFET is turned OFF, the external Schottky diode recirculates the energy stored in the inductor for the remainder of the switching period. To preserve sufficient headroom for the VDD5 regulator at low battery voltage, the VDD6 regulator enters dropout mode for a battery voltage below 7 V.

The internal MOSFET is protected from excess power dissipation with a current-limit circuit and junctionovertemperature protection shared with the VDD3/5 pin. In case of an overtemperature condition in the VDD6 pin detected by the VDD3/5 overtemperature protection, the TPS65381-Q1 device enters the STANDBY state (all regulators switched off).

Because the control loop of the VDD6 SMPS is based on a hysteretic comparator, the output effective capacitance and effective series resistance (ESR) must be considered. The effective capacitance at the operating voltage (6-V DC), temperature range and lifetime of the capacitors must meet the output capacitance range for VDD6. The capacitor supplier should provide the necessary derating data to calculate the effective capacitance. The hysteretic comparator also requires a specified ESR to ensure balanced operation. Typically low-ESR ceramic capacitors are used for the output so an external resistor is required to bring the total ESR into the specified ESR range for VDD6. A general guideline to achieve balanced operation is  $R_{ESR} = L / (15 \times C_{Effective})$ . Using a higher effective output capacitance allows for a lower ESR which leads to lower voltage ripple. The inductance influences the system where using a lower inductance value allows for lower ESR, however the peak current will be higher.

#### 5.3.2 VDD5 Linear Regulator

The VDD5 pin is a regulated supply of 5 V  $\pm$ 2% overtemperature and battery supply range. A low-ESR ceramic capacitor is required for loop stabilization. This capacitor must be placed close to the pin of the IC. This output is protected against shorts to ground by a current-limit. This output also limits output-voltage overshoot during power up and during line or load transients.

On an initial IGN or CANWU power cycle, the soft-start circuit on this regulator is initiated which is typically in the 1-ms to 2-ms range. This output can require a larger output capacitor to ensure that during load transients the output does not drop below the required regulation specifications.

The internal MOSFET is protected from excess power dissipation with junction-overtemperature protection. In case of an overtemperature condition in the VDD5 pin, only the VDD5 regulator switches off by clearing bit D4 in the SENS\_CTRL register. To re-enable the VDD5 pin, bit D4 in the SENS\_CTRL register must be set again.

## 5.3.3 VDD3/5 Linear Regulator

The VDD3/5 pin is a regulated supply of 3.3 V or 5 V  $\pm 2\%$  overtemperature and battery supply range. The output voltage level is selected with the SEL\_VDD3/5 pin (open pin selects 3.3 V, grounded pin selects 5 V). The state of this selection pin is sampled and latched directly at the first initial IGN or CANWU power cycle. When latched, any change in the state of this selection pin after the first initial IGN or CANWU power cycle does not change the initially selected state of the VDD3/5 regulator.

A low-ESR ceramic capacitor is required for loop stabilization. This capacitor must be placed close to the pin of the IC. This output is protected against shorts to ground by a current-limit. This output also limits output-voltage overshoot during power up or during line or load transients.

On an initial IGN or CANWU power cycle, the soft-start circuit on this regulator is initiated which is typically in the 1-ms to 2-ms range. This output may require a larger output capacitor to ensure that during load transients the output does NOT drop below the required regulation specifications.

The internal MOSFET is protected from excess power dissipation with a current-limit circuit and junction overtemperature protection. In case of an over-temperature in the VDD3/5 pin, the TPS65381-Q1 device enters STANDBY state (all regulators switched-off).

## 5.3.4 VDD1 Linear Regulator

The VDD1 pin is an adjustable regulated supply between 0.8 V and 3.3 V. It uses a  $\pm 2\%$  reference (VDD1<sub>SENSE</sub>) over temperature and battery supply range. The tolerance of the external feedback resistor divider resistors will have an impact to the overall VDD1 regulation tolerance. To reduce on-chip power consumption, an external power NMOS is used. The regulation loop and the command gate drive are integrated. TI recommends to apply a resistor in the range of 100 k $\Omega$  to 1 M $\Omega$  between the gate and source of the external power NMOS. The VDD1 gate output is limited to prevent gate-source overvoltage stress during power up or during line or load transients.

On an initial IGN or CANWU power cycle, the soft-start circuit on this regulator is initiated which is typically in the 1-ms to 2-ms range. This soft-start is meant to prevent any voltage overshoot at start-up. The VDD1 output may require larger output capacitor to ensure that during load transients the output does not drop below the required regulation specifications.

The VDD1 LDO has no current-limit and no overtemperature protection for the external NMOS FET. Therefore, supplying the VDD1 pin from the VDD6 pin is recommended (see Section 5.2). In this way, the VDD6 pin current-limit acts as current-limit for the VDD1 pin and the power dissipation is limited as well. To avoid damage in the external NMOS FET, selecting the current rating of the VDD1 pin well above the maximum-specified VDD6 current-limit is recommended.

If the VDD1 regulator is not being used, leave the VDD1\_G and VDD1\_SENSE pins open. An internal pullup device on the VDD1\_SENSE pin detects the open connection and pulls up the VDD1\_SENSE pin. This forces the regulation loop to bring the VDD1\_G output down. This mechanism also masks the VDD1\_OV flag in VMON\_STAT2 register and thus ENDRV pin action from a VDD1 OV condition is also masked. These actions are equivalent to clearing the nMASK\_VDD1\_UV\_OV bit in the DEV\_CFG1 register to 0. This internal pullup device on the VDD1\_SENSE pin also prevents a real VDD1 overvoltage on the MCU core supply in case of an open connection to the VDD1\_SENSE pin, as it brings the VDD1\_G pin down. Therefore in this situation, the VDD1 output voltage is 0 V.

By default, VDD1 monitoring is disabled. If the VDD1 pin is used in the application, TI recommends to set the nMASK\_VDD1\_UV\_OV bit in the DEV\_CFG1 register to 1 when the device is in DIAGNOSTIC state. This setting enables driving and extending the reset to the external MCU when VDD1 under-voltage is detected.



## 5.3.5 VSOUT1 Linear Regulator

The VSOUT1 pin is a regulated supply with two separate modes: tracking mode and non-tracking mode. The mode selection occurs with the VTRACK1 pin. When the voltage applied on the VTRACK1 pin is above 1.2 V, the VSOUT1 pin is in tracking mode. When the VTRACK1 pin is shorted to ground, the VSOUT1 pin is in non-tracking mode. This mode selection occurs during the first ramp-up of the VDDx rails, and is latched after the first VDDx ramp-up is completed. Therefore, after completion of the VDDx ramp-up, any change in the VTRACK1

pin no longer affects the selected tracking or non-tracking mode.

In tracking mode, the VSOUT1 pin tracks the input reference voltage on the VTRACK1 pin with a gain factor determined by the external resistive divider. The tracking offset between the VTRACK1 and VSFB1 pins is ±35 mV over temperature and battery supply range. This mode allows, for instance, the VSOUT1 pin to be 5 V while tracking the VDD3 (3.3-V) supply. In unity-gain feedback, the VSOUT1 pin can directly follow the VDD5 pin or the VDD3 pin.

In non-tracking mode, the VSOUT1 output voltage is proportional to a fixed reference voltage of 2.5 V at the VSFB1 pin, with a gain factor determined by the external resistive divider. This mode allows the VSOUT1 pin to be any factor of the internal reference voltage.

Both in tracking and non-tracking mode, the VSOUT1 output voltage must 3.3 V or higher. The VSOUT1 pin can track the VDD3/5 pin in 3.3-V setting within the specified limits.

VSOUT1 has a separate input supply to reduce the internal power dissipation. For an output voltage of 3.3 V or 5 V, for instance, VDD6 can be used as the input supply. For an output voltage of greater than 5 V, The VBATP pin can be used as the input supply. Here, the maximum power dissipation for the internal FET must not exceed 0.6 W to avoid thermal shutdown.

A low-ESR ceramic capacitor is required for loop stabilization; this capacitor must be placed close to the pin of the IC. This output is intended for going outside the ECU and therefore is protected against shorts to external chassis ground by a current-limit. Furthermore, in case of output shorted to battery voltage, any potential reverse current going back inside the ECU is blocked, hence preventing any unintended supplying of the ECU by this VSOUT1 output. This regulator also limits output-voltage overshoot during power up or during line or load transients.

The VSOUT1 pin is disabled by default on start-up. After the NRES pin release, the MCU can enable the VSOUT1 pin through a SPI command by setting bit D0 in the SENS\_CTRL register. After this SPI command, the soft-start circuit on this regulator is initiated which is typically in the 1-ms to 2-ms range. This output may require a larger output capacitor to ensure that during load transients the output does NOT drop below the required regulation specifications. Regardless of tracking or non-tracking mode, the VSFB1 pin is ramped to the desired value after completion of the soft start.

The internal MOSFET is protected from excess power dissipation with a current-limit circuit and junctionovertemperature protection. In case of an overtemperature condition in the VSOUT1 pin, only the VSOUT1 regulator is switched off by clearing bit 0 in the SENS\_CTRL register. To re-enable the VSOUT1 pin, first bit 2 in the SAFETY\_STAT 1 register must be cleared on read-out, and afterwards bit 0 in the SENS\_CTRL register must be set again.

The VSOUT1 pin can be observed at an ADC input of the MCU through the DIAG\_OUT pin (see Section 5.4.1.8) which allows the detection of a short to any other supply prior to enabling the VSOUT1 LDO.

## 5.3.6 Charge Pump

The charge pump is configured to supply an overdrive voltage of typically 12 V to the supply voltage. This overdrive voltage is required for driving the gate voltages of the internal NMOS-FETs of the VDDx and VSOUT1 supply rails. Furthermore, this overdrive voltage can drive the gate of an external NMOS power FET acting as reverse-battery protection. Such reverse-battery protection allows for lower minimum-battery-voltage operation compared to a traditional reverse-battery blocking diode. If such reverse battery

protection is used, a series resistance of about 10 k $\Omega$  must be connected between the VCP pin and the gate of the NMOS power FET (see Section 5.2). This series resistance is required to limit any current out of the VCP pin when the gate of the NMOS power FET is driven to negative voltage, because the absolute-maximum rating of the VCP pin is limited to -0.3 V because of a parasitic reverse diode to the substrate, that is, ground.

The charge pump requires two external capacitors, one puming capacitor ( $C_{pump}$ ) and one storage capacitor ( $C_{store}$ ). To have sufficient overdrive voltage out of the charge pump even at low battery voltage, the external load current on the VCP pin must be less than 100  $\mu$ A.

## 5.3.7 Wake-Up

The TPS65381-Q1 device has two wake-up pins: IGN and CANWU. Both pins have a wake-up threshold level between 2 V and 3 V, and a hysteresis between 50 mV and 200 mV.

The IGN wake-up pin is level-sensitive and has a deglitch (filter) time between 7.5 ms and 22 ms. The TPS65381-Q1 device provides a power-latch function (POST\_RUN) for this IGN pin, allowing the MCU to decide when to power down the TPS65381-Q1 device through SPI command. For this, the MCU must set the IGN power-latch bit 4 (IGN\_PWRL) in the SPI SAFETY\_FUNC\_CFG register, and read the unlatched status of the deglitched (filtered) IGN pin on theSPI register, DEV\_STAT, bit 0 (IGN). To enter the STANDBY state, the MCU must clear the IGN\_PWRL bit. For this, the TPS65381-Q1 device must be in DIAGNOSTIC state because this SPI register is only writable in DIAGNOSTIC state. The IGN\_PWRL bit is also cleared after a detected CANWU wake-up event. Furthermore, the TPS65381-Q1 device provides an optional transition to the RESET state after a detected IGN wake-up during the POST\_RUN (see Figure 5-2).

The CANWU pin is level sensitive and has a minimum 350-µs deglitch (filter) time. The deglitched (filtered) CANWU wake-up signal is latched, allowing the MCU to decide when to power down the TPS65381-Q1 device through SPI command WR\_CAN\_STBY.

Both the IGN and CANWU pins are high voltage pins. If the pins are connected to lines with transients, the application should provide proper filtering and protection to ensure the pins stay within the specified voltage range.

#### NOTE

If the application does not require wake up from IGN (ignition or KL15) or wake up from CANWU (a CAN or other transceiver), but the device should wake up any time power is supplied, one method is to connect IGN to VBATP (and VBAT\_SAFING) through a 10 k $\Omega$  or greather series resistor. Once the VBATP supply is turned on, the IGN pin will also go high and allow the device to wake up (power up) as soon as voltage levels to allow the relase of power on reset circuits for VBATP and VBAT\_SAFING and IGN is high.

#### 5.3.8 Reset Extension

During a power-up event, the TPS65381-Q1 device releases the reset to the external MCU through the NRES pin with a certain delay time (reset extension time) after the VDD3/5 and VDD1 pins have crossed the respective undervoltage thresholds.

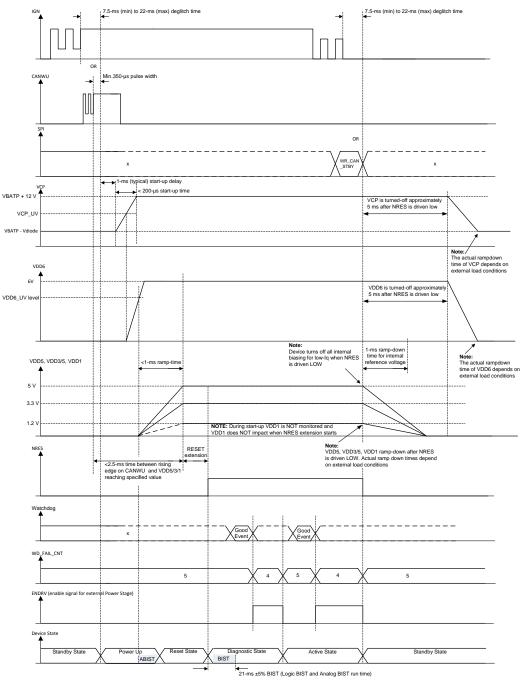
This reset extension time is externally configurable with a resistor between the RESEXT pin and ground. When shorting this RESEXT pin to ground, the minimum reset extension time is typically 1.4 ms. For a 22- $k\Omega$  external resistor, the typical reset extension time is 4.5 ms.



#### 5.4 Device Functional Modes

#### 5.4.1 Power-Up and Power-Down Behavior

Figure 5-1 shows the power-up and power-down behavior.

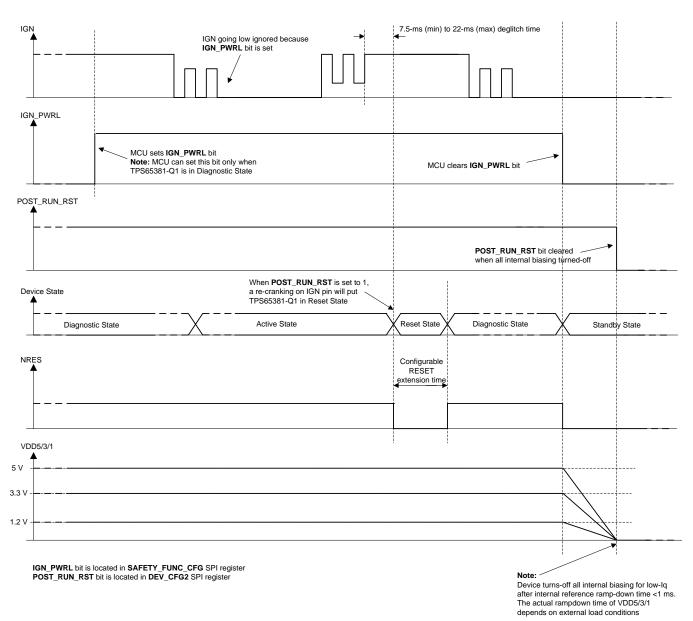


- (1) During a power-up event, the Analog-BIST begins automatically after the VDD6 rail ramps above its UV threshold. If ABIST fails, the device transitions to SAFE state.
- (2) The device may not be able to respond to MCU SPI communication during BIST, so if the MCU boots faster than BIST, it should wait until BIST is complete to use SPI communication. If the Analog or Logic BIST, or both fail, the device transitions to SAFE state.
- (3) ENDRV pin level depends on WD\_FAIL\_CNT, ENABLE\_DRV bit and the signals shown in Figure 5-14. The MCU should only set ENABLE\_DRV bit when the WD\_FAIL\_CNT is below 5.

#### Figure 5-1. Power-Up and Power-Down Behavior

**TPS65381-Q1** SLVSBC4F – MAY 2012 – REVISED MAY 2016





- (1) Under slow VBAT ramp-down and when the VDD3/5 rail is configured as a 5-V rail, the NRES output can be pulled low when VBAT is at approximately 6.3 V. This occurs because of an undervoltage transient on VDD3/5 rail.
- (2) Under slow VBAT ramp-up and when the VDD3/5 rail is configured as a 5-V rail, the NRES output can be pulled low when VBAT is at approximately 6.6 V. This occurs because of an undervoltage transient on VDD3/5 rail.
- (3) Under similar conditions, undervoltage transients are observed on VDD5 and VSOUT1 rails.

#### Figure 5-2. IGN Power Latch and POST-RUN Reset



#### 5.4.1.1 Safety Functions and Diagnostics Overview

The IC is intended to be used in automotive safety applications. The following diagnostic blocks are implemented to achieve a better diagnostic coverage or a lower rate of dangerous undetected faults.

- Voltage monitor (VMON)
- Analog built-in self-test (ABIST) diagnostics for safety analog blocks
- Logic built-in self-test (LBIST) for safety controller functions
- Loss of clock monitor (LCMON)
- Junction temperature monitoring for all power supplies with internal FET
- Current-limit for all power supplies
- Analog MUX (AMUX) for externally monitored diagnostics and debug
- Digital MUX (DMUX) for externally monitored diagnostics and debug
- Watchdog configurable for Trigger Mode (open and close window) or question-answer mode
- MCU error signal monitor (ESM)
- Controlled and protected enable output (ENDRV) for external power stages or peripheral wake-up
- Device configuration register CRC protection
- SPI command decoder with parity check
- SPI data output feedback check
- Reset circuit for initializing external MCU
- EEPROM analog trim content CRC protection
- Device state controller with SAFE state in case of detected error event

#### 5.4.1.2 Voltage Monitor (VMON)

The VBAT supply voltage, all regulator outputs and internally generated voltages are supervised by a voltage monitor module (VMON). An undervoltage or overvoltage condition is indicated by the corresponding VMON register status flag bits:

- VMON flag bit set to 0 when power supply is within specification
- VMON flag bit set to 1 when power supply is outside tolerance band

The monitoring occurs by undervoltage and overvoltage comparators. The reference voltage (BANDGAP\_REF2) for the VMON module is independent of the system reference voltage (BANDGAP\_REF1) used by the regulators. A glitch-filtering function ensures reliable monitoring without false setting of the VMON status flag bits. The complete VMON block is supplied by a separate supply pin, VBAT\_SAFING.

VMON comparator diagnostics are covered by analog built-in self-test (ABIST) executed during device startup and power up or activated with the SPI command by the external MCU SPI request when the device is in the DIAGNOSTIC or ACTIVE state. Each monitored voltage rail is emulated for undervoltage and overvoltage conditions on the corresponding comparator inputs, hence forcing the corresponding comparator to toggle multiple times (in a toggling pattern observed and checked by the ABIST controller). The monitored voltage rails themselves are not affected during this self-test, so no real under voltage or over voltage occurs on any of these rails because of this self-test.

Table 5-1 lists an overview of the performed voltage monitoring. As listed in this table, an overvoltage protection is implemented for some of the internal supply rails.



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VOLTAGE	OUTPUT VOLTAGE	CREATED FROM		IG DETECTION SHOLDS	MONITORED AGAINST REFERENCE		OV PROTECTION	OV PROTECTION	IMPACT ON DEVI	CE BEHAVIOR
RAIL		REFERENCE	UV	ov	REFERENCE	PIN	LEVEL	REFERENCE	UV	ov
				Supply Input						
VBAT	N/A	N/A	4.2 to 4.5 V	34.7 to 36.7 V	VMON_BG	VBATP	N/A	N/A	SPI flag VMON_STAT1 D6 STANDBY state NRES = 0, ENDRV = 0	SPI flag VMON_STAT1 D7 RESET state (when MASK_VBATP_OV = 0)
				Supply Outputs						
VDD6	6 V ± 10%	MAIN_BG	5.2 to 5.4 V	7.8 to 8.2 V	VMON_BG	VDD6	N/A	N/A	SPI flag VMON_STAT2 D6	SPI flag VMON_STAT2 D7
VDD5	5 V ± 2%	MAIN_BG	4.5 to 4.85 V	5.2 to 5.45 V	VMON_BG	VDD5	N/A	N/A	SPI flag VMON_STAT2 D4	SPI flag VMON_STAT2 D5 ENDRV = 0
VDD3/5 (5 V)	5 V ± 2%		4.5 to 4.85 V	5.2 to 5.5 V					SPI flag VMON_STAT2 D2	SPI flag VMON STAT2 D3
VDD3/5 (3.3 V)	3.3 V ± 2%	MAIN_BG	3 to 3.17 V	3.43 to 3.6 V	VMON_BG	VDD3/5	N/A	N/A	RESET state NRES = 0, ENDRV = 0	ENDRV = 0
VDD1	0.8 V to 3.3 V -1% to +2% VDD1_SENSE = 800 mV -1% to +2%	MAIN_BG	0.94 to 0.98 × VDD1	1.03 to 1.06 × VDD1	VMON_BG	VDD1_SENSE	N/A	N/A	SPI flag VMON_STAT2 D0 RESET state NRES = 0, ENDRV = 0 (when nMASK_VDD1_UV_OV=1)	SPI flag VMON_STAT2 D1 ENDRV = 0 (when nMASK_VDD1_UV_OV=1)
VSOUT1 (non-tracking)	3.3 V to 9.5 V ± 2% VDSFB1 = 2.5 V ± 2%	MAIN_BG	0.88 to 0.94 ×	1.06 to 1.12 ×	MAIN_BG	VSFB1	N/A	N/A		
VSOUT1 (tracking)	3.3 V to 9.5 V ± 2% VDSFB1 = VTRACK1 ± 20 mV	VTRACK1	VSOUT1	VSOUT1	VTRACK1	VSFB1	N/A	N/A	SAFETY_STAT1 D5	SPI flag SAFETY_STAT1 D4
				Internal Supplies						
VCP17	17 V (typ)	MAIN_BG	N/A	21 V (typ)	VMON_BG	N/A	21 V (typ)	VMON_BG	N/A	SPI flag VMON_STAT1 D5 VSOUT1 not operational
VCP12	12 V (typ)	MAIN_BG	7.43 V (typ)	14.2 V (typ)	VMON_BG	N/A	14.2 V (typ)	VMON_BG	SPI flag VMON_STAT1 D3	SPI flag VMON_STAT1 D4 VDD5, VDD3/5 and VDD1 not operational $\rightarrow$ RESET state NRES = 0, ENDRV = 0
AVDD	6.9 V (typ)	Internal LV Zener	3.6 V (typ)	N/A	Independent local band gap	N/A	< 10.48 V	Internal MV Zener	NPOR $\rightarrow$ STANDBY state NRES = 0, ENDRV = 0	NPOR $\rightarrow$ STANDBY state NRES = 0, ENDRV = 0
AVDD_VMON	6.9 V (typ)	Internal LV Zener	3.56 V (typ)	N/A	Independent local band gap	Indirectly monitoring VBAT_SAFING	< 10.48 V	Internal MV Zener	SPI flag VMON_STAT1 D2	NPOR $\rightarrow$ STANDBY state NRES = 0, ENDRV = 0
DVDD	3 V (typ)	MAIN_BG	2.472 V (typ)	3.501 V (typ)	VMON_BG	N/A	N/A	N/A	NPOR $\rightarrow$ STANDBY state NRES = 0, ENDRV = 0	NPOR $\rightarrow$ STANDBY state NRES = 0, ENDRV = 0
				Internal Reference	s					
MAIN_BG	2.5 V ± 2%	MAIN_BG	2.364 V (typ)	2.617 V (typ)	VMON_BG	N/A	N/A	N/A	SPI flag VMON_STAT1 D0	SPI flag VMON_STAT1 D1
VMON_BG	2.5 V ± 2%	VMON_BG	2.364 V (typ)	2.617 V (typ)	MAIN_BG	N/A	N/A	N/A	SPI flag VMON_STAT1 D1	SPI flag VMON_STAT1 D0

(1) N/A = Not applicable



# 5.4.1.3 TPS65381-Q1 Internal Error Signals

Table 5-2 lists a useful overview of the TPS65381-Q1 device internal error signals and the impact of the signals on the device behavior.

# Table 5-2. Internal Error Signals

		DETECTIVE CONDITION (TH	RESHOL	D LEVEL)				DEGLIT	СН ТІМЕ "	TO SET FLA	G (µS)	DEVICE STATE WHEN FLAG IS SET		
DMUX POS. NO.	SIGNAL NAME	DESCRIPTION	MIN	ТҮР	MAX	UNIT	ELEC. CHAR. NO.	MIN	ТҮР	МАХ	ELEC. CHAR. NO.	NRES	ENDRV	DEVICE STATE
D1.2	AVDD_UVN	AVDD undervoltage comparator output		3.6		V		15		30		LOW	LOW	STAND-BY
D1.3	BG_ERR1	VMON or main bandgap is OFF (set to 1 when VMON bandgap > main bandgap)		Main bandgap = 2.364 (VMON bandgap = 2.477)		v		15		30		Not changed (unless VDD3/5_UV or VDD1_UV detected, causing NRES = LOW)	Not changed (unless VDD3/5_UV or VDD1_UV detected, causing ENDRV = LOW)	Not changed (unless VDD3/5_UV or VDD1_UV detected, causing transition to RESET)
D1.4	BG_ERR2	VMON or main bandgap is OFF (set to 1 when VMON bandgap < main bandgap)		Main bandgap = 2.617 (VMON bandgap = 2.477)		V		15		30		Not changed	Not changed (unless VDD3/5_UV or VDD1_UV detected, causing ENDRV = LOW)	Not changed
D1.5	VCP12_UVN	VCP12 charge pump undervoltage comparator		7.43		V		15		30		Not changed	Not changed	Not changed
D1.6	VCP12_OV	VCP12 charge pump overvoltage comparator		14.2		V		15		30		Not changed	Not changed	Not changed
D1.7	VCP_OV	VCP17 charge pump overvoltage comparator		21		V		15		30		Not changed	Not changed	Not changed
D1.8	VDD6_UVN	VDD6 undervoltage comparator	5.2		5.4	V	6.22	10		40	6.18	Not changed	Not changed	Not changed
D1.9	VDD6_OV	VDD6 overvoltage comparator	7.8		8.2	V	6.23	10		40	6.18	Not changed	Not changed	Not changed
D1.10	VDD5_UVN	VDD5 undervoltage comparator	4.5		4.85	V	6.8	10		40	6.18	Not changed	Not changed	Not changed
D1.11	VDD5_OV	VDD5 overvoltage comparator	5.2		5.45	V	6.10	10		40	6.18	Not changed	LOW	Not changed
D1.12	VDD3/5 UVN	VDD3/5 undervoltage comparator; 3.3-V setting	3		3.17	V	6.12	10		40	6.18	LOW	LOW	RESET
01.12	VDD3/3_0VN	VDD3/5 undervoltage comparator; 5-V setting	4.5		4.85	v	0.12	10		40	0.10	2010	2011	NEGET
D1.13	VDD3/5 OV	VDD3/5 overvoltage comparator; 3.3-V setting	3.43		3.6	V	6.14	10		40	6.18	Not changed	LOW	Not changed
D1.13	VDD3/3_0V	VDD3/5 overvoltage comparator; 5-V setting	5.2		5.5	v	0.14	10		40	0.10	Not changed	LOW	Not changed
D1.14	VDD1_UVN	VDD1 undervoltage comparator	0.94		0.98	VDD1	6.16	10		40	6.18	Not changed when nMASK_VDD1_UV_OV = 0 (default config) When nMASK_VDD1_UV_OV = 1: NRES = LOW	Not changed when nMASK_VDD1_UV_OV = 0 (default config) When nMASK_VDD1_UV_OV = 1: ENDRV = LOW	Not changed when nMASK_VDD1_UV_OV = 0 (default config) When nMASK_VDD1_UV_OV = 1: RESET
D1.15	VDD1_OV	VDD1 overvoltage comparator	1.03		1.06	VDD1	6.17	10		40	6.18	Not changed	Not changed (default config) When MASK_VDD1_UV_OV = 1: ENDRV = LOW	Not changed
D1.16	LOCLK	Loss-of-system-clock comparator	0.742		2.64	MHz		0.379		1.346		LOW	LOW	STANDBY



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Table 5-2. Internal	Error	Signals	(continued)
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					DEGLITCH TIME TO SET FLAG (µS) DEVICE STATE WHEN FLAG IS SET									
	DETECTIVE CONDITION (THRESHOLD LEVEL)								DEVICE STATE WHEN FLAG IS SET					
DMUX POS. NO.	SIGNAL NAME	DESCRIPTION	MIN	ТҮР	MAX	UNIT	ELEC. CHAR. NO.	MIN	ТҮР	МАХ	ELEC. CHAR. NO.	NRES	ENDRV	DEVICE STATE
D3.4	CP_OV	Charge pump overvoltage comparator		VBAT + 12		V		N/A	N/A	N/A		Not changed	Not changed	Not changed
D3.5	CP_UVN	Charge pump undervoltage Comparator		VBAT + 6		v		N/A	N/A	N/A		Not changed	Not changed	Not changed
D3.8	CP_DIFF3V	Indicates VCP-VBATP > 3 V		VBAT + 3		V		N/A	N/A	N/A		Not changed	Not changed	Not changed
D3.10	VBAT_UVN	VBAT undervoltage comparator	4.2		4.5	V	6.1		200		6.7	LOW	LOW	STANDBY
D3.11	VBATP_OV	VBAT overvoltage comparator	34.7		36.7	v	6.5		200		6.7	LOW (default config) When MASK_VBATP_OV = 1: NRES unchanged	LOW (default config) When MASK_VBATP_OV = 1: ENDRV unchanged	RESET (default config) When MASK_VBATP_OV = 1: device state unchanged
D3.12	VDD5_OT	VDD5 overtemperature	175		210	°C	3.13	45		60		LOW	LOW	RESET
D3.13	VDD3_5_OT	VDD3/5 overtemperature	175		210	°C	2.13	45		60		LOW	LOW	Device state depends on EN_VDD35_OT bit setting: EN_VDD35_OT = 0 : VDD3/5 disabled -> VDD3/5 disabled -> VDD3/5 U event -> RESET EN_VDD35_OT = 1 : STAND-BY
D3.14	VSOUT1_OT	VSOUT1 overtemperature	175		210	°C	5.13	45		60		Not changed	Not changed	Not changed
D3.15	VDD5_CL	VDD5 current-limit	350		650	mA	2.14	15		30		Not changed	Not changed	Not changed
D3.16	VDD3_5_CL	VDD3/5 current-limit	350		650	mA	3.14	15		30		Not changed	Not changed	Not changed
D4.2	VSOUT1_CL	VSOUT1 current-limit	100		500	mA	5.19	15		30		Not changed	Not changed	Not changed
D4.3	VSOUT1_UVN	VSOUT1 undervoltage comparator	0.88		0.94	VSOUT1	6.19	10		40	6.21	Not changed	Not changed	Not changed
D4.4	VSOUT1_OV	VSOUT1 overvoltage comparator	1.06		1.12	VSOUT1	6.20	10		40	6.21	Not changed	Not changed	Not changed
D4.5	DVDD_UVN	DVDD undervoltage comparator		2.472		V			0			LOW	LOW	STANDBY
D4.6	DVDD_OV	DVDD overvoltage comparator		3.501		V			0			LOW	LOW	STANDBY
D4.8	VS_TRK_MODE	VSOUT1 in track-mode indication		1.2		V	5.3a	N/A	N/A	N/A		Not changed	Not changed	Not changed
D4.9	VMON_TRIM_ERR	VMON trim error	Set wh	en bit-flip in VM detec		isters is		15		30		Not changed	Not changed	Not changed



# 5.4.1.4 Loss-of-Clock Monitor (LCMON)

The clock monitor detects internal oscillator failures including:

- Oscillator clock stuck high or stuck low
- Reduced clock frequency

The clock monitor is enabled during a power-up event after power-on reset is released (driven high). The clock monitor remains active during device normal operation (STANDBY, RESET, DIAGNOSTIC, ACTIVE, and SAFE states). In case of a clock failure:

- The device transitions to the STANDBY state.
- All regulators are disabled.
- The digital core is reinitialized.
- Reset to the external MCU is asserted low.
- The failure condition is latched outside the digital core in the SPI register SAFETY\_STAT\_4, bit D5

The loss-of-clock monitor has a self-test structure that is activated and monitored by an analog BIST (ABIST). The external MCU can re-check the clock monitor any time when the device is in the DIAGNOSTIC state or ACTIVE state. The enabled diagnostics emulate a clock failure that causes the clock-monitor output to toggle. The clock-monitor toggling pattern is checked by the ABIST, while the external MCU can check that the loss-of-clock status bit is being set during active test. During this self-test, the actual oscillator frequency (4 MHz) is not changed because of this self-test.

# 5.4.1.5 Analog Built-In-Self-Test (ABIST)

The ABIST is the controller and monitor circuit for performing self-checking diagnostics on critical analog functions:

- VMON undervoltage and overvoltage comparators
- Clock monitor (LCMON)
- EEPROM analog-trim content check (CRC protection)

During the self-test on the VMON undervoltage and over voltage comparators, the monitored voltage rails are left unchanged, so no real undervoltage or overvoltage occurs on any of these rails because of these self-tests. Furthermore, also during the self-check on the clock monitor, the actual oscillator frequency (4 MHz) is not changed because of this self-test.

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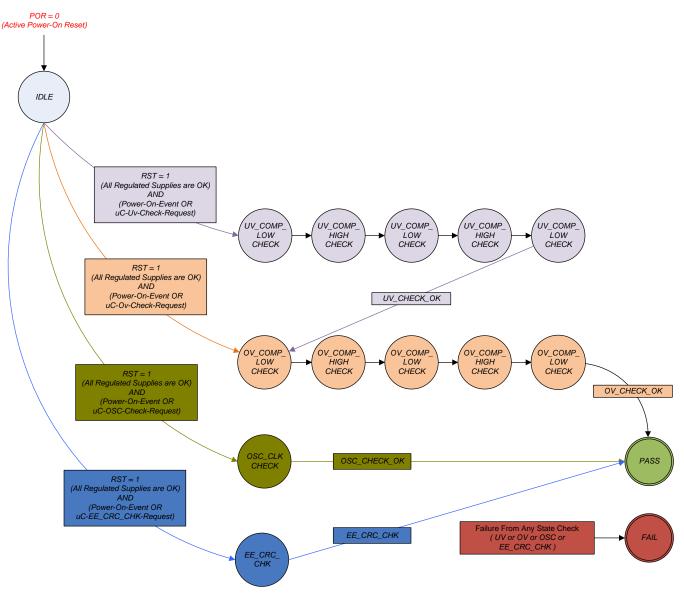


Figure 5-3. Analog BIST Run States

The ABIST is activated with every device power-up event or any transition to RESET state, or by external MCU when the device is in DIAGNOSTIC state (by setting ABIST\_EN in the SAFETY\_BIST\_CTRL register, note that this register has a SW WRITE PROTECT). During an active ABIST run, the device cannot monitor the state of the regulated supplies, and the ENDRV pin is pulled low. The full ABIST run time is approximately 300 µs. The ABIST can also be performed in ACTIVE state on MCU request, depending on system safety requirements (such as system-fault response time).

A running ABIST is indicated in the ABIST\_RUN bit (bit D0) in the SAFETY\_STAT\_3 register. This bit is set to 1 during the ABIST run and is cleared to 0 when the ABIST is completed.

In case of an ABIST failure, the device enters SAFE state without asserting a reset to external MCU, while all ABIST status flag bits remain latched in the digital core. This allows the external MCU to detect the ABIST failure root caused by reading the ABIST\_UVOV\_ERR bit in SAFETY\_STAT\_3 Register.



# 5.4.1.6 Logic Built-In Self-Test (LBIST)

The logic BIST (LBIST) tests the digital-core safety functions.

- Includes an application controllable logic BIST engine which applies test vectors to the digital core.
- The LBIST engine provides stuck-at fault test coverage to logic blocks under test.
- The LBIST run time is typically 4.2 ms (±5%). After the LBIST, a 16-ms (typical) wait period occurs to fill the digital filters covered by the LBIST. During this time, the ABIST is run. The total BIST time is approximately 21 ms. SPI registers may be un-available during BIST, so no SPI reads or writes should be made while BIST is running.
- The LBIST engine has a time-out counter as a fail-safe feature.

The BIST (LBIST with ABIST) is activated with any transition out of the RESET state during power up events. The BIST is also activated with any other transition out of the RESET state unless the AUTO\_BIST\_DIS bit in the SAFETY\_BIST\_CTRL register is set.

The external MCU may activate LBIST (BIST) when the device is in DIAGNOSTIC or ACTIVE state (by setting LBIST\_EN in the SAFETY\_BIST\_CTRL register, note that this register has a *SW WRITE PROTECTION*). Note, LBIST should only be run in ACTIVE state if the system-safety timing requirements can allow the total 21-ms BIST time. During the BIST run, the device cannot monitor the state of regulated supplies, cannot respond to any SPI command and therefore cannot monitor state of MCU through the watchdog timer. During the BIST run, the ENDRV pin is pulled low and the watchdog fail counter reinitializes to 5. After the BIST is complete, the post-BIST-reset initializes following functions and registers:

- DEV\_STAT
- SAFETY\_STAT\_2
- SAFETY STAT 4
- SAFETY STAT 5
- WD\_TOKEN\_VALUE
- WD\_STATUS
- SAFETY\_CHECK\_CTRL
- DIAG\_CFG\_CTRL
- DIAG\_MUX\_SEL

A running LBIST is indicated in the LBIST\_RUN bit (bit D1) in the SAFETY\_STAT\_3 register. This bit is set to 1 while the LBIST is running, and is cleared to 0 when the LBIST is completed. After the LBIST run, completion of the whole BIST is confirmed by the MCU by reading 0 for both the LBIST\_RUN and ABIST\_RUN bits.

In case of a LBIST failure, the device enters SAFE state without asserting a reset to external MCU. The external MCU can detect the LBIST failure root caused by reading the LBIST\_ERR bit in SAFETY\_STAT\_3 Register.

# 5.4.1.7 Junction Temperature Monitoring and Current Limiting

Each LDO with an internal power FET has junction temperature monitoring with thermal shutdown protection. In case of thermal shutdown, a regulated supply can enable only after the thermal shutdown condition is removed.

For VSOUT1 supplies, the thermal shutdown disables the regulator until the VSOUT1 overtemperature condition is no longer present.

For the configurable VDD3/5 regulator, a thermal shutdown event disables regulated supplies, and reset to the external MCU (NRES) and the ENDRV pin are asserted low. The VDD6 buck preregulator shares the thermal protection with the VDD3/5 thermal shutdown.

For the VDD5 regulator, thermal shutdown clears the enable bit and places the device into RESET state with a reset to the external MCU (NRES) asserted low, while all other regulators remain enabled. When the VDD5 overtemperature condition is gone, the external MCU must set this enable control bit again to reenable the regulator.

The VDD3/5, VDD5, and VSOUT1 regulators include a current-limit circuit for additional protection against excessive power consumption and thermal overstress. Respective status bits are set in the SAFETY\_STAT\_1 register when a current-limit is detected on any of these rails.

Table 5-3 lists an overview of the thermal and overcurrent protections on the supply output rails.

VOLTAGE	THERMA	L PROTECT	OVERCURRENT PROTECTION			
RAIL	THRESHOLD (°C)	IMPACT ON DEVICE BEHAVIOR	CURRENT-LIMIT	IMPACT ON DEVICE BEHAVIOR		
VDD6	175 to 210 (shared with VDD3/5)	SPI flag SAFETY_STAT_1 D0 STANDBY state	1.5 to 2.5 A	None		
VDD5	175 to 210	SPI flag SAFETY_STAT_1 D1 RESET state Bit D4 in SENS_CTRL register cleared → VDD5 switched off	350 to 650 mA	SPI flag SAFETY_STAT_1 D7		
VDD3/5	175 to 210	SPI flag SAFETY_STAT_1 D0 STANDBY state	350 to 650 mA	SPI flag SAFETY_STAT_1 D6		
VDD1	None	N/A	None	N/A		
VSOUT1	175 to 210	SPI flag SAFETY_STAT_1 D2 Bit D0 in SENS_CTRL register cleared → VSOUT1 switched off	100 to 500 mA	DIAG_OUT via Digital MUX for VSOUT1_CL		

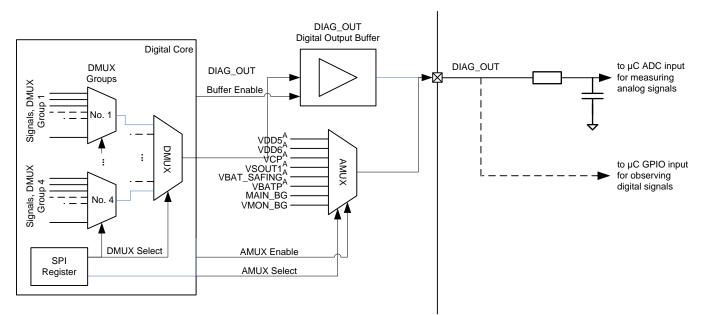
# Table 5-3. Thermal and Overcurrent Protect Overview



## 5.4.1.8 Diagnostic Output Pin DIAG\_OUT

Analog and digital critical signals, which are not directly connected to the MCU, are switched by a multiplexer to the external DIAG\_OUT pin. The programming of the multiplexer is done through the SPI register, DIAG\_MUX\_SEL. The digital signals are buffered to have sufficient drive capabilities.

This multiplexer facilitates external pin interconnect tests by feeding back the input pin state or feeding back internal module self-test status or safety comparator outputs.



Marked analog signals put out with divider ratio

If the user wants to measure analog signals by  $\mu$ C ADC and observe digital signals by  $\mu$ C GPIO, it must assure that

GPIO input stage does not affect  $\mu C$  ADC measurements.

If isolating  $\mu C \ GPIO$  is not possible within  $\mu C$ , the user must achieve isolation externally.

#### Figure 5-4. Diagnostic Output Pin, DIAG\_OUT

In case the DIAG\_OUT pin is connected to a mixed analog or digital input pin of the MCU, TI recommends to configure this MCU input pin and the DIAG\_OUT pin simultaneously in accordance with the desired type of signal (analog or digital). The type of signal (analog or digital) on the DIAG\_OUT1 pin can be configured with the MUX\_CFG bits in the DIAG\_CFG\_CTRL register. The DIAG\_OUT multiplexer can be globally enabled and disabled with bit 7 in the DIAG\_CFG\_CTRL register. When disabled, the DIAG\_OUT pin is in high-ohmic state (tri-stated).

# NOTE

When enabling DIAG\_OUT MUX while using SPI communication, the SDO pin is not in high impedance while NCS = High and DIAG\_OUT MUX is enabled. Software or hardware modification may be needed in the application. For hardware modifications check the SDO threshold level and drive capability if resistors are used to adjust the voltage level of SDO on the SPI bus.

# 5.4.1.9 Analog MUX (AMUX)

Table 5-4 lists the selectable-analog internal signals on the DIAG\_OUT pin. In the DIAG\_CFG\_CTRL register, the MUX\_CFG bits must be set to 10 for the analog MUX mode.

SIGNAL NUMBER	VOLTAGE RAIL/ SIGNAL NAME	DESCRIPTION	DIVIDE RATIO	VOLTAGE RANGE / ACCURACY <sup>(1)</sup>	MAXIMUM OUTPUT RESISTANCE (kΩ)	DIAG_MUX_SEL[3:0]
A.1	VDD5	Linear VDD5 regulator output	2 ± 1.5%	2.5 V ±2%	55	0x01
A.2	VDD6	Switch-mode preregulator	3 ± 2.2%	2 V ±5%	140	0x02
A.3	VCP	External charge pump	13.5 ± 2%	0.6 to 4 V	1640	0x04
A.4	VSOUT1	Sensor-supply voltage	4 ± 0.5%	0.825 to 2.375 V	240	0x08
A.5	VBAT_SAFING	Safing battery supply	10 ± 2%	0.4 to 4 V	1755	0x10
A.6	VBAT	Battery supply	10 ± 2%	0.4 to 4 V	1755	0x20
A.7	MAIN_BG	Regulators bandgap reference	1	2.5 V ±2%	15	0x40
A.8	VMON_BG	Voltage-monitor band gap	1	2.5 V ±2%	15	0x80

# Table 5-4. Analog MUX Selection Table

(1) The given accuracies are without the DC load-current drawn from DIAG\_OUT pin. For overall accuracy calculation, the divide ratio accuracy and the drop voltage caused by I\_DIAG\_OUT × Max. Output Resistance must be considered.

In case one of these analog signals comes to a voltage above VDDIO, a clamp becomes active to avoid any voltage level higher than VDDIO on the DIAG\_OUT pin.

To achieve the fastest stabilization of the signal switched to DIAG\_OUT, following the AMUX switching order from A.1 up to A.8 is not recommended.

The recommendation is to switch the order from high to low voltage, starting with A.8. For example: A.8 - A.7 - A.1 - A.2 - A.3 - A.5 - A.6 - A.4.

# NOTE

The sensor-supply output voltage (VSOUT1) is 0 V in this example. If VSOUT1 is higher, then the switching order described in the previous example must be changed. In the application, a series resistance of at least 100 k $\Omega$  is required on the input capacitor filter of the ADC input of the MCU.

# 5.4.1.10 Digital MUX (DMUX)

The following tables list the selectable digital internal signals on the DIAG\_OUT pin. In the DIAG\_CFG\_CTRL register, the MUX\_CFG bits must be set to 01 for the digital MUX mode.

Most of these signals are internal error signals that influence the device state and behavior of the NRES pin and the ENDRV pin. See Table 5-2 for a more detailed table listing the internal error signals and their impact on the device behavior.

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SIGNAL NUMBER	SIGNAL NAME	DESCRIPTION	CHANNEL GROUP DIAG_MUX_SEL [6:4]	CHANNEL NUMBER DIAG_MUX_SEL [3:0]
D1.1	RSV	Reserved, logic 0	000	0000
D1.2	AVDD_UVN	AVDD undervoltage comparator output	000	0001
D1.3	BG_ERR1	VMON or main band gap is OFF	000	0010
D1.4	BG_ERR2	VMON or main band gap is OFF	000	0011
D1.5	VCP12_UVN	VCP12 charge-pump undervoltage comparator	000	0100
D1.6	VCP12_OV	VCP12 charge-pump overvoltage comparator	000	0101
D1.7	VCP17_OV	VCP17 charge-pump overvoltage comparator	000	0110
D1.8	VDD6_UVN	VDD6 undervoltage comparator	000	0111
D1.9	VDD6_OV	VDD6 overvoltage comparator	000	1000
D1.10	VDD5_UVN	VDD5 undervoltage comparator	000	1001
D1.11	VDD5_OV	VDD5 overvoltage comparator	000	1010
D1.12	VDD3/5_UVN	VDD3/5 undervoltage comparator	000	1011
D1.13	VDD3/5_OV	VDD3/5 overvoltage comparator	000	1100
D1.14	VDD1_UVN	VDD1 undervoltage comparator	000	1101
D1.15	VDD1_OV	VDD1 overvoltage comparator	000	1110
D1.16	LOCLK	Loss-of-system-clock comparator	000	1111

# Table 5-5. Digital MUX Selection Table – Group 1

# Table 5-6. Digital MUX Selection Table – Group 2

SIGNAL NUMBER	SIGNAL NAME	DESCRIPTION	CHANNEL GROUP DIAG_MUX_SEL [6:4]	CHANNEL NUMBER DIAG_MUX_SEL [3:0]
D2.1	RSV	Reserved, logic 0	001	0000
D2.2	SYS_CLK	System clock source	001	0001
D2.3	DFT	Signal reserved for production test	001	0010
D2.4	WDT_CLK	Watchdog clock reference (0.55-ms period time)	001	0011
D2.5	RST_EXT_CLK	Reset extension oscillator output	001	0100
D2.6	T_5US	5-µs time reference	001	0101
D2.7	T_15US	15-µs time reference	001	0110
D2.8	T_40US	40-µs time reference	001	0111
D2.9	T_2MS	2-ms time reference	001	1000
D2.10	UC_ERROR/WDI	External MCU ERROR/WDI input pin	001	1001
D2.11	SPI_NCS	SPI chip-select input pin	001	1010
D2.12	SPI_SDI	SPI slave-data input pin	001	1011
D2.13	SPI_CLK	SPI clock input pin	001	1100
D2.14	SDO_RDBCK	SPI slave-data output-pin readback	001	1101
D2.15	UC_ERROR/WDI	Same signal as 2.10	001	1110
D2.16	NRST_EXT_IN	NRES pin readback (reset to external MCU)	001	1111

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SIGNAL NUMBER	SIGNAL NAME	DESCRIPTION	CHANNEL GROUP DIAG_MUX_SEL [6:4]	CHANNEL NUMBER DIAG_MUX_SEL [3:0]
D3.1	RSV	Reserved, logic 0	010	0000
D3.2	DFT	Signal reserved for production test	010	0001
D3.3	DFT	Signal reserved for production test	010	0010
D3.4	CP_OV	Charge-pump overvoltage comparator	010	0011
D3.5	CP_UVN	Charge-pump undervoltage comparator	010	0100
D3.6	CP_PH1	Charge-pump switching phase 1	010	0101
D3.7	CP_PH2	Charge-pump switching phase 2	010	0110
D3.8	CP_DIFF3V	Indicates VCP-VBATP > 3 V	010	0111
D3.9	DFT	Signal reserved for production test	010	1000
D3.10	VBAT_UVN	VBAT undervoltage comparator	010	1001
D3.11	VBATP_OV	VBAT overvoltage comparator	010	1010
D3.12	VDD5_OT	VDD5 overtemperature	010	1011
D3.13	VDD3_5_OT	VDD3/5 overtemperature	010	1100
D3.14	VSOUT1_OT	VSOUT1 overtemperature	010	1101
D3.15	VDD5_CL	VDD5 current-limit	010	1110
D3.16	VDD3_CL	VDD3 current-limit	010	1111

# Table 5-7. Digital MUX Selection Table – Group 3

# Table 5-8. Digital MUX Selection Table – Group 4

SIGNAL NUMBER	SIGNAL NAME	DESCRIPTION	CHANNEL GROUP DIAG_MUX_SEL [6:4]	CHANNEL NUMBER DIAG_MUX_SEL [3:0]
D4.1	RSV	Reserved, logic 0	011	0000
D4.2	VSOUT1_CL	VSOUT1 current-limit	011	0001
D4.3	VSOUT1_UVN	VSOUT1 undervoltage comparator	011	0010
D4.4	VSOUT1_OV	VSOUT1 overvoltage comparator	011	0011
D4.5	DVDD_UVN	DVDD undervoltage comparator	011	0100
D4.6	DVDD_OV	DVDD overvoltage comparator	011	0101
D4.7	RSV	Reserved	011	0110
D4.8	VS_TRK_MODE	VSOUT1 in track-mode indication	011	0111
D4.9	VMON_TRIM_ERR	VMON trim error	011	1000
D4.10–16	RSV	Reserved	011	1001–1111

# Table 5-9. Digital MUX Selection Table – Group 5

SIGNAL NUMBER	SIGNAL NAME	DESCRIPTION	CHANNEL GROUP DIAG_MUX_SEL [6:4]	CHANNEL NUMBER DIAG_MUX_SEL [3:0]
D5.1	RSV	Reserved, logic 0	111	0000
D5.2	TI_TEST_MODE	TI production test mode indication	111	0001
D5.3 – 16	DFT	Signal reserved for production test	111	0010–1111

A diagnostic check at the SDO digital-output pin is also possible in DMUX mode. For this diagnostic check, the following sequence is required:

- MUX\_CFG[1:0] configuration must be set to 01 for DIGITAL MUX mode
- SPI NCS must be kept HIGH
- The state of SDO is controlled by the SPI\_SDO bit (bit D6 in the DIAG\_CFG\_CTRL register)

During this SDO check at the SDO pin, the DIAG\_OUT pin is kept low if no signal from the Digital MUX table is selected.

# 5.4.1.10.1 Diagnostic MUX Output State (by MUX\_OUT bit)

For a diagnostic interconnect check between the DIAG\_OUT pin and the MCU analog-digital input pin, the state of the DIAG\_OUT pin is controlled with SPI bit MUX\_OUT in DIAG\_CFG\_CTRL register. For using this mode, the MUX\_CFG[1:0] bits must be set to 00 in DIAG\_CFG\_CTRL register.

# 5.4.1.10.2 MUX Interconnect Check

For performing a diagnostic interconnect check at the digital input pins (ERROR/WDI, NCS, SDI, and SCLK) the MUX\_CFG[1:0] bits in the DIAG\_CFG\_CTRL register must be set to 11. With bits INT\_CON[2:0] in the DIAG\_CFG\_CTRL register, it can be selected which of these digital inputs is multiplexed to the DIAG\_OUT pin (see description of DIAG\_CFG\_CTRL register in Section 5.5.1).

# 5.4.1.11 Watchdog Timer (WDT)

The watchdog monitors the correct operation of the MCU. This watchdog requires specific triggers or messages from the MCU in specific time intervals to detect correct operation of the MCU. The MCU can control the logic level of the ENDRV pin with the ENABLE\_DRV bit when the watchdog detects correct operation of the MCU. When the watchdog detects incorrect operation of the MCU, the device pulls the ENDRV pin low. This ENDRV pin can be used in the application as a control-signal to deactive the power output stages, for example a motor driver, in case of incorrect operation of the MCU. This function is consequently referred to as the watchdog-enabled function.

The watchdog has two different modes which are defined as follows:

**Trigger mode:** In trigger mode, the MCU applies a trigger (pulse) on the ERROR/WDI pin to send the required watchdog event for trigger mode. The watchdog operates in trigger mode as the default mode when the device goes from the RESET state to the DIAGNOSTIC state. The MCU error signal monitor (ESM) should not be used when the watchdog operates in trigger mode.

Question-answer mode (Q&A mode): In Q&A mode, the MCU sends watchdog answers through SPI.

To select the Q&A mode, the MCU must set the WD\_CFG bit (bit 5) in the safety-function configuration register (SAFETY\_FUNC\_CFG) while in DIAGNOSTIC state. When the watchdog operates in Q&A mode, the MCU Error Signal Monitor may be used.

# 5.4.1.12 Watchdog Fail Counter, Status, and Fail Event

The watchdog includes a watchdog fail counter (WDT\_FAIL\_CNT[2:0]) which increments because of *bad events* or decrements because of *good events*. When the value of the watchdog fail counter is 5 or more, the watchdog status is out-of-range, and the ENDRV pin is low (the watchdog-enabled function is disabled).

When the watchdog fail counter is 4 or less, the watchdog status is in-range, and the watchdog no longer disables the watchdog-enabled function. In this case, the device pulls up the ENDRV pin when the ENABLE\_DRV control bit (in the SAFETY\_CHECK\_CTRL register) is set and when the device detects no other errors that impact the level of the ENDRV pin.

The watchdog fail counter operates independently of the state of the watchdog reset configuration bit (bit 3), WD\_RST\_EN, in the SAFETY\_FUNC\_CFG register.

The watchdog fail counter responds as follows:

- A good event decrements the fail counter by one, down to the minimum of zero.
- A *bad event* increments the fail counter by one, up to the maximum of seven.
- A *time-out event* increases the fail counter by one, up to the maximum of seven, and sets the TIME\_OUT flag (WDT\_STATUS register, bit 1)

The definitions of *good event*, *bad event* and *time-out event* are listed in the sections describing the Trigger mode and Q&A mode.

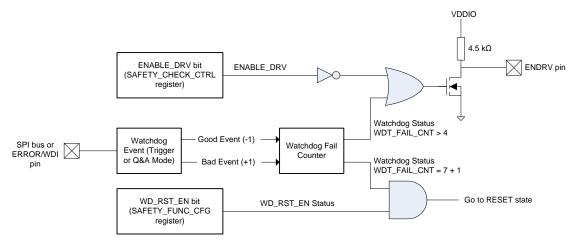


Figure 5-5. Watchdog Impact on ENDRV and RESET

Table 5-10. Watchdog Status for Range of the Watchdog Fail Coun	ter Value
---	-----------

WATCHDOG FAIL COUNTER WDT_FAIL_CNT[2:0]	06000-06100	0b101–0b111	0b111
The watchdog status is based on the WDT_FAIL_CNT [2:0] counter value.	Watchdog in-range	Watchdog is out-of-range	If the WD_RST_EN bit is set to 1, the NRES pin is pulled low, the device is in the RESET state

The watchdog fail counter is initialized to a count of 5 when the device enters DIAGNOSTIC state (after going through RESET state) and when the device transitions from DIAGNOSTIC state to ACTIVE state.

When the watchdog fail counter reaches a count of 7, another *bad event* does not change the counter: the counter remains at 7. However, if the watchdog reset is enabled (WD\_RST\_EN bit in the SAFETY\_FUNC\_CFG register is set to 1), on the next *bad event* (7 + 1) the device enters RESET state and will reset the MCU by pulling the NRES pin low. In RESET state, the watchdog fail counter reinitializes to 5.

If the watchdog fail counter is at seven when WD\_RST\_EN is set to one, the device will immediately enter the RESET state without requiring another *bad event*.



# 5.4.1.13 Watchdog Sequence

Each watchdog sequence begins with a Window 1 followed by a Window 2. The MCU can program the time periods of Window 1 ( $t_{WIN1}$ ) and Window 2 ( $t_{WIN2}$ ) with the WDT\_WIN1\_CFG and WDT\_WIN2\_CFG registers respectively when the device is in the DIAGNOSTIC state. When the device goes from the RESET state to the DIAGNOSTIC state, the watchdog sequence begins with the default  $t_{WIN1}$  and  $t_{WIN2}$  time periods.

Use Equation 1 and Equation 2 to calculate the minimum and maximum values for the  $t_{WIN1}$  time period. Use Equation 3 and Equation 4 to calculate the minimum and maximum values for the  $t_{WIN2}$  time period.

 $t_{WIN1 MIN} = ((RT[6:0] - 1) \times 0.55 \times 0.95) ms$ 

where

The bits RT[6:0] are located in SPI register WDT_WIN1_CFG.	(1)
t <sub>WIN1_MAX</sub> = (RT [6:0] × 0.55 × 1.05) ms	(.)
where	
• The bits RT[6:0] are located in SPI register WDT_WIN1_CFG.	(2)
$t_{WIN2\_MIN} = ((RW[4:0] + 1) \times 0.55 \times 0.95) ms$	
where	
• The bits RW[4:0] are located in SPI register WDT_WIN2_CFG.	(3)
$t_{WIN2_MAX} = ((RW[4:0] + 1) \times 0.55 \times 1.05) ms$	.,
where	

• The bits RW[4:0] are located in SPI register WDT\_WIN2\_CFG.

(4)

The SPI SW\_LOCK command locks the WDT\_WIN1\_CFG and WDT\_WIN2\_CFG registers to prevent write updates in the DIAGNOSTIC state.

If the MCU stops sending *events*, or stops *feeding the watchdog* during the watchdog sequence, the watchdog considers this lack of response from the MCU a *time-out event* (*no response event*). This will set the TIME\_OUT status bit (register WDT\_STATUS, bit 1) and increments the watchdog fail counter. Immediately following a *time-out event* the next watchdog sequence is started.

Based on Window 1 and Window 2 time periods, the watchdog sequence and time-out time periods are calculated as follows:

$t_{sequence_{MIN}} = t_{TIMEOUT_{MIN}} = t_{WIN1_{MIN}} + t_{WIN2_{MIN}}$	(5)
$t_{sequence_{Max}} = t_{timeout_{Max}} = t_{win1_{Max}} + t_{win2_{Max}}$	(6)

The watchdog uses the device's internal system clock ( $\pm$ 5% accuracy) as a time reference for creating the 0.55-ms watchdog time step. WINDOW 1 may be up to one 0.55-ms watchdog time step shorter than programmed as indicated by Equation 1.

# NOTE

Because of the uncertainty in the Window 1 and Window 2 time periods, TI recommends to use settings for WINDOW 1 and WINDOW 2 of two or higher. WINDOW 2 could be set as low as one, assuming WINDOW 1 is set to six or lower. The response from the MCU should be targeted to the mid point of known timing for WINDOW 2. As WINDOW 1 setting is increased above six, the device system clock tolerance (±5%) will become large compared to a setting of one in WINDOW 2 not allowing for a known time range for a response in WINDOW 2, so WINDOW 2 setting must be scaled with WINDOW 1 to allow timing margin.

# 5.4.1.14 MCU to Watchdog Synchronization

To synchronize the MCU with the watchdog sequence, the MCU can write to either the WIN1\_CFG or WIN2\_CFG registers to start a new watchdog sequence. After a write access to the WIN1\_CFG or WIN2\_CFG register by the MCU (even when these registers are locked or when the DEVICE is in the ACTIVE or the SAFE state), the device immediately starts a new watchdog sequence and increments the watchdog fail counter. Therefore a write access to the WDT\_WIN1\_CFG or WDT\_WIN2\_CFG register only takes effect in this new watchdog sequence.

When the MCU is synchronized with the watchdog sequence, a *good event* from the MCU immediately starts a new watchdog sequence. In this way, the MCU stays synchronized with the watchdog sequence.

See Figure 6-11 for an example software flowchart of how to synchronize the MCU with the TPS65381-Q1 watchdog.

# 5.4.1.15 Trigger Mode (Default Mode)

When the device goes from the RESET state to the DIAGNOSTIC state, the watchdog operates in trigger mode (default). The first watchdog sequence begins with the default  $t_{WIN1}$  and  $t_{WIN2}$  time periods. The watchdog receives the triggers from the MCU on the ERROR/WDI pin. A rising edge on the ERROR/WDI pin, followed by a falling edge on the ERROR/WDI pin after more than the required pulse time,  $t_{WD\_pulse(max)}$  (32 µs), is a trigger.

Window 1, called a CLOSE window, is the first window in the watchdog sequence. A trigger received in Window 1 is a *bad event* and ends Window 1 and starts a new watchdog sequence.

Window 2, called an OPEN window, follows Window 1. At a minimum, Window 2 lasts until a trigger is received. At a maximum, Window 2 lasts until the programmed  $t_{WIN2}$  time. A trigger received in Window 2 (OPEN) is a *good event*. A new watchdog sequence begins immediately after the watchdog receives a trigger in Window 2.

If the MCU stops sending triggers during the watchdog sequence, the watchdog considers this lack of response from the MCU a *time-out event* (*no response event*). This will set the TIME\_OUT status bit (register WDT\_STATUS, bit 1) and increments the watchdog fail counter. Immediately following a *time-out event* a new watchdog sequence is started.

The TIME\_OUT flag may be useful for the MCU software to re-synchronize its watchdog trigger pulse events to the required device watchdog timing. When re-synchronizing in this way, the MCU detects the TIME\_OUT flag being set. TIME\_OUT flag being set indicates the *time-out event* and the start of a new watchdog sequence. The MCU should send the trigger with timing so the trigger will be in WINDOW 2 (OPEN) of this new watchdog sequence.

#### NOTE

If there is an active SPI frame (nCS is low) when the *time-out event* occurs, the TIME\_OUT flag will not be latched (set) in the WDT\_STATUS register, but the watchdog fail counter will still be incremented. Since the TIME\_OUT flag is not latched this will impact the resynchronization ability of the MCU and status monitoring.

In trigger mode, the watchdog uses a deglitch filter with  $t_{WD_pulse}$  filter time and an internal system clock to create the internally generated watchdog pulse (see Figure 5-6 and Figure 5-7).

The rising edge of the trigger on the ERROR/WDI pin must occur at least the  $t_{WD_pulse(max)}$  time before the end of Window 2 (OPEN) to generate a good event.

WINDOW 1 (CLOSE) and WINDOW 2 (OPEN) window duration times are programmed through the registers WDT\_WIN1\_CFG and WDT\_WIN2\_CFG when the device is in DIAGNOSTIC state. In Trigger mode, the window duration time are as follows:

 $t_{WCW\_MIN}$  (Trigger Mode) =  $t_{WIN1\_MIN}$ 

where

WCW is Watchdog CLOSE Window

 $t_{WCW\_MAX}$  (Trigger Mode) =  $t_{WIN1\_MAX}$ 

where

• WCW is Watchdog CLOSE Window

 $t_{WOW\_MIN}$  (Trigger Mode) =  $t_{WIN2\_MIN}$ 

where

• WOW is Watchdog OPEN Window

 $t_{WOW\_MIN}$  (Trigger Mode) =  $t_{WIN2\_MIN}$ 

where

• WOW is Watchdog OPEN Window

(10)

(7)

(8)

(9)

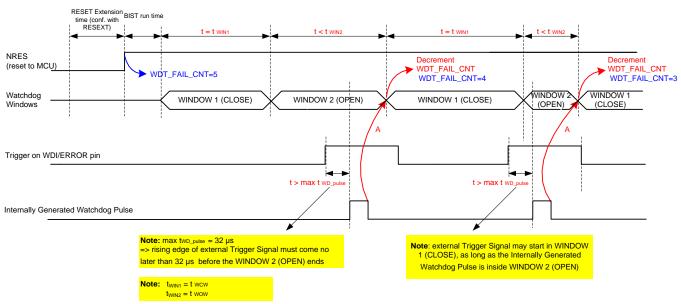
Use Equation 1 and Equation 2 to calculate the minimum and maximum values for the  $t_{WIN1} = t_{WCW}$  time period. Use Equation 3 and Equation 4 to calculate the minimum and maximum values for the  $t_{WIN2} = t_{WOW}$  time period.

Writing a new WINDOW 1 or WINDOW 2 time to WDT\_WIN1\_CFG or WDT\_WIN2\_CFG register immediately begins a new watchdog sequnce and increments the watchdog fail counter.

The SPI SW\_LOCK command locks a write update for the WDT\_WIN1\_CFG register and the WDT\_WIN2\_CFG SPI register, however writing to either of these registers will immediately being a new new watchdog sequence and increment the watchdog fail counter

The watchdog trigger event is considered a *good-event* if received during a WINDOW 2 (OPEN) window, and is considered a *bad-event* if received during WINDOW 1 (CLOSE) window. A *good-event* ends the current watchdog sequence and starts a new watchdog sequence, thus the MCU and device watchdog timing stay synchronized.

A good-event, bad-event, time-out event, power-up event, or power-down event ends the current watchdog sequence and starts a new watchdog sequence.

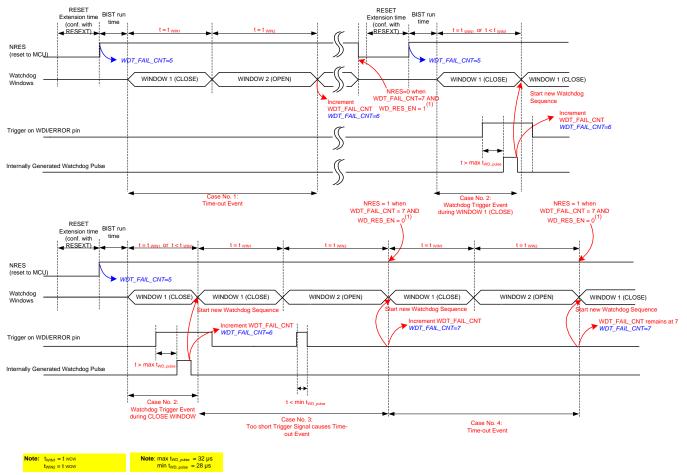


Note: When a *good event* is received in WINDOW 2 (OPEN), 1 system clock-cycle (250 ns, typical) later the next watchdog sequence begins. Therefore the actual length of WINDOW 2 (OPEN) depends on when the MCU sends the *good event*.

Figure 5-6. Example Cases for Good-Events in Trigger Mode



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(1) WD\_RST\_EN = 0 per default

(2) When a *bad event* is received in WINDOW 1 (CLOSE), 1 system clock-cycle (250 ns, typical) later the next watchdog sequence begins. Therefore the actual length of WINDOW 1 (CLOSE) depends on when the MCU sends the *bad event* 

# Figure 5-7. Example Cases for Bad-Event and Time-out Events in Trigger Mode

# 5.4.1.16 Q&A Mode

Setting the WD\_CFG bit in the SAFETY\_FUNC\_REG register to 1 when the device is in DIAGNOSTIC state configures the watchdog for Q & A (question and answer) mode. In Q&A mode, the device provides a *question (or TOKEN)* for the MCU in the WDT\_TOKEN\_VALUE register. The MCU performs a fixed series of arithmetic operations on the question to calculate the required 32-bit answer. This answer is split into four answer bytes or responses. The MCU writes these answer bytes through SPI one byte at a time into the WDT\_ANSWER register. The device verifies that the MCU returned the answer bytes within the specified timing windows, and that the answer bytes are correct.

A *good event* occurs when the MCU sends the correct answer bytes calculated for the current question within the correct watchdog window and in the correct order.

A *bad event* occurs when one of the events that follows occur:

- The MCU sends the correct answer bytes, but not in the correct watchdog window.
- The MCU sends incorrectly calculated answer bytes.
- The MCU returns correct answer bytes in the wrong order (sequence).

If the MCU stops sending answer bytes during the watchdog sequence, the watchdog considers this lack of response from the MCU a *time-out event* (*no response event*). This will set the TIME\_OUT status bit (register WDT\_STATUS, bit 1) and increments the watchdog fail counter. Immediately following a *time-out event* a new watchdog sequence is started.

The TIME\_OUT flag may be useful for the MCU software to re-synchronize its watchdog answer timing to the required device watchdog timing. When re-synchronizing in this way, the MCU detects the TIME\_OUT flag being set. TIME\_OUT flag being set indicates the *time-out event* and the start of a new watchdog sequence. The MCU should send the answer bytes with timing so they will be in the correct windows of the new watchdog sequence.

#### NOTE

If there is an active SPI frame (nCS is low) when the *time-out event* occurs, TIME\_OUT flag will not be latched (set) in the WDT\_STATUS register, but the watchdog fail counter will still be incremented. Since the TIME\_OUT flag is not latched this will impact the resynchronization ability of the MCU and status monitoring.

# NOTE

In Q&A mode, each watchdog sequence starts with WINDOW 1 (OPEN) and followed by WINDOW 2 (CLOSE). Please note the OPEN and CLOSE references for Q&A mode are reversed with respect to those of Trigger mode, but the order of the WINDOW 1 and WINDOW 2 is the same as are the registers containing the setting for each window, WDT\_WIN1\_CFG and WDT\_WIN2\_CFG.



# 5.4.1.16.1 Watchdog Q&A Related Definitions

# Question (Token)

- The question (token) is a 4-bit word (see Section 5.4.1.16.3).
- The watchdog provides the question (token) to the MCU when the MCU reads the question (TOKEN[3:0]) from register WDT\_TOKEN\_VALUE.
- The MCU can request each new question (token) at the start of the watchdog sequence, but this is not required to calculate the answer. The MCU can also generate the question by implementing the question generation circuit as shown in Figure 5-9. Nevertheless, the answer and, and therefore the answer bytes, are always based on the question generated inside the watchdog of the device. So if the MCU generates a wrong question and gives answer bytes calculated from a wrong question, the watchdog detects a *bad event*.
- A new question (token) is generated only when a *good event* occured in the previous watchdog sequence causing the Token Counter (internal counter) to increment and generate a new question (token) as shown in figure Figure 5-9.

# Answer (Response)

- The answer (response) is a 32-bit word that is split into four answer bytes or responses: Answer-3 (WD\_TOKEN\_RESP\_3), Answer-2 (WD\_TOKEN\_RESP\_2), Answer-1 (WD\_TOKEN\_RESP\_1), and Answer-0 (WD\_TOKEN\_RESP\_0).
- The watchdog receives an answer byte when the MCU writes to the watchdog answer register (the WDT\_ANSW[7:0] bits in the WDT\_ANSWER register).
- For each question, the watchdog requires four correct answer bytes from the MCU in the correct timing and order (sequence). Answer-3, Answer-2, and Answer-1 may be in in Window 1 or Window 2 in the correct order, and Answer-0 must be in Window 2 to be detected as a *good event*.

# 5.4.1.16.2 Watchdog Sequence in Q&A Mode

The watchdog sequence in Q&A mode ends after the MCU writes the fourth answer byte, Answer-0 (WD\_TOKEN\_RESP\_0), or after a time-out event. A new watchdog sequence will start after the previous watchdog sequence ends.

WINDOW 1 (OPEN) and WINDOW 2 (CLOSE) window duration times are programmed through the registers WDT\_WIN1\_CFG and WDT\_WIN2\_CFG when the device is in DIAGNOSTIC state. In Q&A mode, the window duration time are as follows:

 $t_{WOW\_MIN}$  (Q&A Mode) =  $t_{WIN1\_MIN}$ 

where

WOW is Watchdog OPEN Window

 $t_{WOW\_MAX}$  (Q&A Mode) =  $t_{WIN1\_MAX}$ 

where

WOW is Watchdog OPEN Window

 $t_{WCW\_MIN}$  (Q&A Mode) =  $t_{WIN2\_MIN}$ 

where

• WCW is Watchdog CLOSE Window

 $t_{WCW\_MIN}$  (Q&A Mode) =  $t_{WIN2\_MIN}$ 

where

WCW is Watchdog CLOSE Window

Use Equation 1 and Equation 2 to calculate the minimum and maximum values for the  $t_{WIN1} = t_{WOW}$  time period. Use Equation 3 and Equation 4 to calculate the minimum and maximum values for the  $t_{WIN2} = t_{WCW}$  time period.

(11)

(12)

(13)

(14)

Writing a new WINDOW 1 or WINDOW 2 time to WDT\_WIN1\_CFG or WDT\_WIN2\_CFG register immediately begins a new watchdog sequnce and increments the watchdog fail counter.

The SPI SW\_LOCK command locks a write update for the WDT\_WIN1\_CFG register and the WDT\_WIN2\_CFG SPI register, however writing to either of these registers will immediately being a new new watchdog sequence and increment the watchdog fail counter.

		WINDOW 1 (OPEN)	WINDOW 2 (CLOSE)	
		Programmed through WDT_WIN1_CFG register $t = t_{\text{WN1}}$	Programmed through WDT_WIN2_CFG register $t = t_{\text{WN2}}$	
	WINDOW 2. The Answer Answer After WINDOW 1	rrect answer bytes (responses) may be scheduled in WINDOW 1 or first three answer bytes must be in the correct order (sequence): r-3 (WD_TOKEN_RESP_3) followed by r-2 (WD_TOKEN_RESP_2) followed by r-1 (WD_TOKEN_RESP_1) time elapses, WINDOW 2 begins to write the answer bytes (responses) to WDT_ANSWER register.	The fourth answer byte, Answer-0 (WD_TOKEN_RESP_0) must provided in WINDOW 2. After the MCU writes the fourth answer byte (Answer-0) to the WDT_ANSWER register, the watchdog generates the next question (token) after which next watchdog sequence begins.	
	Question	Answer		
SPI	MCU reads question	MCU provides answer		
nmands	Ľ			
CS pin		LĮ LĮ LĮ	Ļ	
   			1 internal clock cycle (250 ns) to generate new question for (Q&A [n + 1])	<b> ↓</b>
Х	·	Q&A [n]		Q&A [n + 1]
	<	WATCHDOG SEQUENCE	•	
i	2* = Answer-2 to W 1* = Answer-2 to W	KEN_VALUE KI_WDT_ANSWER /R_WDT_ANSWER /R_WDT_ANSWER /K_WDT_ANSWER		!

- (1) The MCU is not required to read the question (token). The MCU can begin giving the correct answer bytes Answer-3, Answer-2, Answer-1, anywhere in Window 1 or Window 2. The new question (token) is generated and a new watchdog sequence started within 1 system clock cycle after the final Answer-0 as long as the answer was a *good event*. A *bad event* or *time-out event* will cause a new watchdog sequence to start, however a new question (token) will not be generated.
- (2) The MCU can put other SPI commands in-between the WR\_WDT\_ANSWER commands (even re-requesting the question). These SPI commands have no influence on the detection of a *good event*, as long as the four correct answer bytes are in the correct order, and the fourth correct answer byte is provided in Window 2.

#### Figure 5-8. Watchdog Sequence in Q&A Mode

# 5.4.1.16.3 Question (Token) Generation

The watchdog uses a 4-bit token counter (TOKEN\_CNT[3:0] bits in Figure 5-9), and a 4-bit Markov chain to generate a 4-bit question (token). The MCU can read this question in the WDT\_TOKEN\_VALUE register, the TOKEN[3:0] bits. The watchdog generates a new question when the token counter increments, which only occurs when the watchdog detects a *good event*. The watchdog does not generate a new question when it detects a *bad event* or a *time-out event*. The watchdog does not generate a new question for a watchdog sequence which starts after the MCU writes to the WD\_WIN1\_CFG or WD\_WIN2\_CFG registers.

The token counter provides a clock pulse to the Markov chain when it transitions from 4'b1111 to 4'b0000. The question counter and the Markov chain are set to the singular default value of 4'b0000 when the device goes to the RESET state. To leave the singular point, the feedback logic combination is implemented.

Figure 5-9 shows the logic combination for the question (token) generation. The question is in WDT\_TOKEN\_VALUE register, TOKEN[3:0] bits.

The logic combination of the token counter with the WDT\_ANSW\_CNT[1:0] status bits (in the WDT\_STATUS register) generates the reference answer bytes as shown in Figure 5-9.

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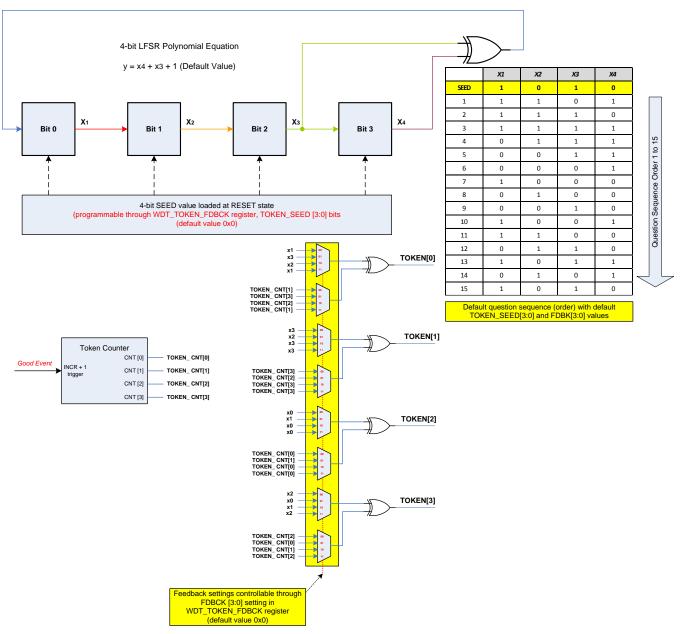
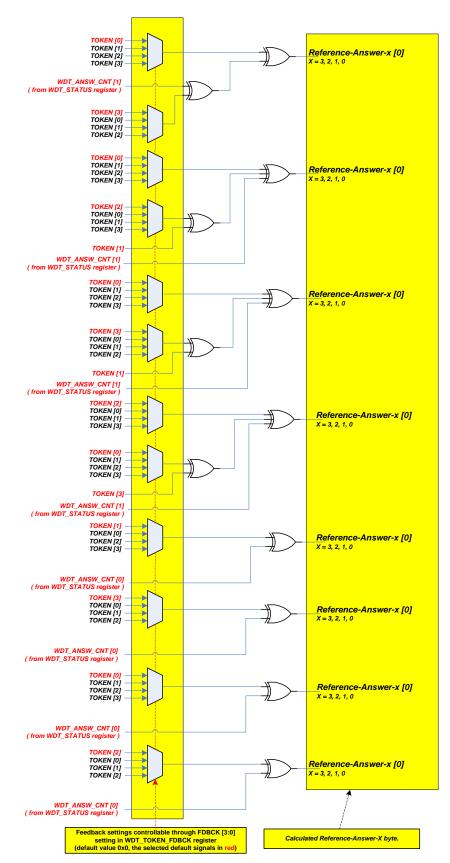
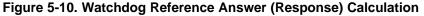


Figure 5-9. Watchdog Question (Token) Generation







# 5.4.1.16.3.1 Answer Comparison and Reference Answer

The 2-bit, watchdog-answer counter, WDT\_ANSW\_CNT[1:0], in the WD\_STATUS register counts the number of received answer bytes and controls the generation of the Reference Answer-x byte as shown in Figure 5-10. At the start of each watchdog sequence, the default value of the WDT\_ANSW\_CNT[1:0] is 2'b11 to indicate that the watchdog expects the MCU to write Answer-3 (WDT\_RESP\_3) in the WDT\_ANSWER register.

# Sequence of the 2-bit Watchdog Answer Counter

The sequence of the 2-bit, watchdog answer counter, WDT\_ANSW[1:0], is as follows for each counter value:

- WDT\_ANSW\_CNT[1:0] = 2'b11:
  - The watchdog calculates reference Answer-3
  - A write access occurs: the MCU writes Answer-3 (WD\_TOKEN\_RESP\_3) byte in the WDT\_ANSWER register.
  - The watchdog compares the Reference Answer-3 with the Answer-3 byte in the WDT\_ANSWER register.
  - The watchodg decrements the WDT\_ANSW\_CNT[1:0] bits to 2b'10 and updates the TOKEN\_ERR flag bit.
- WDT\_ANSW\_CNT[1:0] = 2'b10:
  - The watchdog calculates reference Answer-2
  - A write access occurs: the MCU writes Answer-2 (WD\_TOKEN\_RESP\_2) byte in the WDT\_ANSWER register.
  - The watchdog compares the Reference Answer-2 with the Answer-2 byte in the WDT\_ANSWER register.
  - The watchodg decrements the WDT\_ANSW\_CNT[1:0] bits to 2b'01 and updates the TOKEN\_ERR flag bit.
- WDT\_ANSW\_CNT[1:0] = 2'b01:
  - The watchdog calculates reference Answer-1
  - A write access occurs: the MCU writes Answer-1 (WD\_TOKEN\_RESP\_1) byte in the WDT\_ANSWER register.
  - The watchdog compares the Reference Answer-1 with the Answer-1 byte in the WDT\_ANSWER register.
  - The watchodg decrements the WDT\_ANSW\_CNT[1:0] bits to 2b'00 and updates the TOKEN\_ERR flag bit.
- WDT\_ANSW\_CNT[1:0] = 2'b00
  - The watchdog calculates reference Answer-0
  - A write access occurs: the MCU writes Answer-0 (WD\_TOKEN\_RESP\_0) byte in the WDT\_ANSWER register.
  - The watchdog compares the Reference Answer-0 with the Answer-0 byte in the WDT\_ANSWER register.
  - The watchodg updates the TOKEN\_ERR flag bit.
  - The watchdog starts a new watchdog sequence and sets the WDT\_ANSW\_CNT[1:0] to 2'b11.



# Table 5-11. Set of Questions (Tokens) and Corresponding Answer Bytes Using Default Setting of WDT\_TOKEN\_FDBK Register

QUESTION (TOKEN)	EN) WDT ANSWER (TO BE WRITTEN INTO WDT_ANSW REGISTER)			ſER)	
IN WDT_TOKEN_VALUE REGISTER	Answer-3 (WD_TOKEN_ RESP_3)	Answer-2 (WD_TOKEN_ RESP_2)	Answer-1 (WD_TOKEN_ RESP_1)	Answer-0 (WD_TOKEN_ RESP_0)	
TOKEN [3:0]	WDT_ANSW_CNT [1:0] = 11	WDT_ANSW_CNT [1:0] = 10	WDT_ANSW_CNT [1:0] = 01	WDT_ANSW_CNT [1:0] = 00	
0x0	FF	0F	F0	00	
0x1	B0	40	BF	4F	
0x2	E9	19	E6	16	
0x3	A6	56	A9	59	
0x4	75	85	7A	8A	
0x5	3A	CA	35	C5	
0x6	63	93	6C	9C	
0x7	2C	DC	23	D3	
0x8	D2	22	DD	2D	
0x9	9D	6D	92	62	
0xA	C4	34	СВ	3B	
0xB	8B	7B	84	74	
0xC	58	A8	57	A7	
0xD	17	E7	18	E8	
0xE	4E	BE	41	B1	
0xF	01	F1	0E	FE	

# 5.4.1.16.4 Watchdog Q&A Mode Sequence Events and WDT\_STATUS Register Updates

The watchdog sequence events are as follows for the different scenarios listed:

- A *good event* occurs when all answer bytes are correct in value (the TOKEN\_ERR bit is set to 0) and timing. For such a good event, then the events that follow occur:
  - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] decrements by one
  - The Token Counter increments by one, causing a new question (token) to be generated
  - The SEQ\_ERR bit resets
  - The TOKEN\_EARLY bit resets
- A *bad event* occurs when all answer bytes are correct in value (the TOKEN\_ERR bit is set to 0) but not in correct timing. For such a bad event, then the events that follow occur:
  - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] increments by one
  - The Token Counter does not change, thus the question (token) does not change
  - The SEQ\_ERR bit is set
  - The TOKEN\_EARLY bit is set
- A *bad event* occurs when one or more of the answer bytes are not correct in value (the TOKEN\_ERR bit is set to 1) but in correct timing. For such a bad event, then the events that follow occur:
  - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] increments by one
  - The Token Counter does not change, thus the question (token) does not change
  - The SEQ\_ERR bit is set
  - The TOKEN\_EARLY bit is reset

- A *bad event* occurs when one or more of the answer bytes are not correct in value (the TOKEN\_ERR status bit is set to 1) and not in correct timing. For such a bad event, then the events that follow occur:
  - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] increments by one
  - The Token Counter does not change, thus the question (token) does not change
  - The SEQ\_ERR bit is set
  - The TOKEN\_EARLY bit is set
  - In case a *time-out event* occurs, then the events that follow occur:
    - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] increments by one
    - The Token Counter does not change, thus the question (token) does not change
    - The TIME\_OUT bit is set
- In case the MCU writes to registers WDT\_WIN1\_CFG or WDT\_WIN2\_CFG, the events that follow occur:
  - The watchdog fail counter, WDT\_FAIL\_CNT[2:0] increments by one
  - The WD\_CFG\_CHG bit is set

	WATCHDOG SEQUENCE EVENTS				v	DT_STATUS	REGISTER BI	TS
All MCU Answer Bytes Correct?	Answer-0 Arrived During WINDOW 2 (CLOSE)	Answer-0 Arrived During WINDOW 1 (OPEN)	Time-out Occurred While Waiting for Answer?	WINDOW 1 or WINDOW 2 Duration Changed?	WD_CFG_ CHG	SEQ_ERR	TIME_OUT	TOKEN_EA RLY
Yes	Yes	No	No	No	0	0	0	0
Yes	No	Yes	No	No	0	1	0	1
No	Yes	No	No	No	0	1	0	0
No	No	Yes	No	No	0	1	0	1
Yes	—	—	Yes	No	0	0	1	0
No	—	—	Yes	No	0	1	1	0
_	—	—	_	Yes	1	0	0	0

# Table 5-12. WDT\_STATUS Bits Versus Possible Watchdog Sequence Events

# 5.4.1.17 MCU Error Signal Monitor (MCU ESM)

This block monitors the external-MCU error conditions signaled over the ERROR/WDI input pin. This block is configurable to monitor two different signaling options:

- Detecting a low-pulse signal with programmable low-pulse duration threshold (TMS570 mode, see Section 5.4.1.17.1)
- Detecting the PWM signal with programmable frequency and duty cycle (PWM mode, see Section 5.4.1.17.2) <sup>(1)</sup>

The error-signal monitor is deactivated by default, and activates by setting bit NO\_ERROR to 0 in the SAFETY\_CHECK\_CTRL SPI register. Note that activating the error-signal monitor is only recommended when the watchdog is configured in question-answer (Q&A) mode, otherwise the ERROR/WDI pin is used both for watchdog trigger input and MCU error signaling.

The operating mode is controlled through the ERROR\_CFG bit in the SAFETY\_FUNC\_CFG register. The low-signaling duration threshold (for TMS570 mode) or the expected PWM low-pulse duration (for PWM mode) is set through the SAFETY\_ERR\_PWM\_L register, and expected PWM high-pulse duration (for PWM mode) is set through the SAFETY\_ERR\_PWM\_H register.

A detected MCU signaling error is stored in bit ERROR\_PIN\_FAIL in the SAFETY\_ERR\_STAT SPI register. When the TPS65381-Q1 device is in DIAGNOSTIC state, the MCU emulates a signaling error (emulated fault-injection) for a diagnostic check of the error-signal monitor by checking the status of the ERROR\_PIN\_FAIL bit. When the TPS65381-Q1 device is in ACTIVE state, a detected MCU signaling error leads to a transfer into SAFE state, and a dedicated 4-bit error counter (bits DEV\_ERR\_CNT[3:0] in the SAFETY\_ERROR\_STAT SPI register) counts the transitions from ACTIVE state to SAFE state.

(1) PWM mode can be used as an external clock-monitor function.



For both error-signal monitor operating-modes, the ERROR/WDI input pin is deglitched with a 15- $\mu$ s (with ± 5% accuracy) filter time, and synchronized to internal system clock within 500 ns (with ± 5% accuracy). The deglitched and synchronized ERROR/WDI signal is monitored.

The module is covered by a logic BIST and is activated at a device power-up event or by the external MCU when the device is in the DIAGNOSTIC or ACTIVE state.

# 5.4.1.17.1 TMS570 Mode

An error condition is detected when the ERROR/WDI pin remains low for a programmed amount of time set by the SAFETY\_ERR\_PWM\_L register. The programmable time range is 5  $\mu$ s to 1.28 ms, with 5- $\mu$ s steps.

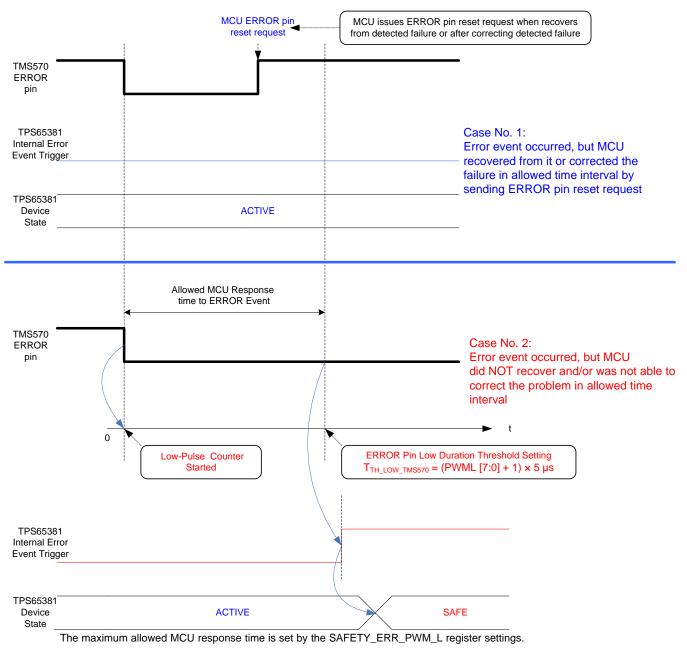
The SAFETY\_ERR\_PWM\_L register must be set to the desired value based on the maximum required time for the TMS570 MCU to detect an error or fault and to potentially recover from or correct the error or fault. Figure 5-11 shows the error-detection case scenarios.

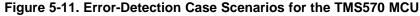
The low-pulse monitoring on the ERROR/WDI pin is implemented as follows:

- When NO\_ERROR = 0, every falling edge of the deglitched or synchronized ERROR/WDI signal reinitializes the low-pulse duration counter to 0 within one system clock-cycle (250 ns ± 5%).
- After reinitialization, the low-pulse counter restarts one system clock-cycle (250 ns ± 5%).
- The low-pulse duration counter increases every 5 µs (with ± 5% accuracy) as long as the ERROR/WDI pin is low. A rising edge on the ERROR/WDI pin stops the low-pulse duration counter
- When low-pulse duration counter is equal SAFETY\_ERR\_PWM\_L register setting, the ERROR/WDI pin signaling failure is detected.

The ERROR\_PIN\_FAIL bit in the SAFETY\_ERR\_STAT SPI register is set within one system clock cycle (250 ns  $\pm$  5%) after detecting an MCU signaling error. When the device is in ACTIVE state, a transition to SAFE state occurs after one more system clock-cycle.

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# 5.4.1.17.2 PWM Mode

- The TPS65381-Q1 device detects an MCU signaling error on the ERROR/WDI pin if the following occurs:
- The ERROR/WDI pin high-pulse duration exceeds the threshold value programmed by the PWM\_H
  register
  - OR
- The ERROR/WDI pin low-pulse duration exceeds the threshold value programmed by the PWM\_L register

The TPS65381-Q1 device does NOT detect an MCU signaling error on the ERROR/WDI pin if the following occurs:

The ERROR pin high-pulse duration is less than the threshold value programmed by the PWM\_H register

AND

• The ERROR pin low-pulse duration is less than the threshold value programmed by the PWM\_L register

The programmable time range for the expected HIGH and LOW pulse duration is 5  $\mu$ s to 1.28 ms, with 5- $\mu$ s resolution steps.

The monitoring of the high-pulse duration and low-pulse duration is implemented as follows:

Low-Phase Monitoring:

- Every falling edge of the deglitched and synchronized ERROR/WDI signal, or setting the NO\_ERROR bit from 1 to 0 when the ERROR/WDI pin is low, re-initializes the low-pulse duration counter to 0 within one system clock-cycle (250 ns ± 5%).
- After reinitialization, the low-pulse counter re-starts after one system clock-cycle (250 ns ± 5%).
- The low-pulse duration counter increases every 15  $\mu$ s (with ± 5% accuracy)
- When the low-pulse duration counter is equal to the SAFETY\_ERR\_PWM\_L register setting, ERRORpin signaling failure is detected

High-Phase Monitoring:

- Every rising edge of the deglitched and synchronized ERROR/WDI signal, or setting the NO\_ERROR bit from 1 to 0 when the ERROR/WDI pin is high, reinitializes the high-pulse duration counter to 0 within one system clock-cycle (250 ns ± 5%).
- After reinitialization, the high-pulse counter re-starts after one system clock-cycle (250 ns ± 5%).
- The high-pulse duration counter increases every 15  $\mu$ s (with ± 5% accuracy)
- When high-pulse duration counter is equal SAFETY\_ERR\_PWM\_H register setting, error pin signaling failure is detected

The ERROR\_PIN\_FAIL bit in the SAFETY\_ERR\_STAT register is set within one system clock cycle (250 ns  $\pm$  5%) after detecting an MCU signaling error. When the device is in ACTIVE state, a transition to SAFE state occurs after one more system clock-cycle.

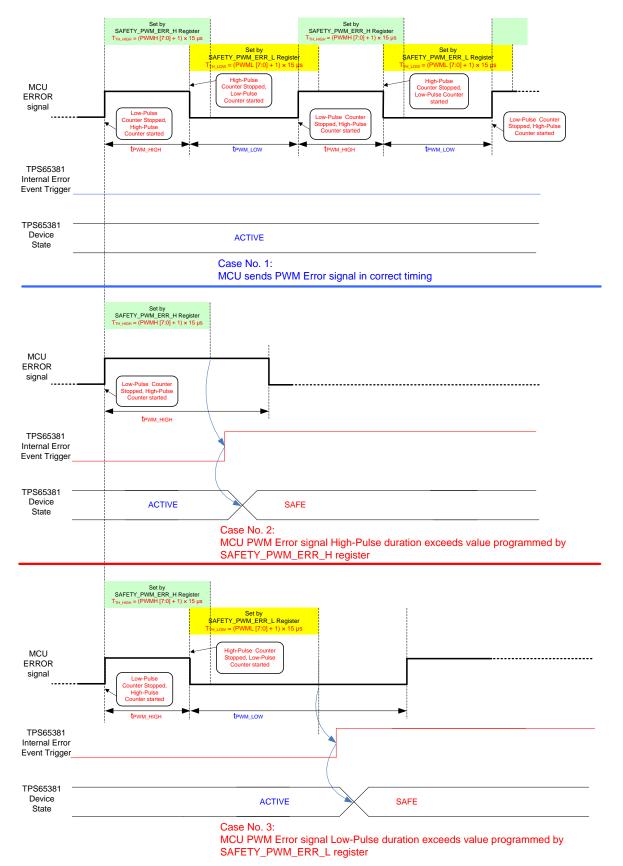


Figure 5-12. ERROR Pin Monitor – PWM Mode



# 5.4.1.18 Device Configuration Register Protection

This function offers a mechanism to protect safety SPI-mapped registers by means of SPI write-access protection and CRC check.

The register access protection includes two distinctive features:

- A register cannot be written after write-access lock protection is set. The lock is cleared by software or by a power-on reset.
- CRC protection for configuration registers

A CRC occurs on safety data after an SPI write updates to verify the SPI register contents are correctly programmed. The CRC controller is a diagnostic module which performs CRC to verify the integrity of the SPI-mapped register space. A signature representing the content of the safety registers is obtained when the content is read into the CRC controller. The responsibility of the CRC controller is to calculate the signature for a set of data and then compare the calculated signature value against a predetermined good-signature value. The predetermined CRC signature value is stored in the SAFETY\_CFG\_CRC register. The external MCU uses the SAFETY\_CHECK\_CTL register to enable a CRC check and the SAFETY\_STAT\_2 register to monitor the status. When enabled, a CRC check on the configuration registers is performed. In case of a detected signature error, a flag called CFG\_CRC\_ERR is set in SPI register in the SAFETY\_STAT\_2 register. The device state and the ENDRV pin state remain unchanged. In case of a detected checksum error with the TPS65381-Q1 device in DIAGNOSTIC state, clearing bit CFG\_CRC\_EN to 0 brings the TPS65381-Q1 device into SAFE state (the ENDRV pin is pulled low).

A standard CRC-8 polynomial is used: X8 + X2 + X1 + 1

The CRC monitor test is covered by a logic BIST.

A 64-bit string is protected by CRC. The following registers are protected:

- SAFETY\_FUNC\_CFG
- DEV\_REV
- SAFETY\_PWD\_THR\_CFG
- SAFETY\_ERR\_CFG
- WDT\_TOKEN\_FDBCK
- WDT\_WIN2\_CFG
- WDT\_WIN1\_CFG
- SAFETY\_ERR\_PWM\_L
- DEV\_CFG2
- DEV\_CFG1 (only bit number 6)

Table 5-13 lists the CRC bus structure.

REGISTER NAME	64-BIT BUS ORDERING	
SAFETY_FUNC_CFG [6:0]	[63:57]	
DEV_REV [7:0]	[56:49]	
SAFETY_PWD_THR_CFG [3:0]	[48:45]	
SAFETY_ERR_CFG [7:0]	[44:37]	
WDT_TOKEN_FDBCK [7:0]	[36:29]	
WDT_WIN2_CFG [4:0]	[28:24]	
WDT_WIN1_CFG [6:0]	[23:17]	
SAFETY_ERR_PWM_L [7:0]	[16:9]	
DEV_CFG2 [7:0]	[8:1]	
DEV_CFG1 [6]	0	

# Table 5-13. CRC Bus Structure

In the external MCU, the CRC calculation must be done byte-wise, starting with the lowest byte of the 64bit bus ordering value. The most significant bit is first in the bit order. The resulting CRC of one calculation is the seed value for the next calculation. The initial seed value is 0xFF. The CRC result of the 8th bytewise calculation is the CRC signature value, which must be stored in the SAFETY\_CFG\_CRC register (see Figure 5-13).

64-bit bus ordering value:

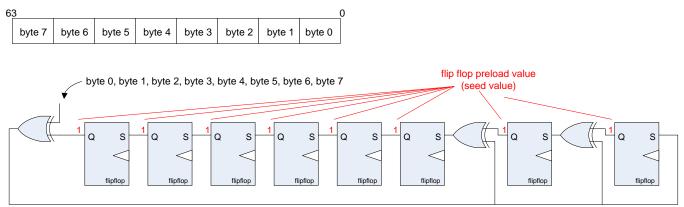


Figure 5-13. CRC Calculation Logic

Table 5-14 lists some CRC calculation examples.

	•
64-BIT BUS ORDERING VALUE	CRC-8 RESULT
0x0000 0000 0000 0000	0xDB
	000

Table 5-14. CRC Calculation Examples	

64-BIT BUS ORDERING VALUE	CRC-0 RESULT
0x0000 0000 0000 0000	0xDB
0xFFFF FFFF FFFF FFFF	0x0C
0x0A0A 0505 0A0A 0505	0xD4
0x0505 0A0A 0505 0A0A	0x17
0xA0A0 5050 A0A0 5050	0x2B
0x0A23 E000 18FE 7B80	0x1B
	•

In case the CRC controller detects a signature error on the configuration registers, care must be taken when performing an EEPROM CRC check afterwards. In case of a detected signature error in the configuration registers, the device reports an EEPROM signature error when the CFG\_CRC\_EN bit in the SAFETY\_CHECK\_CTL register is set to 0 first before performing the EEPROM CRC check by setting the EE\_CRC\_CHK bit in the SAFETY\_BIST\_CTRL register to 1, even when the EEPROM bits do not have an error. Therefore, when performing an EEPROM CRC check after a CRC check on the configuration registers, the steps must always occur in the following order:

- 1. Calculate CRC8 in the MCU and store in the SAFETY\_CFG\_CRC register.
- 2. Set the CFG\_CRC\_EN bit in the SAFETY\_CHECK\_CTL register to 1 to perform a CRC Check on configuration registers.
- 3. After the SPI command sets the CFG\_CRC\_EN bit to 1 (for example: after rising edge on NCS), wait at least 2.1 µs for the configuration register to complete the CRC check.
- 4. Read the results of configuration register CRC check in the SAFETY\_STAT\_2 register, bit CFG\_CRC\_ERR. If continuous CRC check on the configuration register must be performed, clear the CFG\_CRC\_EN bit in the SAFETY\_CHECK\_CTL register to 0 and repeat beginning with Step 1. If the CRC check on EEPROM registers must be performed, proceed to Step 5.

#### NOTE

A correct EEPROM CRC check afterwards (as described in Step 5) clears this CFG\_CRC\_ERR bit. Therefore, TI recommends to read out this CFG\_CRC\_ERR bit before performing the EEPROM CRC check.

- 5. Set the EE\_CRC\_CHK bit in the SAFETY\_BIST\_CTRL register to 1 to perform the CRC Check on EEPROM registers.
- 6. After the SPI command sets the EE\_CRC\_CHK bit to 1 (for example: after rising edge on NCS), wait at least 811 μs for the EEPROM CRC check to finish.
- 7. Completion of the EERPOM CRC check is observed by reading the EE\_CRC\_CHK bit. When EEPROM CRC is complete, this EE\_CRC\_CHK bit is cleared to 0.
- 8. Clear the CFG\_CRC\_EN bit in the SAFETY\_CHECK\_CTL register to 0
- 9. Read the results of the EEPROM CRC check in the SAFETY\_STAT\_2 register, bit EE\_CRC\_ERR.
- 10. Go back to Step 1.

# NOTE

Returning to Step 1 is not required; returning to Step 2 is also an option.

# 5.4.1.19 Enable and Reset Driver Circuit

Figure 5-14 shows the Enable and reset circuit.

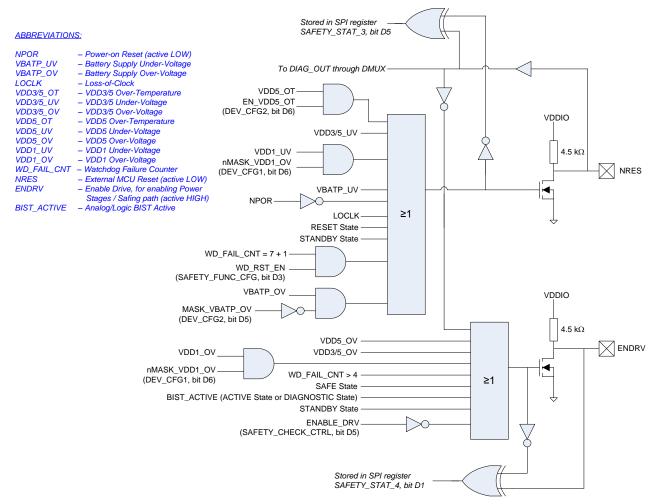


Figure 5-14. Reset and Enable Circuit

The ENDRV pin features a read-back circuit to compare the external ENDRV level with the internally applied ENDRV level. This feature detects any possible failure in the ENDRV pullup or pulldown components. A failure is detected by the MCU through the SPI register SAFETY\_STAT\_4, bit 1.

The ENDRV pin is pulled low for the ABIST duration time (approximately 300 µs) when activating the ABIST function after the ENDRV output is turned on and driven high. This is part of ENDRV diagnostics to validate all monitoring functions that disable ENDDRV output and confirm ENDRV output is controllable by utilizing ENDRV read-back path.

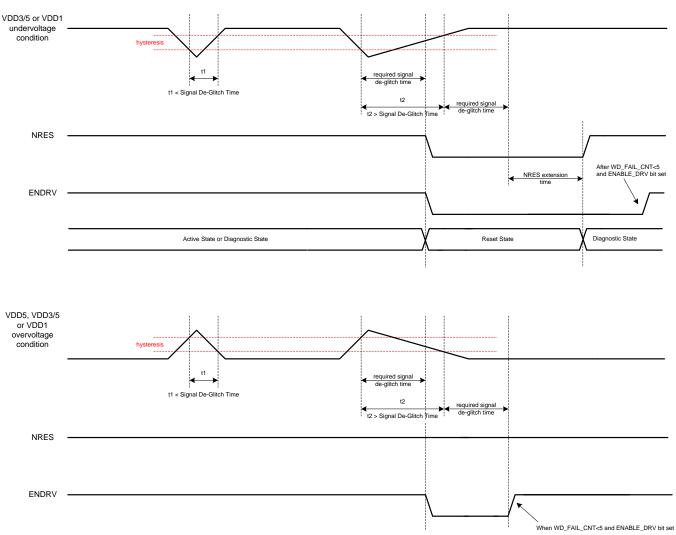
The NRES pin features a readback of the external NRES level. The value is read on the DIAG\_OUT pin and in the SPI register SAFETY\_STAT\_3, bit 5.

For both the ENDRV therminal and the NRES pin, the logic readback-threshold level is typically 400 mV.

Figure 5-15 shows the timing-response diagram for the NRES and ENDRV pins to any VDDx undervoltage or overvoltage condition.



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(1) The signal deglitch time is defined for each undervoltage or overvoltage condition as given in Section 4.

(2) The NRES extension time is defined by the external resistor value as given in Section 4.

#### Figure 5-15. Timing-Response Diagram for NRES and ENDRV Pins to any VDDx Undervoltage or Overvoltage Condition



# 5.4.1.20 Device Controller State Diagram

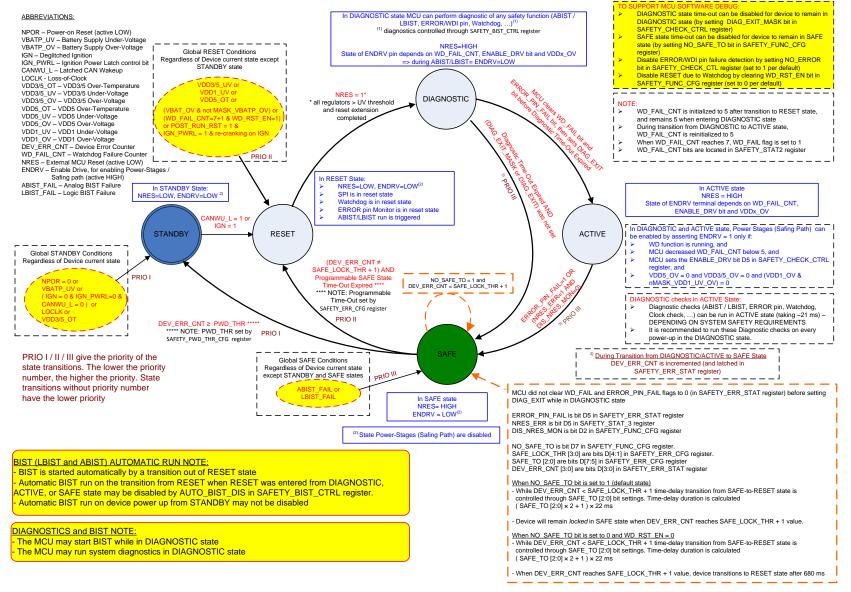


Figure 5-16. Device Controller State Diagram

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### 5.4.1.21 STANDBY State

STRUMENTS

- This state is the default state at power up.
- All regulators are disabled, ENDRV is disabled, and NRES to the external MCU is driven low.
- The device transitions to the STANDBY state from any state because of the following:
  - VBATP undervoltage event
  - Deglitched IGN = 0 and IGN\_PWRL = 0 (cleared IGN power-latch control bit) and CANWU\_L = 0
  - VDD3/5 overtemperature event
  - Loss-of-clock detection
  - The error count reached the programmed power-down threshold
  - Internal NPOR (power-on reset)

### 5.4.1.22 RESET State

- Enters from the STANDBY state after an IGN or CANWU event
  - In this case, the VDDx regulators are ramping up.
- Enters from the SAFE state after a reset delay time-out expires when the device error count is below the programmed SAFE\_LOCK\_THR + 1
- The device transitions to the RESET state from any other state because of the following:
  - VDD3/5 undervoltage event
  - VDD1 undervoltage event
  - VBATP overvoltage event
  - Watchdog reset. A watchdog reset occurs after the watchdog fail counter has reached a value of 7 and another bad event occurs (7+1)
  - (which sets the WD\_FAIL flag) when WD\_RST\_EN = 1
  - VDD5 overtemperature event

In all transitions to RESET state (except when coming from STANDBY state), the VDDx regulator stays on, but the VSOUT1 regulator is disabled. The NRES and ENDRV pins are low in RESET state.

## 5.4.1.23 DIAGNOSTIC State

- Enters from the RESET state after all regulators are ramped-up and the MCU reset (NRES pin) extension is completed and the NRES pin is pulled up
- VSOUT1 regulator is disabled per default, can be enabled and disabled through SPI
- Watchdog and ERROR/WDI pin monitoring functions can be configured and operated. Emulated MCU\_ERROR on the ERROR/WDI pin does not cause a transition to the SAFE state
- Upon entry of DIAGNOSTIC state, watchdog failure counter is initialized to 5.
- State of the ENDRV pin is determined by the watchdog fail count value, VDDx\_OV, and the ENABLE\_DRV bit
- This state performs all device self-tests and diagnostics by the MCU (failures are induced to emulate internal failures and confirm detection).

### NOTE

DIAGNOSTIC State TIME-OUT: When DIAGNOSTIC state is entered, if the DIAG\_EXIT\_MASK or DIAG\_EXIT bit is not set to 1 within 512 ms (typical), the DIAGNOSTIC state time-out interval expires, causing a transition to SAFE state. This will also set both the ERROR\_PIN\_FAIL and WD\_FAIL bits in the SAFETY\_ERR\_STAT register, and the device error count (DEV\_ERR\_CNT[3:0]) is incremented. Only the DIAG\_EXIT\_MASK or DIAG\_EXIT should be set in a single SPI write command to the SAFETY\_CHECK\_CTRL. Setting the DIAG\_EXIT bit to 1 causes a transition to the ACTIVE state. Setting the DIAG\_EXIT\_MASK bit to 1 causes the device to remain in DIAGNOSTIC (only recommended for software debug).

### NOTE

DIAG\_EXIT\_MASK for software debug: When the DIAG\_EXIT\_MASK bit is set to 1 before the DIAGNOSTIC state time-out interval expires, the device stays in the DIAGNOSTIC state until the bit is cleared. The DIAGNOSTIC state time-out timer remains free running in the background, but will not cause a state transition. Once the DIAGNOSTIC state time-out interval has expired, the DIAG\_EXIT bit will be set automatically (in addition to the DIAG\_EXIT\_MASK bit remaining set) and the device will remain in DIAGNOSTIC state. For a controlled transition to ACITVE state, it is recommended to clear the DIAG\_EXIT\_MASK bit and set the DIAG\_EXIT\_MASK bit and DIAG\_EXIT bits are cleared at the same time, the device will remain in DIAGNOSTIC state time-out interval expires causing a transition to SAFE state or the DIAG\_EXIT bit is set, prior to the DIAGNOSTIC state time-out interval expires.

### 5.4.1.24 ACTIVE State

• Enters from the DIAGNOSTIC state after the MCU sets the DIAG\_EXIT bit in the SAFETY\_CHECK\_CTRL register

### NOTE

While in DIAGNOSTIC state, the MCU must clear the ERROR\_PIN\_FAIL bit and the WD\_FAIL bit in the SAFETY\_ERR\_STAT register before setting the DIAG\_EXIT bit. Otherwise, a transition to SAFE state occurs.

- Watchdog and ERROR/WDI pin monitoring functions are operated as configured but cannot be reconfigured.
- Upon entry to the ACTIVE state, the watchdog failure counter reinitializes to 5.
- The VDDx regulators are up and running, and the VSOUT1 regulator maintains the same state as configured in DIAGNOSTIC state
- The NRES pin is pulled up, and the state of the ENDRV pin is determined by the watchdog fail count value, VDDx\_OV, and ENABLE\_DRV bit.

### 5.4.1.25 SAFE State

- Enters from the ACTIVE state after an ERROR/WDI pin.
- Enters from the ACTIVE state after detected read-back error on NRES pin (bit NRES\_ERR in SAFETY\_STAT\_3 register) when bit DIS\_NRES\_MON = 0 (1 in default state) in SAFETY\_FUNC\_CFG register.
- Enters from the DIAGNOSTIC state after the DIAGNOSTIC state time-out event happens when the DIAG\_EXIT\_MASK is not set to 1.
  - Uncontrolled transition in case of error in MCU which sets the ERROR\_PIN\_FAIL and WD\_FAIL status bits in the SAFETY\_ERR\_STAT register and causes transition to the SAFE state and Device Error Count is incremented.
- Enters from RESET, DIAGNOSTIC, or ACTIVE state after ABIST or LBIST failure.
- Every transition to the SAFE state increments the error count.
- Stays in SAFE state when NO\_SAFE\_TO = 1 (default state) and DEV\_ERR\_CNT = SAFE\_LOCK\_THR + 1 which allows programming the MCU without triggering a reset.
- NRES is pulled high, but the ENDRV pin is kept low regardless of the watchdog fail count value, VDDx\_OV and ENABLE\_DRV bit.
- VDDx regulators are up and running, and the VSOUT1 regulator maintains the same state as configured in ACTIVE state.

### 5.4.1.26 State Transition Priorities

For all global or possible double-state transitions, the following priorities hold true:

- 1. All conditions for STANDBY state transition
- 2. All conditions for RESET state transition
- 3. All conditions for SAFE state transition

All other state transitions have a lower priority compared to any of the state transitions previously listed.

#### 5.5 **Register Maps**

### 5.5.1 SPI

The primary communication between the IC and the external the MCU is through an SPI bus which provides full-duplex communications in a master-slave configuration. The external MCU is always an SPI master which sends command requests on the SDI pin, and receives device responses on the SDO pin. The TPS65381-Q1 device is always an SPI slave device which receives command requests and sends responses (status, measured values) to the external MCU over the SDO line.

- SPI is a 4-pin interface.
  - NCS—SPI chip select (active-low)
  - SCLK—SPI clock
  - SDI—SPI slave-in / master-out (SIMO)
  - SDO—SPI slave-out / master-in (SOMI, three-state output)
- Frame size is 16 bits.
- Speed is up to 6 Mbit/s.
- Commands and data are shifted MSB first, LSB last.
- The SDI line is sampled on the falling edge of SCLK. ٠
- The SDO line is shifted out on the rising edge of SCLK.

The SPI communication starts with the NCS falling edge, and ends with NCS rising edge. The NCS high level keeps the SPI slave interface in the reset state, and the SDO output is tri-stated.

### 5.5.1.1 SPI Command Transfer Phase

Table 5-15 lists the SPI command-transfer frame during a command or read access.

			able 5-15.	SPI Comma	ind Transfer	Phase		
BIT	D7	D6	D5	D4	D3	D2	D1	D0
FUNCTION	CMD6	CMD5	CMD4	CMD3	CMD2	CMD1	CMD0	PARITY
CMDIG:01	Degister W/D	r DD commond						

## Table 5.45, SDI Command Transfer Dhee

CMD[6:0] Register WR or RD command PARITY Parity bit for 7-bit command filed

> The SPI Interface does not support back-to-back SPI frame operation. After each SPI command or read access, the NCS pin must go from low to high before the next SPI transfer can start. The minimum time (t<sub>hics</sub>) between two SPI commands during which the NCS pin must remain high is 788 ns.

### 5.5.1.2 SPI Data-Transfer Phase

Table 5-16 lists the SPI data-transfer frame format during a write access:

#### Table 5-16. SPI Data-Transfer Phase

BIT	D7	D6	D5	D4	D3	D2	D1	D0	
FUNCTION	DATA7	DATA6	DATA5	DATA4	DATA3	DATA2	DATA1	DATA0	
DATA[7:0] Data value for write access (8 hit)									

DATA[7:0] Data value for write access (8-bit)

The SPI interface does not support back-to-back SPI frame operation. After each SPI transfer, the NCS pin must go from low to high before the next SPI transfer can start. The minimum time ( $t_{hlcs}$ ) between two SPI commands during which the NCS pin must remain high is 788 ns.

#### 5.5.1.3 Device Status Flag Byte Response

Table 5-17 lists the SPI data status response frame format during a command, read access, or write access:

		Та	able 5-17. De	evice Status	s Flag Byte F	Response		
BIT	R7	R6	R5	R4	R3	R2	R1	R0
FUNCTION	STAT[7]	STAT[6]	STAT[5]	STAT[4]	STAT[3]	STAT[2]	STAT[1]	STAT[0]
<ul> <li>STAT[7]</li> </ul>	: 1							
<ul> <li>STAT[6]</li> </ul>	: 0							
<ul> <li>STAT[5]</li> </ul>	: 1							
<ul> <li>STAT[4]</li> </ul>	: 0							
<ul> <li>STAT[3]</li> </ul>	: SPI WR acce	ss (during previ	ous SPI frame-o	command phase	e)			
074701								

- STAT[2]: SPI SDO error (during previous SPI frame)
- STAT[1]: 0
- STAT[0]: Invalid SPI transfer

The status bits sent during the current SPI command are reflecting the status of the previous SPI command.

#### NOTE

If a reset to the MCU is asserted during a SPI frame transfer (causing a truncated SPI frame), these SPI Error Status bits are not cleared, but maintain the status according to the truncated previous SPI frame until SPI Read access.

#### NOTE

The SPI SDO error bit, STAT[2], may be inadvertantly set when nCS is HIGH, SDO is HIGH and there is a falling edge on SPICLK. This combination occurs most often when the device is used in a SPI bus with multiple SPI slaves. If all three of these conditions are met, the SDO error flag will be set, 1, in the second SPI Flag Byte Response of the following SPI communication with the TPS65381. The application software should mask out the SDO error flag if the device is used under these conditions.

#### 5.5.1.4 Device SPI Data Response

Table 5-18 lists the device SPI data-response frame format during a read access:

			Table 5-1	8. Device SF	PI Data Resp	oonse		
BIT	R7	R6	R5	R4	R3	R2	R1	
FUNCTION	R7	R6	R5	R4	R3	R2	R1	

• R[7:0] Internal register value. All unused bits are set to zero.

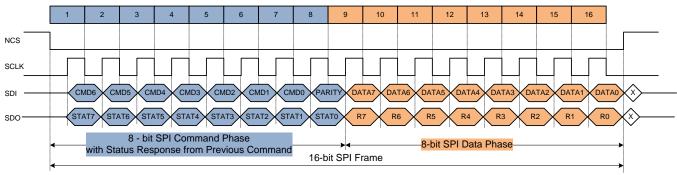
R0

R0



### 5.5.1.5 SPI Frame Overview

Figure 5-17 shows an overview of a complete 16-bit SPI Frame:



SPI Master (MCU) and SPI Slave (TPS65381) sample received data on the falling SCLK edge and transmit on the rising SCLK edge.

Figure 5-17. 16-Bit SPI Frame

### 5.5.2 Device SPI Mapped Response

The following tables list the available SPI registers. For each SPI register, the bit names are given along with the default values (values after internal logic reset). These default values apply after each wake-up from IGN or CANWU. The reserved bits (RSV) default is indicated however some of these bits are used for internal device operation and the application software should mask them as they may not remain at their default value. The following tables also list an explanation of each bit function.

### 5.5.2.1 Device Revision and ID

### 5.5.2.1.1 DEV\_REV Register

### Read command: **RD\_DEV\_REV**

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
REV[7]	REV[6]	REV[5]	REV[4]	REV[3]	REV[2]	REV[1]	REV[0]				
0	0	1	1	0	0	0	0				

D[7:0] REV[7:0]: Device Revision

- REV[3:0]: Device minor revision

- REV[7:4]: Device major revision

### 5.5.2.1.2 DEV\_ID Register

### Read command: RD\_DEV\_ID

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
ID[7]	ID[6]	ID[5]	ID[4]	ID[3]	ID[2]	ID[1]	ID[0]				
0	0	0	0	0	0	0	1				

### 5.5.2.2 Device Status

### 5.5.2.2.1 DEV\_STAT Register

### Read command: RD\_DEV\_STAT

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
RSV	RSV	RSV	RSV	RSV	RSV	CANWU_L	IGN				
0	0	0	0	0	0	Х	Х				

D[7:2] RSV

D[1] CANWU\_L: Latched CAN wake-up event

 The reset value depends on whether a device wake-up event occurred through the CANWU or IGN pin. When a device wake-up occurred through a CANWU, only WR\_CAN\_STBY command, or any other global Standby condition, this bit can clear to 0

#### D[0] IGN: Deglitched IGN pin (7.5-ms to 22-ms deglitch time)

 The reset value depends on whether a device wake-up event occurred through the CANWU or IGN pin. This bit follows the deglitched IGN signal, and therefore is only cleared to 0 when the deglitched IGN is low or by any other global STANDBY condition www.ti.com

### 5.5.2.3 Device Configuration

### 5.5.2.3.1 DEV\_CFG1 Register

#### Read command: RD\_DEV\_CFG1

#### Write command: WR\_DEV\_CFG1

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
VDD_3_5_SEL	nMASK_VDD1_UV_ OV	RSV	RSV	RSV	RSV	RSV	RSV				
Х	0	0	0	0	0	0	0				

D[7] VDD\_3\_5\_SEL: Status bit of VDD3/VDD5 selection at power up

SEL\_VDD3/5 input pin is sampled and latched at power up

- 0: 5-V setting (pin SEL\_VDD3/5 to ground)
- 1: 3.3-V setting (pin SEL\_VDD3/5 not connected)
- Value in RESET state depends on state of SEL\_VDD3/5 pin at first power up
- This bit is READ-ONLY
  - (NOTE: Same as SAFETY\_FUNC\_CFG bit D0)

#### D[6] nMASK\_VDD1\_UV\_OV

- Set to 0 per default:
  - Masked VDD1\_OV does not impact ENDRV pin state
  - Masked VDD1\_UV does not impact NRES state
- The default setting (0, masked) can be used in case VDD1 is not used in an application and external power FET is not populated.

**Note**: If VDD1 is used in an application, TI recommends to set this bit to 1 when the device is in the DIAGNOSTIC state after the first start-up or power-up event.

**Note**: Even if this bit is set to 1, but the VDD1\_SENSE pin is externally floating, the pin will be pulled up. The pull up condition will be detected but the VDD1\_OV condition will be masked and ENDRV pin state will not be impacted.

D[5:0] RSV

### 5.5.2.3.2 DEV\_CFG2 Register

#### Read command: **RD\_DEV\_CFG2**

#### Write command: WR\_DEV\_CFG2

		DATA	INFORMATIO	N						
D7	D7 D6 D5 D4 D3 D2 D1 D0									
EN_VDD3/5_OT	EN_VDD5_OT	MASK_VBATP_OV	POST_RUN _RST	RSV	RSV	RSV	RSV			
1	1	0	0	0	0	0	0			

#### D[7] EN\_VDD3/5\_OT

- Set to 1 by default.

- When set to 0 and an overtemperature event is detected, VDD3/5 supply is disabled
- When set to 1 and an overtemperature event is detected the device enters STAND-BY state.

#### D[6] EN\_VDD5\_OT

 Set to 1 by default. Clearing this bit to 0 disables the VDD5 overtemperature shutdown. The VDD5\_OT flag is still present in SAFETY\_STAT\_REG1 bit D1.

#### D[5] MASK\_VBATP\_OV

- Set to 0 by default. When set 1, VBATP\_OV is masked from the RESET condition.

- D[4] POST\_RUN\_RST: Set to 0 per default. If this bit is set to 1 when using the IGN\_PWRL function, a re-cracking on the IGN pin causes the device to go to the RESET state.
- D[3:0] RSV (bits are readable and writable in DIAGNOSTIC state with no impact to device state, ENDRV and NRES output)

### 5.5.3 Device Safety Status and Control Registers

### 5.5.3.1 VMON\_STAT\_1 Register

### Read command: RD\_VMON\_STAT\_1

				DATA INI	ORMATION			
	D7	D6	D5	D4	D3	D2	D1	D0
VBA	TP_OV	VBATP_UV	VCP17_OV	VCP12_OV	VCP12_UV	AVDD_VMON_ERR	BG_ERR2	BG_ERR1
	0	0	0	0	0	0	0	0
D[7]	VBATP	OV: VBATP ove	ervoltage status bit					
	– Set	t to 1 when VBAT	P overvoltage is d	etected				
	– Cle	ared to 0 if an ov	ervoltage conditior	n is no longer pre	sent			
D[6]	VBATP	<b>_UV</b> : VBATP und	lervoltage status b	it				
	– Set	t to 1 when VBAT	P undervoltage is	detected				
	– Cle	ared to 0 if an un	dervoltage condition	on is no longer pr	resent			
D[5]	VCP17	_OV: VCP17 ove	rvoltage status bit					
	– Set	t to 1 when VCP1	7 overvoltage is de	etected				
	– Cle	ared to 0 if an ov	ervoltage conditior	n is no longer pre	sent			
D[4]	VCP12	_OV: VCP12 ove	rvoltage status bit					
	– Set	t to 1 when VCP1	2 overvoltage is de	etected				
	– Cle	ared to 0 if an ov	ervoltage conditior	n is no longer pre	sent			
D[3]	VCP12	_UV: VCP12 und	ervoltage status bi	t				
	– Set	t to 1 when VCP1	2 undervoltage is	detected				
	– Cle	ared to 0 if an un	dervoltage condition	on is no longer pr	resent			
D[2]			tage-monitor powe	11 7 1 0	ood status			
	– Set	t to 1 when voltag	e-monitor power s	upply is not OK.				
			ror condition is no	longer present				
D[1]	_	R2: Reference ba	01					
	– Set	t to 1 when the vo	ltage monitor is le	ss than the main	band gap			
			ror condition is no	longer present				
D[0]	BG_ER	R1: Reference ba	andgap 1 error					

- Set to 1 when the voltage monitor is greater than the main band gap

- Cleared to 0 if an error condition is no longer present



### 5.5.3.2 VMON\_STAT\_2 Register

### Read command: **RD\_VMON\_STAT\_2**

				DATA INF	ORMATION			
	D7	D6	D5	D4	D3	D2	D1	D0
VDI	D6_OV	VDD6_UV	VDD5_OV	VDD5_UV	VDD3/5_OV	VDD3/5_UV	VDD1_OV	VDD1_UV
	0	0	0	0	0	0	0	0
D[7]	VDD6_C	DV: VDD6 overvoli	tage status bit					
	<ul> <li>Set</li> </ul>	to 1 when VDD6 of	overvoltage is dete	ected				
	– Clea	ared to 0 if an ove	rvoltage condition	is no longer pres	ent			
D[6]	VDD6_L	JV: VDD6 undervo	oltage status bit					
	– Set	to 1 when VDD6 u	undervoltage is de	tected				
			ervoltage conditio	n is no longer pre	sent			
D[5]	_	<b>DV</b> : VDD5 overvol	0					
			overvoltage is dete					
			rvoltage condition	is no longer pres	ent			
D[4]	_	JV: VDD5 undervo	0					
			undervoltage is de					
			ervoltage conditio	n is no longer pre	sent			
D[3]		_	rvoltage status bit					
			5 overvoltage is de					
<b>B</b> 741			rvoltage condition	0 1	ent			
D[2]		_	ervoltage status b					
			5 undervoltage is o					
D[4]			ervoltage condition	h is no longer pre	sent			
D[1]	_	<b>DV</b> : VDD1 overvolt	0	atad				
			overvoltage is dete		opt			
נסוס		JV: VDD1 undervo	rvoltage condition	is no longer pres	ent			
D[0]	_		undervoltage is de	toctod				
	- Set		undervoltage is de	lecleu				

- Cleared to 0 if an undervoltage condition is no longer present

### 5.5.3.3 SAFETY\_STAT\_1 Register

### Read command: **RD\_SAFETY\_STAT\_1**

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
VDD5_ILIM	VDD3_5_ILIM	VSOUT1_UV	VSOUT1_OV	RSV	VSOUT1_OT	VDD5_OT	VDD_3_5_OT				
0	0	0	0	0	0	0	0				

D[7] VDD5\_ILIM: VDD5 current-limit status bit

- Set to 1 when a VDD5 current-limit is exceeded

- Cleared to 0 if a current-limit condition is no longer present

Note: This status bit is valid only when VDD5\_EN bit in SENS\_CTRL register is set to 1.

- D[6] VDD3\_5\_ILIM: VDD3 current-limit status bit
  - Set to 1 when a VDD3 current-limit is exceeded
  - Cleared to 0 if a current-limit condition is no longer present

D[5] VSOUT1\_UV: Sensor-supply undervoltage status bit

- Set to 1 when a VSOUT1 undervoltage is detected
- Cleared to 0 if an undervoltage condition is no longer present

D[4] VSOUT1\_OV: Sensor-supply overvoltage status bit

- Set to 1 when a VSOUT1 overvoltage is detected
- Cleared to 0 if an overvoltage condition is no longer present
- D[3] RSV
  - Was VSOUT1\_ILIM bit: VSOUT1 sensor-supply current-limit status bit
  - Use diagnostic output pin, DIAG\_OUT, with the Digital MUX setting for VSOUT1\_CL to monitor current limit status for VSOUT1
- D[2] VSOUT1\_OT: Sensor-supply overtemperature status bit
  - Set to 1 when VSOUT1 overtemperature is exceeded. This bit keeps VSOUT1 regulator disabled as long as this bit is set.
  - Cleared to 0 if an overtemperature condition is no longer present
- **D[1] VDD5\_OT**: VDD5 overtemperature status bit
  - Set to 1 when VDD5 overtemperature is exceeded. This bit keeps VDD5 regulator disabled as long as this bit is set by clearing the VDD5\_EN control bit in SENS\_CTRL register
  - Cleared to 0 if an overtemperature condition is no longer present
- D[0] VDD\_3\_5\_OT: VDD3/5 overtemperature status bit
  - Set to 1 when VDD3/5 overtemperature is exceeded. This bit keeps VDD3/5 regulator disabled as long as this bit is set to 1.
  - Cleared to 0 if an overtemperature condition is no longer present



### 5.5.3.4 SAFETY\_STAT\_2 Register

#### Read command: **RD\_SAFETY\_STAT\_2**

	DATA INFORMATION											
D7	D6	D5	D4	D3	D2	D1	D0					
RSV	RSV	CFG_CRC_ER R	EE_CRC_ERR	RSV	WDT_FAIL_CNT[2]	WDT_FAIL_CNT[1]	WDT_FAIL_CNT[0]					
0	0	0	0	0	1	0	1					

D[7:6] RSV

**D[5] CFG\_CRC\_ERR**: CRC Error status bit for safety configuration registers

- Safety configuration registers are protected by CRC8.
- This bit is set to 1 when the calculated CRC8 value for safety configuration registers does not match the expected CRC8 value stored in the SAFETY\_CFG register.
- Cleared to 0 when a CRC8 mismatch is no longer present.
- Cleared to 0 when EEPROM CRC performs without error (regardless of CFG\_CRC check result)

#### **D[4] EE\_CRC\_ERR**: EPROM CRC error status bit

- EEPROM content is protected by CRC8.
  - This bit is set to 1 when the calculated CRC8 value does not match the expected CRC8 value stored in the EEPROM DFT register. When this bit is set to 1 and device is in the DIAGNOSTIC state, the device transitions to SAFE state.
  - Cleared to 0 when a CRC8 mismatch is no longer present.

#### D[3] RSV

- **D[2:0]** WDT\_FAIL\_CNT[2:0]: Watchdog failure counter state
  - The default value is 5, and is initialized to this value upon entering DIAGNOSTIC and ACTIVE state
  - Watchdog failure counter is incremented every time the device watchdog-response failure is detected and decreases each time the correct response is received.
  - Watchdog failure counter must decrease below 5 to enable the ENABLE\_DRV output pin.
  - Watchdog failure is detected on the next bad event after the watchdog failure counter reached the count of 7 (that is 7+1) and the WD\_FAIL status bit is set to 1 in the SAFETY\_ERR\_STAT register (setting the WD\_FAIL bit to 1 in the SAFETY\_ERR\_STAT register).

### 5.5.3.5 SAFETY\_STAT\_3 Register

### Read command: **RD\_SAFETY\_STAT\_3**

	DATA INFORMATION											
D	7	D6	D5	D4	D3	D2	D1	D0				
RS	SV	RSV	NRES_ERR	LBIST_ERR	ABIST_UVOV_ERR	ABIST_RUN						
(	)	0	0	0	0	R         ABIST_UVOV_ERR         LBIST_RUN         ABIS           0						
D[7:6]	6] RSV											
D[5]	NRES	_ERR: Reset e	rror input status									
••	– T	– nis bit is set to 1	∣when a misma	tch between NF	RES output and NRES in	put feedback is detected	d.					
					s present anymore.							
D[4]		ERR: Logic Bl										
-1.1		his bit is set to 1										
			0		l without failure, followed	hy SPI read access						
		nly valid when t	•	•		by of fredd access						
נכום		•	_		overvoltage BIST error-	atatua hit						
D[3]			0	0	0							
		ate, device tran			d overvoltage BIST fails.	If this bit is set to 1 and	device is in DA	IGNOSTIC				
	- C	leared to 0 after	SPI read acces	s								
	- O	nly valid when t	he ABIST_RUN	bit is 0								
D[2]	ABIS	LUVOV_ERR:	Analog BIST un	dervoltage and	overvoltage BIST error-	status bit (identical to D3	3)					
		his bit is set to 1 ate, device tran			d overvoltage BIST fails.	If this bit is set to 1 and	device is in DA	IGNOSTIC				
	- C	leared to 0 after	· SPI read acces	SS								
	- 0	nly valid when t	he ABIST_RUN	bit is 0								
D[1]	LBIST	_RUN: Logic B	IST run-status b	it								
	т	 sia hit ia aat ta 1	when a logic D									

- This bit is set to 1 when a logic BIST is running.
- Cleared to 0 after a logic BIST is finished running.
- D[0] ABIST\_RUN: Analog BIST run-status bit
  - This bit is set to 1 when an analog BIST is running.
  - Cleared to 0 after a analog BIST is finished running.



### 5.5.3.6 SAFETY\_STAT\_4 Register

#### Read command: **RD\_SAFETY\_STAT\_4**

	DATA INFORMATION									
D7	D6	D5	D4	D3	D2	D1	D0			
SPI_ERR[1]	SPI_ERR[0]	LOCLK	RSV	MCU_ERR	WD_ERR	ENDRV_ERR	TRIM_ERR_V MON			
0	0	0	0	0	0	0	0			

D[7:6] SPI\_ERR[1:0]: SPI error-status bits

- 00: No error
- 01: Command error
- 10: Format error (received bit count is not equal to 16)
- 11: Data output mismatch
- Cleared to 0 after SPI read access.

**Note**: If a reset to the MCU is asserted during an SPI frame transfer (causing a truncated SPI frame), these SPI error status bits are not cleared, but maintain the status according to the truncated previous SPI frame until SPI read access

- D[5] LOCLK: Loss of clock-detection status bit
  - Set when loss-of-clock failure is detected
  - Cleared to 0 after internal NPOR and if clock failure is no longer present.

#### D[4] RSV

- D[3] MCU\_ERR: MCU error monitor status bit
  - This bit is set to 1 when MCU error-signal monitoring module detects MCU\_ERROR pin failure on ERROR/WDI pin.
  - Cleared to 0 after SPI read access and if bit ERROR\_PIN\_FAIL in SAFETY\_ERR\_STAT is cleared
- D[2] WD\_ERR: Watchdog error-status bit
  - This bit is set to 1 when on the next bad event
    - once the watchdog fail counter reaches a count of 7 (that is 7+1) (WDT\_FAIL\_CNT [2:0] in SAFETY\_STATUS\_2 register) only if bit WD\_RST\_EN (SAFETY\_FUNC\_CFG, bit 3) is set to 1
  - Cleared to 0 after SPI read access when watchdog fail counter is less than 7

#### D[1] ENDRV\_ERR: Enable driver error

- This bit is set to 1 when a mismatch between the EN\_DRV output and EN\_DRV input feedback is detected.
- Cleared to 0 if failure is no longer present
- D[0] TRIM\_ERR\_VMON: VMON trimming error-status bit
  - This bit is set to 1 when mismatch voltage-monitor trim error is detected.
  - Cleared to 0 after internal NPOR and if failure is not present anymore.

### 5.5.3.7 SAFETY\_STAT\_5 Register

### Read command: RD\_SAFETY\_STAT\_5

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
RSV	RSV RSV RSV RSV RSV FSM[2] FSM[1] FSM[0]										
0	0 0 0 0 0 0 0 1 1										

**D[2:0] FSM[2:0]**: Current device state

- STANDBY state: 8'h00
- RESET state: 8'h03
- DIAGNOSTIC state: 8'h07
- ACTIVE state: 8'h05
- SAFE state: 8'h04

<sup>-</sup>Reflects current device state

Write command: WR\_SAFETY\_ERR\_CFG

### 5.5.3.8 SAFETY\_ERR\_CFG Register

### Read command: RD\_SAFETY\_ERR\_CFG

	DATA INFORMATION											
D7	D6	D5	D4	D3	D2	D1	D0					
SAFE_TO [2]	SAFE_TO [1]	SAFE_TO [0]	SAFE_LOCK_THR [3]	SAFE_LOCK_THR [2]	SAFE_LOCK_THR [1]	SAFE_LOCK_THR [0]	CFG_LOCK					
0	0	0	0	0	0	0	0					

#### D[7:5] SAFE\_TO[2:0]: SAFE state time-out settings

- Duration of SAFE state is time-limited to protect against potential MCU *locked* state.

- Time-out duration = (2 × SAFE\_TO[2:0] + 1) × 22 ms

Minimum duration is 22 ms

- Maximum duration is 330 ms

- 22-ms time reference has 5% accuracy coming from 4-MHz internal oscillator)

#### D[4:1] SAFE\_LOCK\_THR[3:0]

- Sets the corresponding device ERR\_CNT threshold at which device remains in SAFE state regardless of time-out event

- When NO\_SAFE\_TO bit (SAFETY\_FUNC\_CFG register, bit 7) is set to 1:

- While ERR\_CNT < SAFE\_LOCK\_THR + 1, time-delay transition from SAFE-to-RESET state is controlled through SAFE\_TO[2:0] bit settings. Time-delay duration is calculated (SAFE\_TO[2:0] × 2 + 1) × 22 ms
- Device remains locked in SAFE state when ERR\_CNT reaches SAFE\_LOCK\_THR + 1 value.
- When NO\_SAFE\_TO bit (SAFETY\_FUNC\_CFG register, bit 7) is set to 0:
  - While ERR\_CNT < SAFE\_LOCK\_THR + 1, time-delay transition from SAFE-to-RESET state is controlled through SAFE\_TO[2:0] bit settings. Time-delay duration is calculated (SAFE\_TO[2:0] × 2 + 1) × 22 ms
  - When ERR\_CNT reaches SAFE\_LOCK\_THR + 1 value, device transitions to RESET state after 680 ms.

- Intended to support software debug and development and is NOT recommended for normal functional operation.

- The 0000 setting is the default setting, and has same effect as the 1111 setting. Both settings give the minimum threshold.

#### D[0] CFG\_LOCK

- Register lock access control
- When set to 1, the register content cannot be updated by SPI WR access.



### 5.5.3.9 SAFETY\_BIST\_CTRL Register

#### Read command: **RD\_SAFETY\_BIST\_CTRL**

### Write command: WR\_SAFETY\_BIST\_CTRL

	DATA INFORMATION									
D7	D6	D5	D4	D3	D2	D1	D0			
BIST_DEG_CNT[1]	BIST_DEG_CNT[0]	AUTO_BIST_DIS	EE_CRC_CHK	RSV	LBIST_EN	ABIST_EN	ABIST_EN			
0	0	0	0	0	0	0	0			

### **D[7:6] BIST\_DEG\_CNT[1:0]**: Deglitch filter duration setting during active analog BIST

- This bit controls deglitch filter duration for every safety monitored voltage.

- Resolution is 15  $\mu$ s (with the minimum setting at 15  $\mu$ s and the maximum setting at 60  $\mu$ s): bist\_deglitch = (BIST\_DEG\_CNT[1:0] + 1) × 15  $\mu$ s)
- 15-µs time reference has 5% accuracy coming from 4-MHz internal oscillator.
- When the ABIST is run in ACTIVE state, TI recommends to set this to the maximum deglitch time

#### D[5] AUTO\_BIST\_DIS

- This bit controls automatic BIST start-up in RESET state ONLY when device enters RESET sate from DIAGNOSTIC, ACTIVE, or SAFE state.
- When set to 1, automatic BIST start-up is disabled.
- **D[4] EE\_CRC\_CHK**: Recalculate EEPROM CRC8
  - This bit controls the EEPROM CRC8 check function
  - When set to 1, EEPROM content is reloaded and CRC8 re-calculated and compared against expected value stored in EEPROM DFT register.

Note: With every power-up event, EEPROM content is reloaded and its CRC8 re-calculated.

- The self-test status is checked through bit 4 in SAFETY\_STATUS\_2 register.
- D[3] RSV, readable and writable without effect

#### D[2] LBIST\_EN: Enable logic BIST run

- This bit controls the logic BIST run (which will also run ABIST)
- The self-test status is monitored through bits D1 and D4 in the SAFETY\_STAT\_3 register.
- LBIST\_EN clears the DIAG\_EXIT\_MASK bit to 0. The time-out counter only stops during the running of LBIST. After LBIST completes, the time-out counter continues from last value. To stay in the DIAGNOSTIC state, the DIAG\_EXIT\_MASK bit must be set to 1 after LBIST completion. For transition from the DIAGNOSTIC state to the ACTIVE state, the DIAG\_EXIT bit must be set to 1.
- **D[1] ABIST\_EN**: Enable analog BIST run (same as D[0])
  - This bit controls the analog UV,OV and LOC BIST run.
  - The self-test status is monitored through bits D0, D2, and D3 in the SAFETY\_STAT\_3 register, and bit D5 in the SAFETY\_STAT4 register.
- D[0] ABIST \_EN: Enable analog BIST run (same as D[1])
  - The bit controls the analog UV, OV, and LOC BIST run.
  - The self-test status is monitored through bits D0, D2, and D3 in the SAFETY\_STAT\_3 register, and bit D5in the SAFETY\_STAT4 register.

Write command: WR\_SAFETY\_CHECK\_CTRL

### 5.5.3.10 SAFETY\_CHECK\_CTRL Register

### Read command: RD\_SAFETY\_CHECK\_CTRL

#### DATA INFORMATION D7 D6 D5 D4 D3 D2 D1 D0 CFG\_CRC\_EN RSV ENABLE\_DRV RSV RSV NO\_ERROR DIAG\_EXIT\_MASK DIAG\_EXIT 0 0 0 1 1 0 0 0

### D[7] CFG\_CRC\_EN

- Controls the enabling of CRC8 protection for the device configuration registers.
- When set to 1, CRC8 is calculated for all device configuration registers and compared with the CRC8 value stored in the SAFETY\_CFG\_CRC register.
- TI recommends to first to set the desired device configuration, followed by updating the SAFTY\_CFG\_CRC register before setting this bit to 1.
- The following registers are protected:
  - •SAFETY\_FUNC\_CFG register
  - •DEV\_REV (device revision) register
  - •SAFETY\_PWD\_THR\_CFG register
  - •SAFETY\_ERR\_CFG register
  - •WDT\_TOKEN\_CFG register
  - •WDT\_WIN1\_CFG register
  - •WDT\_WIN2\_CFG register
  - •SAFETY\_ERR\_PWM\_L register
  - •DEV\_CFG2 register
  - •DEV\_CFG1 register (only bit D6)
- D[6] RSV, readable and writeable with no impact to device state, ENDRV, and NRES output

#### D[5] ENABLE\_DRV

- Controls the enabling of the ENDRV output
- In addition to setting this bit to 1, the watchdog failure counter must be decremented below the default count value of 5 to enable the ENDRV output.
- D[4:3] RSV, readable and writeable with no impact to device state, ENDRV, and NRES output

#### D[2] NO\_ERROR

- Controls the enabling of the MCU\_ERROR pin-monitor function (through the device ERROR/WDI pin) and transition from the ACTIVE state to the SAFE state when an MCU\_ERROR pin failure is detected.
  - •1: MCU\_ERROR pin failure is not monitored, but a detected failure in the ACTIVE state does not cause a transition to the SAFE state.
  - •0: MCU\_ERROR pin failure is monitored, and a detected failure in the ACTIVE state causes a transition to the SAFE state.
- If an MCU\_ERROR pin failure is detected, the ERROR\_PIN\_FAIL status bit in the SAFETY\_ERR\_STAT register is set, only for setting NO\_ERROR = 0.

•ERROR\_PIN\_FAIL status bit in SAFETY\_ERR\_STAT register, and MCU\_ERR status bit in SAFETY\_STAT\_4 are set

#### D[1] DIAG\_EXIT\_MASK

- Controls the exit from the DIAGNOSTIC state
- When set to 1, exit from the DIAGNOSTIC state is disabled regardless if a DIAGNOSTIC state time-out event occurs or if the DIAG\_EXIT bit is set.
- This feature is only recommended for software debug and development and must not be activated in functional mode.

#### D[0] DIAG\_EXIT

- Controls exit from the DIAGNOSTIC state to ACTIVE state
- When set to 1 and the DIAG\_EXIT\_MASK bit is 0, the device transitions from the DIAGNOSTIC to the ACTIVE state.



### 5.5.3.11 SAFETY\_FUNC\_CFG Register

Read command: RD\_SAFETY\_FUNC\_CFG

### Write command: WR\_SAFETY\_FUNC\_CFG

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
NO_SAFE_TO	ERROR_CFG	WD_CFG	IGN_PWRL	WD_RST_EN	DIS_NRES_M ON	RSV	VDD_3_5_SEL				
1	0	0	0	0	1	0	Х				

#### D[7] NO\_SAFE\_TO

- Controls the enabling and disabling of the SAFE state time-out function

- When set to 1, the SAFE state time-out is disabled. Device remains *locked* in the SAFE state when ERR\_CNT reaches the SAFE\_LOCK\_THR + 1 value.

– When set to 0, SAFE state time-out is enabled. The device transitions to the RESET state after 680 ms when ERR\_CNT reaches the SAFE\_LOCK\_THR + 1 value.

#### D[6] ERROR\_CFG: MCU Error Signal Monitor configuration bit

 When set to 0, PWM monitoring is enabled (can be used as an external clock monitor). Expected ERROR/WDI pin LOW and HIGH durations are controlled by the SAFETY\_ERR\_PWM\_H and SAFETY\_ERR\_PWM\_L registers (see Section 5.5.3.13 and Section 5.5.3.14, respectively).

 When set to 1, the TMS570 ERROR pin mode is enabled. The ERROR pin low-duration threshold is set by the SAFETY\_ERR\_PWM\_L register.

#### D[5] WD\_CFG: Watchdog function configuration bit

- When set to 0: Trigger Mode (default) - watchdog trigger input through ERROR/WDI pin

- When set to 1: Q&A Mode watchdog trigger (answer) input through SPI
- D[4] IGN\_PWRL: Ignition-power latch control bit
  - Controls the enabling of the ignition-power latch
    - Note: This bit can only be changed when the device is in DIAGNOSTIC state
  - When set to 1, the user can pull the ignition input LOW, but the device remains powered up.
  - When cleared to 0 with IGN input pin LOW, device enters STANDBY state. Cleared by a CANWU event

#### D[3] WD\_RST\_EN

- 1: Watchdog failure is detected when WDT\_FAIL\_CNT[2:0] reaches the count of 7 (in the SAFETY\_STAT\_2 register), leading to a transition to the RESET state.
- 0: Watchdog failure events are detected, but device does not transition to RESET state when WDT\_FAIL\_CNT reaches count of 7.

#### D[2] DIS\_NRES\_MON

- When set to 1 (default state): NRES monitoring is disabled.
- When set to 0: NRES monitoring is enabled. In this case and device in ACTIVE state, a difference between NRES pin state and NRES driver state (for example: the bit NRES\_ERR in SAFETY\_STAT\_3) will cause a transition to SAFE state
- D[1] RSV, readable and writeable in DIAGNOSTIC state with no impact to device state, ENDRV and NRES output

#### D[0] VDD\_3\_5\_SEL: Status bit of VDD3/VDD5 selection at power up

- SEL\_VDD3/5 input pin is sampled and latched at power up
  - •0: 5-V setting (pin SEL\_VDD3/5 connected to ground)
  - •1: 3.3-V setting (pin SEL\_VDD3/5 not connected)
  - Value in RESET state depends on state of SEL\_VDD3/5 pin at first power up
- This bit is READ-ONLY

Note: Same as DEV\_CFG1 bit D7

### 5.5.3.12 SAFETY\_ERR\_STAT Register

Read command: RD\_SAFETY\_ERR\_STAT

	DATA INFORMATION											
		1	DF			ľ						
D7	D6	D5	D4	D3	D2	D1	D0					
RSV	RSV	ERROR_PIN_FAI	WD_FAIL	DEV_ERR_CNT[	DEV_ERR_CNT[	DEV_ERR_CNT[	DEV_ERR_CNT[					
		L		3]	2]	1]	0]					
0	0	0	0	0	0	0	0					

D[7:6] RSV

#### D[5] ERROR\_PIN\_FAIL

 Set to 1 when the MCU Error Signal Monitoring Module detects MCU\_ERROR pin failure on ERROR/WDI pin, only if NO\_ERROR = 0 (bit D2 in SAFETY\_CHECK\_CTRL register). Device enters SAFE state when this ERROR\_PIN\_FAIL bit is set to 1

- Cleared to 0 after SPI WR access or cleared to 0 during reset event

#### D[4] WD\_FAIL

Set to 1 when the watchdog function failure counter reaches the count of 7 (WDT\_FAIL\_CNT[2:0] in the SAFETY\_STATUS\_2 register) only if bit WD\_RST\_EN (SAFETY\_FUNC\_CFG, bit 3) is set to 1

- Cleared to 0 after SPI WR access when the watchdog fail counter is less than 7 or cleared to 0 during reset event

#### D[3:0] DEV\_ERR\_CNT[3:0]

- Tracks the current device error count.
- Overwritten by SPI WR access, but ONLY in the DIAGNOSTIC mode.

### 5.5.3.13 SAFETY\_ERR\_PWM\_H Register

### Read command: **RD\_SAFETY\_ERR\_PWM\_H**

#### DATA INFORMATION D7 D6 D4 D3 D2 D0 D5 D1 PWMH[6] PWMH[5] PWMH[0] PWMH[7] PWMH[4] PWMH[3] PWMH[2] PWMH[1] 0 0 0 0 1 0 1 1

D[7:0] PWMH[7:0]: ERROR pin high-phase duration in PWM mode (15-µs resolution)

Controls the expected high-phase duration with 15-µs resolution

(15-µs time reference has 5% accuracy coming from 4-MHz internal oscillator)

### 5.5.3.14 SAFETY\_ERR\_PWM\_L Register

Read command: **RD\_SAFETY\_ERR\_PWM\_L** 

#### Write command: WR\_SAFETY\_PWM\_L

Write command: WR SAFETY PWM H

Write command: WR\_SAFETY\_ERR\_STAT

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
PWML[7]	PWML[6]	PWML[5]	PWML[4]	PWML[3]	PWML[2]	PWML[1]	PWML[0]				
0	0	1	1	1	1	0	1				

D[7:0] PWML[7:0]: ERROR pin low-phase duration

- Controls expected low-phase duration

•When the ERR\_CFG bit is 0 (in PWM mode): ERR PWM low-phase duration with 15-µs resolution

 $T_{PWM LOW} = (PWML[7:0] + 1) \times 15 \ \mu s$ 

(15-µs time reference has 5% accuracy coming from 4-MHz internal oscillator)

•When ERR\_CFG bit is 1 (TMS570 mode): ERR low duration with 5-µs resolution

 $T_{TH_LOW_TMS570} = (PWML[7:0] + 1) \times 5 \ \mu s$ 

(5-µs time reference has 5% accuracy coming from 4-MHz internal oscillator)

 $T_{PWM HIGH} = (PWMH[7:0] + 1) \times 15 \ \mu s$ 



### 5.5.3.15 SAFETY\_PWD\_THR\_CFG Register

### Read command: RD\_SAFETY\_PWD\_THR\_CFG Write command: WR\_SAFETY\_PWD\_THR\_CFG

	DATA INFORMATION										
D7	D6	D5	D4	D3	D2	D1	D0				
RSV	RSV	RSV	RSV	PWD_THR[3]	PWD_THR[2]	PWD_THR[1]	PWD_THR[0]				
0	0	0	0	1	1	1	1				

D[7:4] RSV

**D[3:0] PWD\_THR[3:0]**: Device error-count threshold to power down the device

- When DEV\_ERR\_CNT reaches programmed threshold, the device powers down.

- The device recovers with a new wake-up or ignition event.

- This register can be updated only in DIAGNOSTIC mode.

### 5.5.3.16 SAFETY\_CFG\_CRC Register

### Read command: **RD\_SAFETY\_CFG\_CRC**

### Write command: WR\_SAFETY\_CFG\_CRC

	DATA INFORMATION										
D7	D7 D6 D5 D4 D3 D2 D1 D0										
CFG_CRC[7]	CFG_CRC[7] CFG_CRC[6] CFG_CRC[5] CFG_CRC[4] CFG_CRC[3] CFG_CRC[2] CFG_CRC[1] CFG_CRC[0]										
0	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$										

D[7:0] CFG\_CRC[7:0]: CRC8 value for safety configuration registers Note: Can be updated only in the DIAGNOSTIC state

### 5.5.3.17 Diagnostics

### 5.5.3.17.1 DIAG\_CFG\_CTRL Register

Read command: RD\_DIAG\_CFG\_CTRL

/ loud e		0/ 00				_0/ 0_0///2				
			DATA INFO	ORMATION	-	-	-			
D7	D6	D5	D4	D3	D2	D1	D0			
MUX_EN	SPI_SDO	MUX_OUT	INT_CON[2]	INT_CON[1]	INT_CON[0]	MUX_CFG[1]	MUX_CFG[0]			
0	0	0	0	0	0	0	0			
D[7] MUX_E	[7] MUX_EN: Enable diagnostic MUX output									
0: E	0: Disabled (tri-stated)									
1: E	Inabled									
D[6] SPI_SD	O: To control the	SPI_SDO output-b	ouffer state during	an interconnect te	est					
То	check the SDO dia	agnostics use the f	following sequenc	e:						
	<ul> <li>MUX_CFG cor</li> </ul>	nfiguration must be	e 0x1 (DIAG_CFG	_CTRL register bi	its [1:0])					
	=> DIGITAL M	UX mode								
	<ul> <li>SPI NCS must</li> </ul>	be kept HIGH								
	<ul> <li>The state of SI</li> </ul>	DO is controlled by	/ bit SPI_SDO							
D[5] MUX_O	UT: Diagnostic MI	UX output-state co	ntrol bit							
Not	e: When the MUX	_CFG bits are set	to 00 and the ML	IX_EN bit is set to	1					
D[4:2] INT_CC	N[2:0]: Device int	erconnect-test cor	figuration bits							
	: No active interco									
	: ERR input state	-								
010	: SPI_NCS input s	state observed on	diagnostic MUX o	utput						
	: SPI_SDI input st		-							
	: SPI_SCLK input	observed on diag	nostic MUX outpu	t						
	: Not applicable									
	: Not applicable									
	: Not applicable									
	FG: Diagnostic MI	0								
	The MUX output is		JX_OUT bit (bit 5	in DIAG_CFG_CT	RL register)					
	Digital MUX mode									
	Analog MUX mod									
11:	Device interconne	ect mode (input-pir	is interconnect tes	st)						
5.5.3.17.2 D	IAG_MUX_SE	L Register								
Read o	command: <b>RD</b> _	_DIAG_MUX_S	SEL	Write commar	nd: WR_DIAG_	_MUX_SEL				
			DATA INFO	ORMATION						
D7	D6	D5	D4	D3	D2	D1	D0			
		1		1			1			

D[7:0] MUX\_SEL[7:0]: Diagnostic MUX channel select

MUX\_SEL[5]

0

MUX\_SEL[6]

0

Note: The MUX channel table is dependent on the MUX\_CFG[1:0] bit settings in the DIAG\_CFG\_CTRL register (see Section 5.5.3.17.1)

MUX\_SEL[3]

0

MUX\_SEL[2]

0

MUX\_SEL[4]

0

MUX\_SEL[7]

0

MUX\_SEL[1]

0

MUX\_SEL[0]

0



### Write command: WR\_DIAG\_CFG\_CTRL

### 5.5.4.1 WDT\_TOKEN\_FDBCK Register

Read command: **RD\_WDT\_TOKEN\_FDBCK** 

				DATA INFORMAT	TION		
D7	D6	D5	D4	D3	D2	D1	D0
FDBK[3]	FDBK[2]	FDBK[1]	FDBK[0]	TOKEN_SEED[3]	TOKEN_SEED[2]	TOKEN_SEED[1]	TOKEN_SEED[0]
0	0	0	0	0	0	0	0

D[7:4] FDBK[3:0]: Watchdog quesiton (token) FSM feedback configuration bits

- FDBK [3:0] bits control the sequence of generated questions and respective answers

- There is a set of 16 generated questions, repetition or sequence ordering can be adjusted by FDBK[3:0] bits

D[3:0] TOKEN\_SEED[3:0]: Watchdog token seed value, used to generate a set of new questions (tokens)

- Ttoken seed value can be updated by the MCU only after watchdog is reinitialization in DIAGNOSTIC state after RESET:

Only for Q&A Mode

### 5.5.4.2 WDT\_WIN1\_CFG Register

Read command: **RD\_WDT\_WIN1\_CFG** 

#### Write command: WR\_WDT\_WIN1\_CFG

	DATA INFORMATION							
D7	D6	D5	D4	D3	D2	D1	D0	
RSV	RT[6]	RT[5]	RT[4]	RT[3]	RT[2]	RT[1]	RT[0]	
0	1	1	1	1	1	1	1	

D[7] RSV

D[6:0] RT[6:0]: Watchdog WINDOW 1 duration setting

- See Equation 1 and Equation 2 to calculate the minimum and maximum values for the t<sub>WIN1</sub> time period.

### 5.5.4.3 WDT\_WIN2\_CFG Register

#### Read command: **RD\_WDT\_WIN2\_CFG**

### Write command: WR\_WDT\_WIN2\_CFG

	DATA INFORMATION						
D7	D6	D5	D4	D3	D2	D1	D0
RSV	RSV	RSV	RW[4]	RW[3]	RW[2]	RW[1]	RW[0]
0	0	0	1	1	0	0	0

D[7:5] RSV

D[4:0] RW[4:0]: Watchdog WINDOW 1 duration setting

- See Equation 3 and Equation 4 to calculate the minimum and maximum values for the t<sub>WIN2</sub> time period.

## Write command: WR\_WDT\_TOKEN\_FDBCK

### 5.5.4.4 WDT\_TOKEN\_VALUE Register

### Read command: **RD\_WDT\_TOKEN\_VALUE**

	DATA INFORMATION							
D7	D6	D5	D4	D3	D2	D1	D0	
WDFAIL_TH	RSV	RSV	RSV	TOKEN[3]	TOKEN[2]	TOKEN[1]	TOKEN[0]	
1	0	0	0	0	0	0	0	

#### D[7] WDFAIL\_TH

Set to 1 when the watchdog fail counter reaches a count of 4 or higher (WDT\_FAIL\_CNT[2:0] in the SAFETY\_STATUS\_2 register)

Set to 0 when the watchdog fail counter reaches a count of less than 4 (WDT\_FAIL\_CNT[2:0] in the SAFETY\_STATUS\_2 register)

D[6:4] RSV

D[3:0] TOKEN[3:0]: watchdog question (token)

- The MCU must read (or calculate) the current question (token) to generate a correct answer bytes.

- Only for Q&A Mode

### 5.5.4.5 WDT\_STATUS Register

### Read command: RD\_WDT\_STATUS

			DAT	A INFORM	ATION				
	D7	D6	D5	D4	D3	D2	D1	D0	
WDT_	_ANSW_CNT [1]	WDT_ANSW_CNT TOKEN_ERR WD_WR ONG_CF ONG_CFG_CHG SEQ_ERR TIME_OUT TOKEN_ [0]							
	1	1	0	0	0	0	0	0	
D[7:6]	WDT_ANSW_	CNT[1:0]: Current watc	hdog answer cou	int					
	<ul> <li>Only for Q</li> </ul>	&A Mode							
D[5]	TOKEN_ERR:	Watchdog question (tol	ken) error-status	bit to show	incorrect answers				
		set to 1 as soon as one correct again. This bit is				prrect. This flag	is cleared if the	e following	
	<ul> <li>Only for Q</li> </ul>	&A Mode							
D[4]	WD_WRONG	_CFG							
	<ul> <li>Set to 1 w</li> </ul>	hen either WDT_WIN1_	CFG or WDT_W	IN2_CFG a	re set to 0x00				
D[3]	WD_CFG_CH	G: Watchdog configurat	ion-change statu	s bit					
		set to 1 when switching re changed	between the Trig	ger and Q8	A Mode or when	WDT_WIN1_CF	G or WDT_WI	N2_CFG	
D[2]	SEQ_ERR: The last answer byte sequence was wrong								
	<ul> <li>Incorrect timing or wrong answer</li> </ul>								
	<ul> <li>Only for Q&amp;A Mode</li> </ul>								
D[1]	TIME_OUT: N	o full watchdog event (tr	igger or answer-	x bytes) rec	eived within the wa	atchdog sequer	nce (time-out ev	vent)	
	<ul> <li>In Trigger</li> </ul>	Mode (default configura	tion): set to 1 wh	en no trigge	er has been receiv	ed on the ERR	OR/WDI pin du	ring the	

watchdog sequence
 In Q&A Mode: set to 1 when less than four answer-x bytes have been received during the watchdog sequence

- This flag may be used to re-synchronize the MCU timing to the device watchdog:

#### **D[0] TOKEN\_ERLY**: Answer byte sequence completed too early

- Set to 1 if all four answer bytes are returned during WINDOW 1
- Only for Q&A Mode



## 5.5.4.6 WDT\_ANSWER Register

#### Write command: WR\_WDT\_ANSWER

	DATA INFORMATION							
D7	D6	D5	D4	D3	D2	D1	D0	
WDT_ANSW[7]	WDT_ANSW[6]	WDT_ANSW[5]	WDT_ANSW[4]	WDT_ANSW[3]	WDT_ANSW[2]	WDT_ANSW[1]	WDT_ANSW[0]	
0	0	0	0	0	0	0	0	

D[7:0] WDT\_ANSW[7:0]: answer bytes

- See Section 5.4.1.16.3.1 for details on answer bytes

Only for Q&A Mode

### 5.5.5 Sensor Supply

#### 5.5.5.1 SENS\_CTRL Register

#### Read command: RD\_SENS\_CTRL

#### Write command: WR\_SENS\_CTRL

	DATA INFORMATION						
D7	D6	D5	D4	D3	D2	D1	D0
RSV	RSV	RSV	VDD5_EN	RSV	RSV	RSV	VSOUT1_EN
0	0	0	1	0	0	0	0

#### D[7:5] RSV

#### D[4] VDD5\_EN: If cleared to 0, VDD5 then turns off.

 This bit is set to 1 by default, and is cleared in case of VDD5 over-temperature (indicated by the VDD5\_OT bit D1 in SAFETY\_STAT1).

**Note**: When VDD5 is disabled, bit VDD5\_ILIM (bit D7 in SAFETY\_STAT\_1) is set to 1 and remains set to 1 as long as VDD5 is disabled (or VDD5\_EN bit is 0).

#### D[3:1] RSV

D[0] VSOUT1\_EN: Sensor-supply enable bit (set this bit to 1 to enable the VSOUT1 sensor supply)

 This bit is set to 0 by default, and must be set to 1 by the MCU to enable VSOUT1. In case of VSOUT1 over-temperature (indicated by VSOUT1\_OT bit D2 in SAFETY\_STAT1), VSOUT1 is disabled; however this bit, VSOUT1\_EN, remains set to 1. As soon as the over-temperature in VSOUT1 has disappeared, VSOUT1 is re-enabled.



### 5.5.6 SPI Command Table

8-BIT HEX COMMAND CODE (WITH PARITY)	7-BIT HEX COMMAND CODE (WITHOUT PARITY)	7-BIT BINARY COMMAND CODE (WITHOUT PARITY)	PARITY	WR SW LOCK PROTECT	REGISTER COMMAND NAME <sup>(1)</sup>	
BD	5E	1011 110	1	N/A	SW_LOCK with data 0xAA (to lock SPI WR access to listed registers)	
BB	5D	1011 101	1	N/A	SW_UNLOCK with data 0x55 (to unlock SPI WR access to listed registers)	
06	03	0000 011	0	N/A	RD_DEV_ID	
0C	06	0000 110	0	N/A	RD_DEV_REV	
B7	5B	1011 011	1	YES	WR_DEV_CFG1 (SPI WR update can occur only in DIAGNOSTIC state)	
AF	57	1010 111	1	N/A	RD_DEV_CFG1	
95	4A	1001 010	1	YES	WR_DEV_CFG2 (SPI WR update can occur only in DIAGNOSTIC state)	
48	24	0100 100	0	N/A	RD_DEV_CFG2	
7D	3E	0111 110	1	NO	WR_CAN_STBY	
24	12	0010 010	0	N/A	RD_SAFETY_STAT_1	
C5	62	1100 010	1	N/A	RD_SAFETY_STAT_2	
A3	51	1010 001	1	N/A	RD_SAFETY_STAT_3	
A5	52	1010 010	1	N/A	RD_SAFETY_STAT_4	
C0	60	1100 000	0	N/A	RD_SAFETY_STAT_5	
30	18	0011 000	0	N/A	RD_SAFETY_ERR_CFG	
DB	6D	1101 101	1	YES	WR_SAFETY_ERR_CFG (SPI WR update can occur only in DIAGNOSTIC state)	
A9	54	1010 100	1	YES	WR_SAFETY_ERR_STAT (SPI WR update can occur only in DIAGNOSTIC state)	
AA	55	1010 101	0	N/A	RD_SAFETY_ERR_STAT	
39	1C	0011 100	1	N/A	RD_SAFETY_PWD_THR_CFG	
99	4C	1001 100	1	YES	WR_SAFETY_PWD_THR_CFG (SPI WR update can occur only in DIAGNOSTIC state)	
44	22	0100 010	0	N/A	RD_SAFETY_CHECK_CTRL	
93	49	1001 001	1	NO	WR_SAFETY_CHECK_CTRL	
3C	1E	0011 110	0	N/A	RD_SAFETY_BIST_CTRL	
9F	4F	1001 111	1	YES	WR_SAFETY_BIST_CTRL (SPI WR update can occur only in DIAGNOSTIC and ACTIVE states)	
2E	17	0010 111	0	N/A	RD_WDT_WIN1_CFG	
ED	76	1110 110	1	YES	WR_WDT_WIN1_CFG (SPI WR update can occur only in DIAGNOSTIC state)	
05	02	0000 010	1	N/A	RD_WDT_WIN2_CFG	
09	04	0000 100	1	YES	WR_WDT_WIN2_CFG (SPI WR update can occur only in DIAGNOSTIC state)	
36	1B	0011 011	0	N/A	RD_WDT_TOKEN_VALUE	
4E	27	0100 111	0	N/A	RD_WDT_STATUS	
E1	70	1110 000	1	NO	WR_WDT_ANSWER	
11	08	0001 000	1	N/A	RD_DEV_STAT	
12	09	0001 001	0	N/A	RD_VMON_STAT_1	
A6	53	1010 011	0	N/A	RD_VMON_STAT_2	
56	2B	0101 011	0	N/A	RD_SENS_CTRL	
7B	3D	0111 101	1	N/A	WR_SENS_CTRL	
3A	1D	0011 101	0	N/A	RD_SAFETY_FUNC_CFG	

(1) All commands have even parity.

96 Detailed Description



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8-BIT HEX COMMAND CODE (WITH PARITY)	7-BIT HEX COMMAND CODE (WITHOUT PARITY)	7-BIT BINARY COMMAND CODE (WITHOUT PARITY)	PARITY	WR SW LOCK PROTECT	REGISTER COMMAND NAME <sup>(1)</sup>
35	1A	0011 010	1	YES	WR_SAFETY_FUNC_CFG (SPI WR update can occur only in DIAGNOSTIC state)
5A	2D	0101 101	0	N/A	RD_SAFE_CFG_CRC
63	31	0110 001	1	YES	WR_SAFE_CFG_CRC (SPI WR update can occur only in DIAGNOSTIC state)
DD	6E	1101 110	1	N/A RD_DIAG_CFG_CTRL	
CC	66	1100 110	0	NO	WR_DIAG_CFG_CTRL
AC	56	1010 110	0	N/A	RD_DIAG_MUX_SEL
C9	64	1100 100	1	NO	WR_DIAG_MUX_SEL
D7	6B	1101 011	1	N/A	RD_SAFETY_ERR_PWM_H
D8	6C	1101 100	0	YES	WR_SAFETY_ERR_PWM_H (SPI WR update can occur only in DIAGNOSTIC state)
59	2C	0101 100	1	N/A	RD_SAFETY_ERR_PWM_L
7E	3F	0111 111	0	YES WR_SAFETY_ERR_PWM_L (SPI WR update can occur only in DIAGNOSTIC state)	
78	3C	0111 100	0	N/A	RD_WDT_TOKEN_FDBCK
77	3B	0111 011	1	YES	WR_WDT_TOKEN_FDBCK (SPI WR update can occur only in DIAGNOSTIC state)

### 6 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 6.1 Application Information

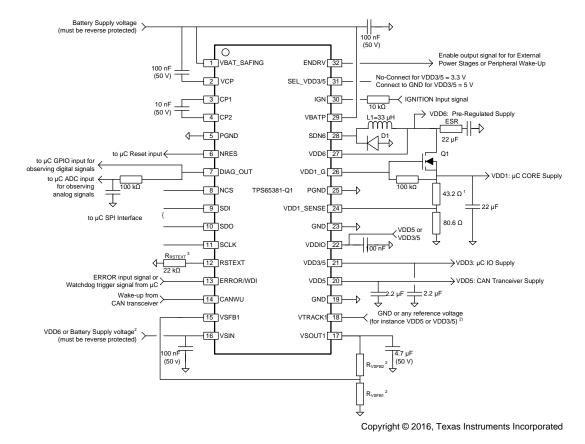
The TPS65381-Q1 device is a multi-rail power supply including one buck preregulator, one linear controller, one 5-V linear regulator, one programmable 3.3-V or 5-V linear regulator, and one linear tracking regulator with protection against short to battery and ground. The device has many diagnostic and monitoring functions. This device provides a power management basis for many different applications.

### 6.2 Typical Application

The following design requirements and design procedure are an example of how to select component values for the TPS65381-Q1 device for a typical application. Because many of the regulators are adjustable, the equations should be used to calculate the component values for the specific application. For additional reference, also refer to the design checklist and application notes listed in Section 9.2.1.



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#### Example components:

- ٠ Q1: BUK9213-30A
- ٠ D1: Vishay SS3H09/10, OnSemi MBRS340T3
- D2: ROHM UDZSTE-176.2B ٠
- ٠ L1: EPCOS B82464G4333M000 or COILCRAFT MSS1246T-333ML

#### NOTE:

- 1. 43.2 Ω for 1.23-V output voltage (Recommended for TI TMS570 MCU). Change this resistor to obtain different VDD1 output voltage (Note: VDD1\_SENSE = 800 mV)
- 2.  $R_{VSFB1}$  and  $R_{VSFB2}$  configure the VSOUT1 voltage
  - Pin 16 (VSIN) to be connected either to pin 27 (VDD6) for VSOUT1 ≤ 5 V or to pin 29 (VBATP) for 5 V < VSOUT1 < 9.5 V</p> \_
    - Pin 18 (VTRACK1) to be connected to GND for non-tracking mode, or a reference voltage (for example VDD5 or VDD3/5) for tracking mode.
  - See Section 5.3.5 for details. \_
- 3. R<sub>RSEXT</sub> configures the Reset Extension time. See the Reset and Enable outputs section of Section 4.5

### Figure 6-1. Typical Application Diagram

### 6.2.1 Design Requirements

While selecting capacitors for the application consider the following characteristics:

- The effective capacitance at the operating voltage must be used when selecting the proper capacitor. Capacitors derate with operating voltage, sometimes as much as 70%. Therefore the capacitance of the circuit could be outside of the specified value for the capacitor as listed in Section 4.
- The temperature and lifetime of the capacitor may also have an impact on the effective capacitance and should be considered.
- The voltage ratings of the capacitor should be considered, especially on the high-voltage input circuits that may also experience transient voltages.

These impacts must all be considered when selecting a capacitor so that the circuit has the specified capacitance required for this device at the application operating conditions of the capacitor such as temperature, voltage, and lifetime.

VBATP and VBAT\_SAFING are the supply inputs to the device. These supplies must be reverse battery protected. The supplies should also be adequately protected against transients and have sufficient noise filtering for the intended application. If the application has noisy and high current output drives that are connected to either VBATP, VBAT\_SAFING, or both, additional filtering may be necessary between the output drive and the device.

IGN is a wake-up input to the device. This input provides up to -7 V of protection. Beyond this voltage, IGN must be reverse protected. If the noise occurs longer than the specified deglitch time, IGN should also be adequately protected against transients and have sufficient noise filtering for the intended application.

### 6.2.2 Detailed Design Procedure

### 6.2.2.1 VDD6 Preregulator

The inductor, output capacitor, and total effective series resistance of the output capacitance must be considered to achieve balanced operation of the VDD6 preregulator.

The output inductor must be greater than or equal to the minimum 22- $\mu$ H inductance. The typical specified inductance is 33  $\mu$ H which was selected for this design.

The effective output capacitance for VDD6 is specified between 22  $\mu$ F and 47  $\mu$ F. An effective capacitance of 22  $\mu$ F at the 6-V DC operating point was selected for this design. This value allows for additional downstream input capacitance on voltage regulator inputs. To filter high frequencies, use 10-nF and 0.1- $\mu$ F capacitors. If higher effective capacitance is used the voltage ripple is reduced and lowers the required ESR. The effective capacitance of a capacitor should be provided by the capacitor supplier and needs to be de-rated for lifetime, temperature and operating voltage.

Because the VDD6 preregulator is a hysteretic architecture, controlled ESR is required with the output capacitance. The specified ESR range is 100 m $\Omega$  to 300 m $\Omega$ . Use Equation 15 to calculate the minimum total ESR to achieve balanced operation.

$$R_{ESR} = L / (15 \times C_{Effective}) = 33 / (15 \times 22) = 100 \text{ m}\Omega$$
(15)

As an example, the data sheet for the capacitor states that the ESR of the capacitor is 4 m $\Omega$  and the parasitic extraction of the PCB design is 6 m $\Omega$ . An ESR resistor of 100 m $\Omega$  can still be used, or the discrete ESR resistor can be sized to 90 m $\Omega$  resulting in a total effective ESR at least 100 m $\Omega$ . If a larger effective capacitance is used the equation may result in an ESR value below 100 m $\Omega$ . In this case, the total ESR should still be brought up to the 100 m $\Omega$  total ESR minimum to meet the specification.

A high-voltage surface-mount Schottky rectifier diode, such as SS3H9/10 or MBRS340T3, should be used.

Figure 6-2 shows this configuration.





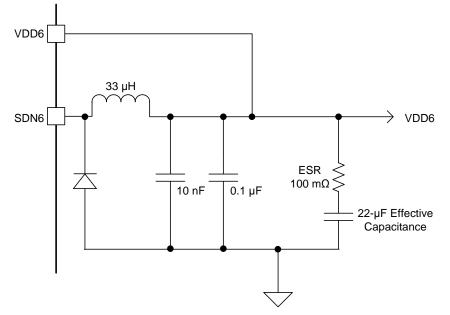


Figure 6-2. VDD6 Design

### 6.2.2.2 VDD1 Linear Controller

The microprocessor used with the TPS65381-Q1 device requires a core voltage of 1.23 V.

The output voltage of the VDD1 linear controller is set by a resistor divider from the VDD1 output to ground with the divided voltage connected to the VDD1\_SENSE pin which must be set to 800 mV. To ensure sufficient bias current through the resistor divider select a value of R1 as 80.6  $\Omega$ . Use Equation 16 to calculate the resistance of R2.

$$R2 = ([VDD1 \times R1] / V_{VDD1\_SENSE}) - R1 = ([1.23 V \times 80.6 \Omega] / 0.8 V) - 80.6 \Omega = 43.3 \Omega$$
(16)

Select the standard value 43.2  $\Omega$ .

Select an output FET for the VDD1 linear controller that meets the requirements in the VDD1 – LDO With External FET specifications in Section 4.5. An example output FET is BUK9213-30A. The gate of the output FET is connected to VDD1\_G. A 100-k $\Omega$  resistor is connected between the gate and source of the FET. The drain of the FET is connected to the VDD6 preregulator output which is used as the supply input for the VDD1 linear controller.

A low-ESR ceramic output capacitor with 22- $\mu$ F effective capacitance at 1.23 V is used to meet the requirements for the output capacitor that are listed in this data sheet. Depending on the application, this output may require a larger output capacitor to ensure the output does not drop below the required regulation specification during load transients. The VDD1 output capacitance is specified up to 40  $\mu$ F.

Figure 6-3 shows this configuration.



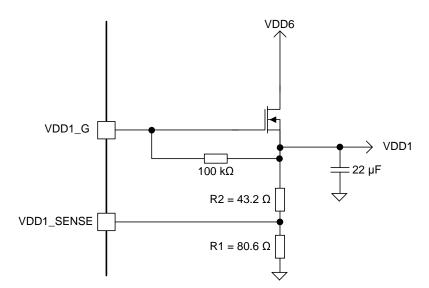


Figure 6-3. VDD1 Design

### 6.2.2.3 VSOUT1 Tracking Linear Regulator, Configured to Track VDD5

The system has a sensor that requires a 5-V supply that must track the VDD5 supply. The configuration should be set up for higher efficiency.

The VDD5 output is connected to the VTRACK1 pin which configures the regulator for tracking mode. Because the output must track the input, unity gain feedback is used on the VSFB1 pin by connecting it to the VSOUT1 pin.

For efficiency, use the VDD6 preregulator as the supply. Therefore, the VDD6 output is connected to VSIN. A local, low-ESR 100-nF ceramic capacitor is used on the VSIN pin to stabilize the input.

A local, low-ESR 4.7- $\mu$ F ceramic capacitor is used on the VSOUT1 output for loop stabilization. Depending on the application, this output may require a larger output capacitor to ensure that the output does not drop below the required regulation specification during load transients. The VSOUT1 output capacitance is specified up to 10  $\mu$ F.

Figure 6-4 shows this configuration.

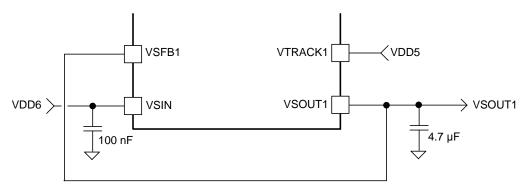


Figure 6-4. VSOUT1 Design—Tracking, No Gain



# 6.2.2.4 Alternative Use for VSOUT1 Tracking Linear Regulator, Configured for 6-V Output Tracking VDD3/5 In 3.3-V Mode

The system has a sensor that requires a 6-V supply that must track the VDD3/5 supply operating at 3.3 V.

The VDD3/5 supply, operating in 3.3-V mode, is connected to the VTRACK1 pin which configures the regulator for tracking mode. Because the output must have gain to make the 6-V output track a 3.3 V supply, gain feedback is used on the VSFB1 pin. To achieve the required gain, connect a resistor divider the VSOUT1 and VSFB1 pins. Select a value of 3.3 k $\Omega$  for the RVSFB1 resistor to balance the current through the resistor divider for reasonable bias current and reasonable losses. Use Equation 17 to calculate the resistance of RVSFB2.

RVSFB2 = ([VSOUT1 × RVSFB1] / VTRACK) – RVSFB1 = ([ $6 V \times 3.3 k\Omega$ ] / 3.3 V) –  $3.3 k\Omega$  =  $2.7 k\Omega$  (17)

Select the standard value of 2.7 k $\Omega$ .

Because the desired VSOUT1 output is greater than 5 V, the VBATP supply must be used for the tracking supply. Therefore, connect the VBATP supply to the VSIN pin. A local, low-ESR 100-nF ceramic capacitor is used on the VSIN pin to stabilize the input.

A local, low-ESR 4.7- $\mu$ F ceramic capacitor is used on the VSOUT1 pin for loop stabilization. Depending on the application, this output may require a larger output capacitor to ensure that the output does not drop below the required regulation specification during load transients. The VSOUT1 output capacitance is specified up to 10  $\mu$ F.

Figure 6-5 shows this configuration.

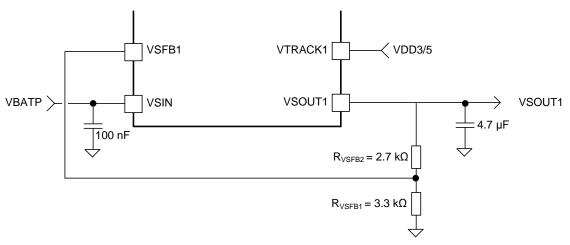


Figure 6-5. VSOUT1 Design—Tracking, With Gain (VDD3/5)

# 6.2.2.5 Alternative Use for VSOUT1 Tracking Linear Regulator, Configured for 9-V Output Tracking to 5-V Input from VDD5

The system has a sensor that requires a 9-V supply that must track the VDD5 supply operating at 5 V.

The VDD5 supply is connected to VTRACK1 which configures the regulator for tracking mode. Because the output must have gain to make the 9-V output track a 5-V supply, gain feedback is used on the VSFB1 pin. To achieve the required gain, connect a resistor divider between the VSOUT1 and VSFB1 pins. Select a value of 3.3 k $\Omega$  for the RVSFB1 resistor to balance the current through the resistor divider for reasonable bias current and reasonable losses. Use Equation 18 to calculate the resistance of RVSFB2.

RVSFB2 = ([VSOUT1 × RVSFB1] / VTRACK) – RVSFB1 = ([9 V ×  $3.3 \text{ k}\Omega$ ] / 5 V) –  $3.3 \text{ k}\Omega$  = 2.64 k $\Omega$  (18)

Select the standard value of 2.7 k $\Omega$ .

Because the desired VSOUT1 output is greater than 5-V, the VBATP supply must be used as the tracking supply. Therefore, connect the VBATP supply to the VSIN pin. A local, low-ESR 100-nF ceramic capacitor is used on the VSIN pin to stabilize the input.

A local, low-ESR 4.7- $\mu$ F ceramic capacitor is used on the VSOUT1 pin for loop stabilization. Depending on the application, this output may require a larger output capacitor to ensure that the output does not drop below the required regulation specification during load transients. The VSOUT1 output capacitance is specified up to 10  $\mu$ F.

Figure 6-6 shows this configuration.

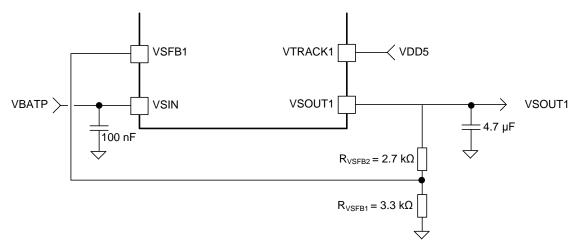


Figure 6-6. VSOUT1 Design—Tracking, With Gain (VDD5)



### 6.2.2.6 Alternative Use for VSOUT1 Tracking Linear Regulator, Configured in Non-tracking Mode Providing a 4.5-V Output

If the system requires a 4.5-V supply that does not track any other supply.

The VTRACK1 pin is connected to ground (GND) which configures the regulator for non-tracking mode. The output is now proportional to a fixed reference voltage (VREF) of 2.5 V on the VSFB1 pin. Because the output must have gain to result in a 4.5-V output, gain feedback will be used on the VSFB1 pin. To achieve the required gain, connect a resistor divider between the VSOUT1 and VSFB1 pins. Select a value of 3.3 k $\Omega$  for the RVSFB1 resistor to balance the current through the resistor divider for reasonable bias current and reasonable losses. Use Equation 19 to calculate the resistance of RVSFB2.

RVSFB2 = ([VSOUT1 × RVSFB1] / VREF) – RVSFB1 = ([4.5 V × 3.3 kΩ] / 2.5 V) – 3.3 kΩ = 2.64 kΩ (19)

Select the standard value of 2.7 k $\Omega$ .

For efficiency, the VDD6 preregulator is the supply and therefore the VDD6 output is connected to the VSIN pin. A local, low-ESR 100-nF ceramic capacitor is used on the VSIN pin to stabilize the input.

A local, low-ESR 4.7- $\mu$ F ceramic capacitor is used on the VSOUT1 pin for loop stabilization. Depending on the application, this output may require a larger output capacitor to ensure that the output does not drop below the required regulation specification during load transients. The VSOUT1 output capacitance is specified up to 10  $\mu$ F.

Figure 6-7 shows this configuration.

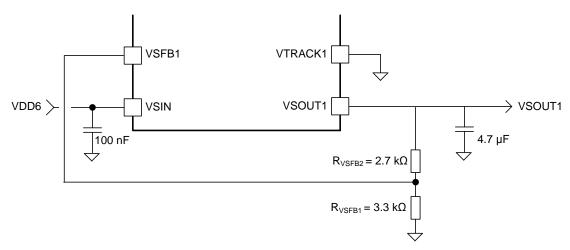


Figure 6-7. VSOUT1 Design—Non-Tracking

### 6.2.3 Application Curves

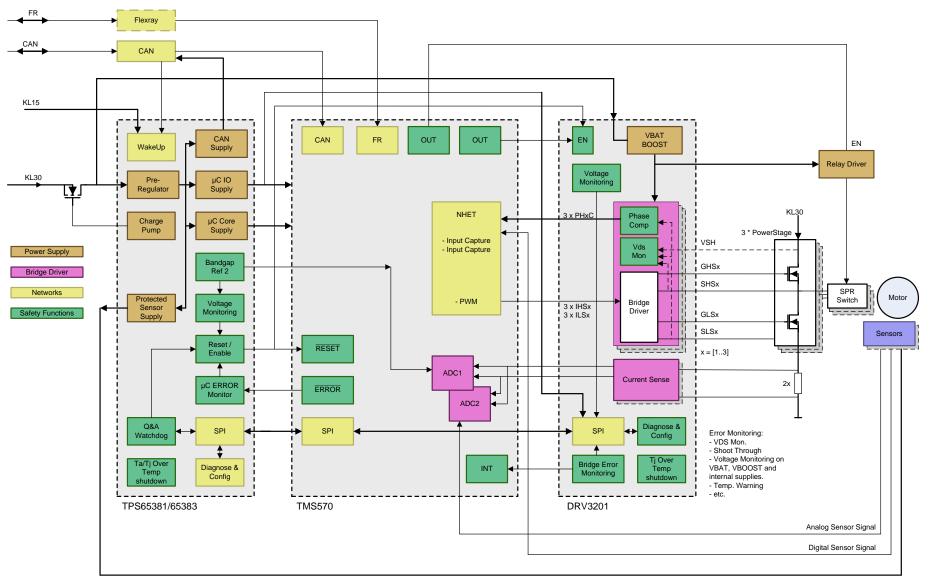
For the application curves, see the figures listed in Table 6-1.

Table	6-1.	Table	of	Graphs
1 4 5 1 5	• • •		•••	0.00

FIGURE TITLE	FIGURE NUMBER
SPI SDO Buffer Source/Sink Current	Figure 4-3
VDD6 BUCK Efficiency	Figure 4-4



6.3 System Examples







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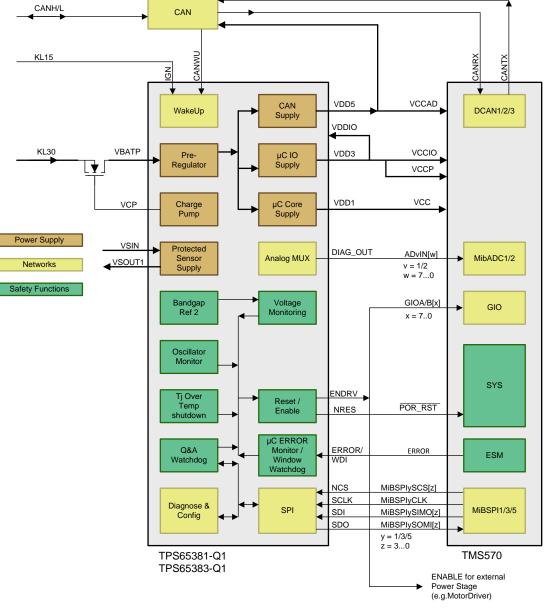


Figure 6-9. Example TPS65381-Q1 With TI's TMS570LS

¥ VDD5 CAN WakeUp DCAN1/2 Supply VDDIO VCCAD KL30 VBATP VDD3 VCCP1 PreuC IO Regulator **V** Supply VCCPIOR µC Core VCC Supply VDD1 µC Core Charge VCP Pump Supply Power Supply VSIN Protected DIAG\_OUT ADIN[w] Sensor Analog MUX MibADC VSOUT1 Networks Supply w = 15...0 Safety Functions GIOA[x] Voltage Monitoring Bandgap Ref 2 GIO GIOA[x] x = 7..0 Oscillator Monitor SYS ENDRV Tj Over Reset / Temp shutdown POR\_RST NRES Enable µC ERROR Monitor / Q&A ERROR Watchdog Window /wdi<sup>A</sup> Watchdog NCS MiBSPlySCS[z] MiBSPlyCLK SCLK ◄ Diagnose & SPI MiBSPI1/2 SDI MiBSPlySIMO[z] Config ◄ SDO MiBSPlySOMI[z] y = 1/2z = 3...0TPS65381-Q1 TMS470 TPS65383-Q1 EN for external Power Stage ► (example MotorDriver)

The ERROR/WDI pin can be configured as an input for the µC ERROR monitor (TMS570 dual core) or as a window watchdog input (TMS470 single core).

# Figure 6-10. Example TPS65381-Q1 With TI's TMS470 (Using an Internal MCU Core Supply)



CANTX

CANRY

CANH/L

KL15

CAN

Ч

CANWU



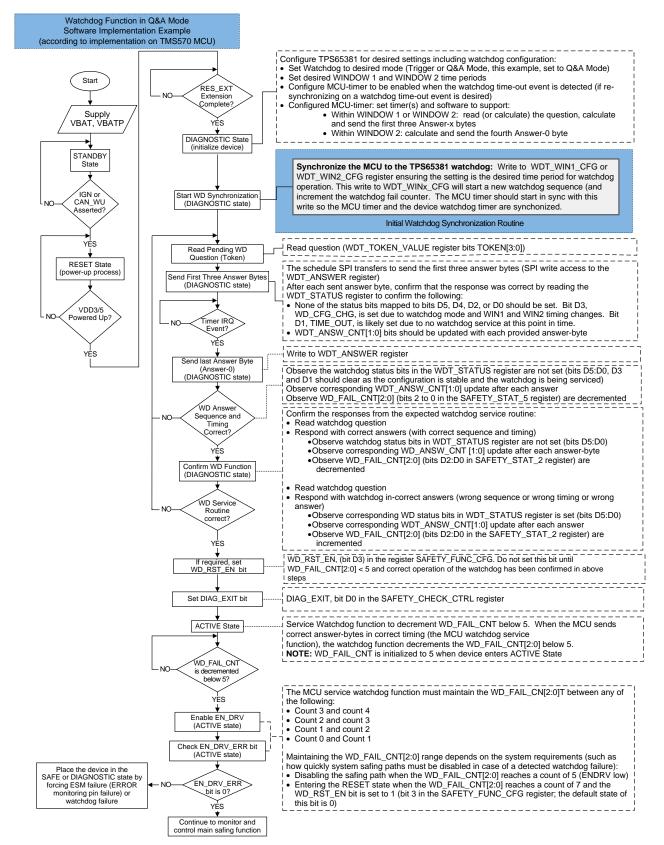
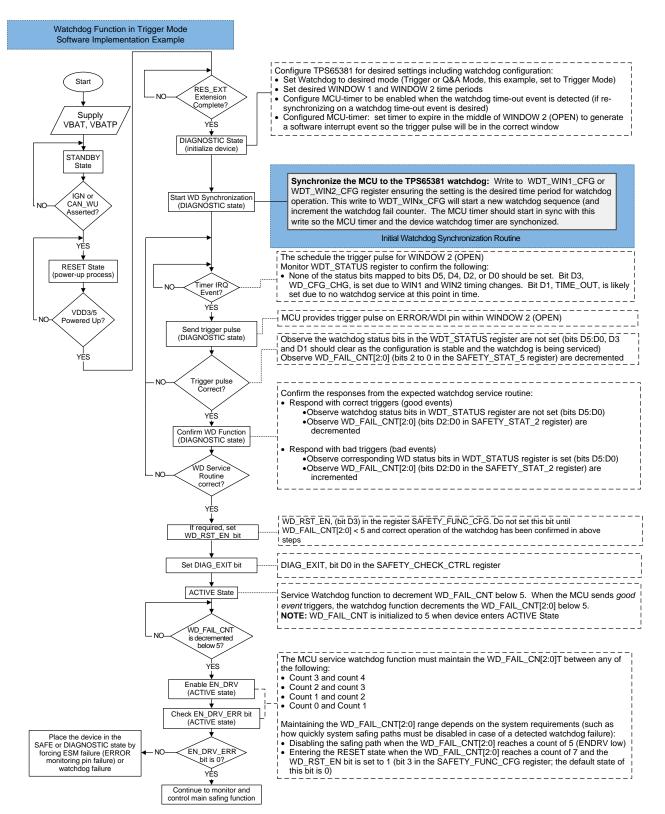


Figure 6-11. Software Flowchart for Configuring and Synchronizing the MCU With the Watchdog in Q&A Mode





# Figure 6-12. Software Flowchart for Configuring and Synchronizing the MCU With the Watchdog in Trigger Mode

## 7 Power Supply Recommendations

The TPS65381-Q1 device is designed to operate using an input supply voltage range from 5.8 V to 36 V (CAN, I/O, MCU core, and functional sensor-supply regulators) or 4.5 V to 5.8 V (3.3-V I/O and functional MCU-core voltage). The device has two supply pins: VBATP and VBAT\_SAFING. VBATP pin is the main supply pin for the device. VBAT\_SAFING supply pin for monutoring (VMON) and BG2 functions. Both VBATP and VBAT\_SAFING must be reverse protected. VBAT\_SAFING should be connected to VBATP with a low impedence connection to minimize voltage differences between the device supply pins. For additional power supply recommendations, see the *TPS65381EVM User's Guide*, SLVU847.

#### 8 Layout

#### 8.1 Layout Guidelines

#### 8.1.1 VDD6 Buck Preregulator

- Minimize the loop area for the switching loop of the inductor, ESR resistor and output capacitor and diode.
- Minimize the parasitic trace impedance by using as wide of traces as possible.
- Minimize the parasitic via impedance by using multiple vias, especially on high current and switching nodes.
- Connect the inductor and diode to SDN6 as close as possible to the pin.
- Connect the diode to PGND (ground plane).
- Connect the ESR resistor and output capacitor in series between VDD6 output (inductor output) and PGND.
- Connect the EMC filter capacitor between VDD6 output and PGND.
- Connect the VDD6 output to the VDD6 pin with routing to avoid coupling switching noise. Trace length should be minimized and as wide a trace as possible. This trace is the supply input to the downstream regulators using VDD6 as a pre-regulator, parasitic impedance should be minimized.

Additional consideration: add footprint for a RC snubber circuit if one is necessary for the application. The RC connects in-series between SDN6 and PGND.

### 8.1.2 VDD1 Linear Regulator Controller

- Connect the drain of the external FET to VDD6 node, the trace should be minimized so that additional downstream buffering capacitors are not needed.
- Connect the output capacitor to the source of the external FET, the length of this trace should be minimized. Connect the output capacitor to the ground plane.
- Connect the gate drive, VDD1\_G, to the gate of the FET. Connect the resistor between the gate of the FET and the source of the FET, minimize the trace length.
- The resistor divider for sensing and setting the output voltage connects between the source of the FET (VDD1 output) and GND (IC signal ground). Do not locate these components and their traces near the switching nodes or high-current traces.

### 8.1.3 VDD5 and VDD3/5 Linear Regulators

Connect the output capacitor as close as possible between the VDDx output and GND.

### 8.1.4 VSOUT1 Tracking Linear Regulator

- Connect the output capacitor as close as possible between the VSOUT1 output and GND.
- The resistor divider for sensing and setting the output voltage connects between the VSOUT1 and GND (IC signal ground). Do not locate these components and their traces near the switching nodes or high-current traces.
- Connect the local decoupling capacitor between VSIN and PGND. Minimize trace length.
- Route the tracking supply signal, connected to VTRACK1, away from switching nodes or high-current traces.

#### 8.1.5 Charge Pump

- Connect the capacitor as close as possible between the CP1 and CP2.
- Connect the capacitor between VCP and VBATP (reverse protected and filtered) supply.

#### 8.1.6 Other Considerations

- Use ground planes.
- Minimize parasitic impedance on the critical switching and high current paths.
- Short PGNDx and GND to the thermal pad.
- Use a star ground configuration if connecting to a non-ground plane system. Use tie-ins for the, voltage-sense feedback ground, and local biasing bypass capacitor ground networks to this star ground.
- Connect the local decoupling capacitor between VBATP and PGND. Minimize trace length.



## 8.2 Layout Example

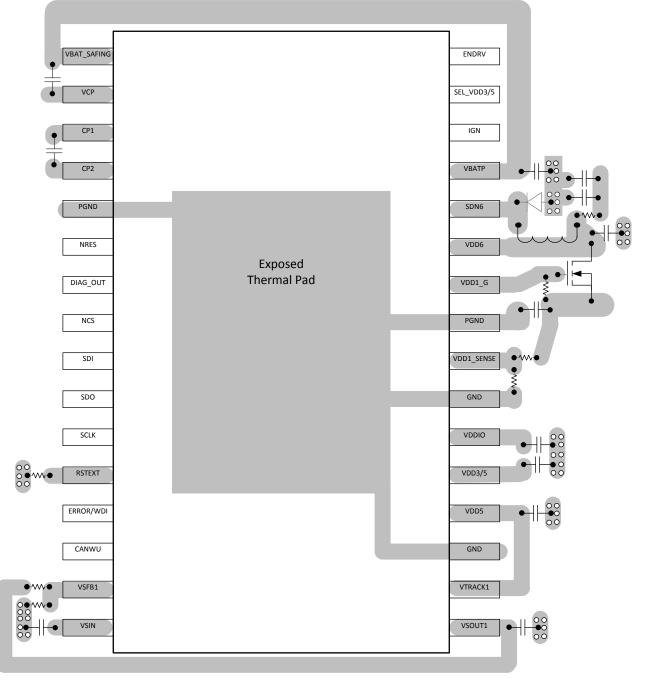


Figure 8-1. TPS65381-Q1 Board Layout

## 9 Device and Documentation Support

#### 9.1 Device Support

#### 9.1.1 Third-Party Products Disclaimer

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#### 9.2 Documentation Support

#### 9.2.1 Related Documentation

For related documentation see the following:

- Device Behavior Under Slow VBAT Ramp-Up and Ramp-Down, SLVA643
- DPI Evaluation TPS65381-Q1, SLVA575
- Efficiency Evaluation TPS65381-Q1, SLVA606
- Safety Manual for TPS65381-Q1 Multi-Rail Power Supply, SLVA528
- TPS65381EVM User's Guide, SLVU847
- TPS65381-Design-Checklist, SLVA611

#### 9.3 Community Resources

#### 9.3.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 9.4 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

#### 9.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

### 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



1-Jul-2016

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS65381QDAPRQ1	NRND	HTSSOP	DAP	32	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	TPS65381	

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

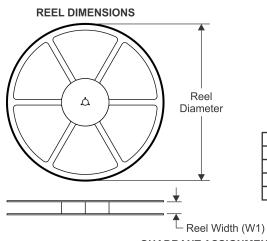
1-Jul-2016

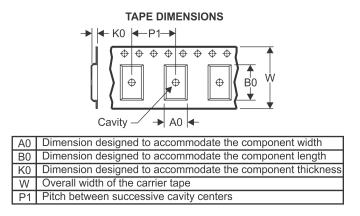
## PACKAGE MATERIALS INFORMATION

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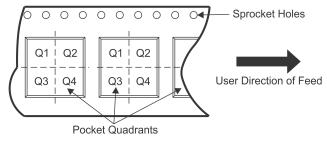
Texas Instruments

## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nomi	inal
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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS65381QDAPRQ1	HTSSOP	DAP	32	2000	330.0	24.4	8.6	11.5	1.6	12.0	24.0	Q1

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

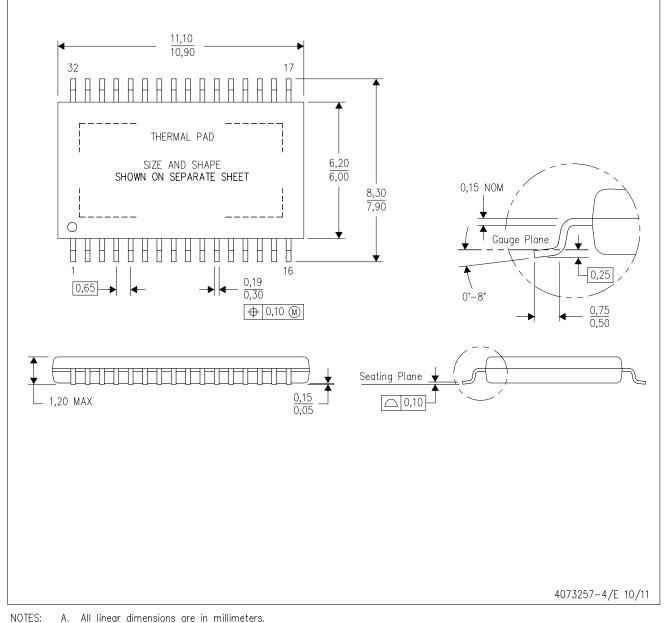
4-Nov-2015



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS65381QDAPRQ1	HTSSOP	DAP	32	2000	367.0	367.0	45.0





- This drawing is subject to change without notice. Β.
- Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad
- Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>. Falls within JEDEC MO-153 Variation DCT.

PowerPAD is a trademark of Texas Instruments.



## DAP (R-PDSO-G32)

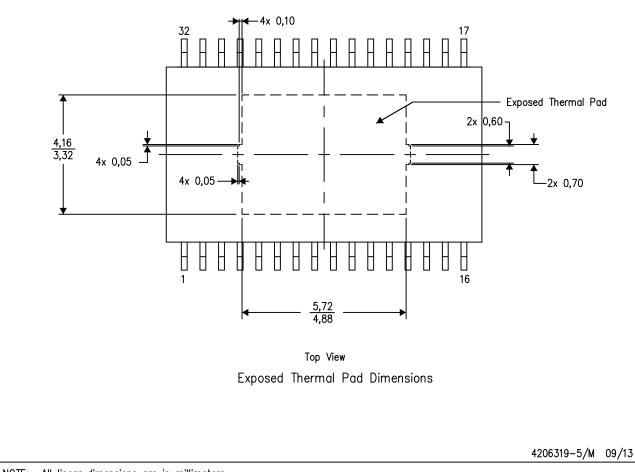
## PowerPAD<sup>™</sup> PLASTIC SMALL OUTLINE

#### THERMAL INFORMATION

This PowerPAD<sup>™</sup> package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



#### NOTE: All linear dimensions are in millimeters

#### PowerPAD is a trademark of Texas Instruments.



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